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A journal devoted to the physics and chemistry of interfaces

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Surface Science 401–410 (1998) 1–27

Author index to volumes 401–410

Aaronson, H.I., see Lee 408 (1998) 288
Abe, D., see Hasegawa 405 (1998) L503
Abe, K., see Tsukada 401 (1998) 355
Abukawa, T., see Kim 410 (1998) 99
Aebi, P., R. Fasel, D. Naumović, J. Hayoz, Th. Pillo, M. Bovet, R.G. Agostino, L. Patthey, L. Schlapbach, F.P. Gil, H. Berger, T.J. Kreutz and J. Osterwalder, Angle-scanned photoemission: Fermi surface mapping and structural determination 402–404 (1998) 614
Aeschlimann, M., see Bauer 402–404 (1998) 62
Aeschlimann, M., see Pawlik 402–404 (1998) 556
Agostino, R.G., see Aebi 402–404 (1998) 614
Agrawal, B.K., P. Srivastava and S. Agrawal, First-principles calculation of electron surface states of the zinc-blende GaN(110) surface 405 (1998) 54
Agrawal, B.K., S. Agrawal and P. Srivastava, Electronic localized and resonance states of relaxed GaAs(110) surfaces – an ab initio LMTO approach 408 (1998) 275
Agrawal, S., see Agrawal 405 (1998) 54
Agrawal, S., see Agrawal 408 (1998) 275
Ågren, H., see Pettersson 408 (1998) 1
Aguilar, M., A.I. Oliva and P. Quintana, The effect of electrical current (DC) on gold thin films 409 (1998) 501
Ahdjoudj, J. and C. Minot, Adsorption of H_2O on metal oxides: a periodic ab-initio investigation 402–404 (1998) 104
Aimé, J.P., see Boisgard 401 (1998) 199
Aizpurua, J., A. Rivacoba, N. Zabala and F.J. García de Abajo, Collective excitations in an infinite set of aligned spheres 402–404 (1998) 418
Akemann, W., see Petukhov 402–404 (1998) 182
Akemann, W., K.A. Friedrich, U. Linke and U. Stimming, The catalytic oxidation of carbon monoxide at the platinum/electrolyte interface investigated by optical second harmonic generation (SHG): comparison of Pt(111) and Pt(997) electrode surfaces 402–404 (1998) 571
Akita, M., N. Osaka and K. Itoh, Infra-red reflection absorption spectroscopic study on adsorption structures of acrolein on polycrystalline gold and Au(111) surfaces under ultra-high vacuum conditions 405 (1998) 172
Akpati, H.C., P. Nordlander, L. Lou and Ph. Avouris, A density-functional study of the effects of an external electric field on admolecule–surface systems 401 (1998) 47
Akremi, A., J.-P. Lacharme and C.A. Sébenne, Influence of defects on surface scattering of UV photoemitted electrons in near perfect Si(111)1×1-H 402–404 (1998) 746
Aktsipetrov, O.A., E.D. Mishina, T.V. Misuryaev, A.A. Nikulin, V.R. Novak, R. Stolle and Th. Rasing, Nonlinear optical interferometry and second harmonic generation spectroscopy of Langmuir films of fullerene-indopane derivative 402–404 (1998) 576
Ala-Nissila, T., see Hjelt 402–404 (1998) 253
Albertini, D., see Thibaudau 409 (1998) L718
Aldaz, A., see Gómez 410 (1998) 48
Alfè, D., S. de Gironcoli and S. Baroni, The reconstruction of Rh(001) upon oxygen adsorption 410 (1998) 151
Allegretti, F.E., see Tejedor 407 (1998) 82
Allison, W., see Quinton 402–404 (1998) 66
Allison, W., see Luo 402–404 (1998) 437
Allouche, A., Water adsorption on NaCl(100): a quantum ab-initio cluster calculation 406 (1998) 279
Almeida, J., G. Margaritondo, M. Righini, S. Selci, C. Coluzza, Ballistic-electron emission and secondary photoelectron microscopy of the sulfur-passivated Pt–GaP(001) interface 402–404 (1998) 470
Altman, E.I., see Nakakura 401 (1998) 173
Altman, M.S., see Bartoš 402–404 (1998) 697
Ammer, C., K. Meinel, H. Wolter and H. Neddermeyer, Oxidized surfaces of Cu films on Ru(0001) 401 (1998) 138
Ammer, Ch., see Meinel 401 (1998) 434
Ammer, Ch., see Meinel 402–404 (1998) 299
An, K.S., A. Kimura, K. Ono, N. Kamakura, A. Kakizaki, C.Y. Park and K. Tanaka, Surface structure and segregation of ordered $Pt_3Co(110)$ induced by oxygen 401 (1998) 336
Ancilotto, F., see Scandolo 402–404 (1998) 808
Andersen, J.N., see Strisland 410 (1998) 330
Andersson, G. and H. Morgner, Impact collision ion scattering spectroscopy (ICISS) and neutral impact collision ion scattering spectroscopy (NICISS) at surfaces of organic liquids 405 (1998) 138
Andreazza-Vignolle, C., see Brault 406 (1998) L597
Andrieu, S., see Bencok 402–404 (1998) 327
Andryushechkin, B.V., K.N. Eltsov, V.M. Shevlyuga and V.Yu. Yurov, Atomic structure of saturated chlorine monolayer on Ag(111) surface 407 (1998) L633
Angot, T. and R. Chelly, Stable Ge–H phase at 620 K on $Si_{1-x}Ge_x$/Si(001) surface: a high resolution electron energy loss spectroscopy study 402–404 (1998) 52
Angot, T., see Dentel 402–404 (1998) 211
Angot, T., P. Louis and G. Gewinner, Epitaxy of two-dimensional

$ErSi_xGe_{2-x}$ on Si(111) (5×5)–Ge observed by LEED and HREELS 409 (1998) 350

Aoki, K., T. Suzuki, H. Minoda, Y. Tanishiro and K. Yagi, Au adsorption induced faceting and phase transitions of facet planes on the Si[110] zone studied by UHV-REM 408 (1998) 101

Aphek, O.B., L. Kronik, M. Leibovitch and Y. Shapira, Quantitative assessment of the photosaturation technique 409 (1998) 485

Arabczyk, W. and U. Narkiewicz, The effect of the real crystal structure of iron on the behaviour of surface contaminants 402–404 (1998) 502

Aray, Y. and J. Rodriguez, Study of CO adsorption on the Fe(100) surface using the Laplacian of the electronic charge density 405 (1998) L532

Arcade, P., see Bencok 402–404 (1998) 327

Argile, C., Interaction of oxygen with lead-precovered nickel(100) 409 (1998) 265

Aristov, V.V., V.V. Kazmiruk, V.A. Kudryashov, V.I. Levashov, S.I. Red'kin, C.W. Hagen and P. Kruit, Microfabrication of ultrathin free-standing platinum foils 402–404 (1998) 337

Aristov, V.Yu., see Douillard 401 (1998) L395

Aristov, V.Yu., see Layet 402–404 (1998) 724

Aruga, T., see Okuyama 401 (1998) 344

Asaklil, A., see Mazroui 409 (1998) 528

Asanari, J., see Yamada 402–404 (1998) 683

Aschoff, M., G. Piaszenski, S. Speller and W. Heiland, The structure of the $Au_3Pd(113)$ surface studied by low energy ion scattering 402–404 (1998) 770

Asensio, M.C., see Huttel 402–404 (1998) 609

Asensio, M.C., see Mascaraque 402–404 (1998) 742

Asensio, M.C., see Laine 402–404 (1998) 871

Asensio, M.C., see Laine 402–404 (1998) 875

Asmussen, B., M. Strzelczyk, W. Press and J.Z. Larese, Low coverage structure of tetramethyltin adsorbed on graphite 406 (1998) 138

Asoka Kumar, P.S., see Klauser 402–404 (1998) 87

Atrei, A., see Ceelen 406 (1998) 264

Averous, M., see Breton 406 (1998) 63

Avila, J., see Huttel 402–404 (1998) 609

Avila, J., see Mascaraque 402–404 (1998) 742

Avila, J., see Laine 402–404 (1998) 871

Avila, J., see Laine 402–404 (1998) 875

Avouris, Ph., see Akpati 401 (1998) 47

Ayadi, A., see Madih-Ayadi 402–404 (1998) 836

Ayadi, A., see Madih-Ayadi 405 (1998) 192

Azpuru, I.G., see Berlouis 408 (1998) 173

Baba, Y., K. Yoshii and T.A. Sasaki, Desorption of fragment ions from mono- and multilayered CCl_4 on Cu(100) by inner-shell photoexcitation 402–404 (1998) 115

Baberschke, K., see Bovensiepen 402–404 (1998) 396

Baberschke, K., see Srivastava 402–404 (1998) 818

Babonneau, D., T. Cabioc'h, A. Naudon, J.C. Girard and M.F. Denanot, Silver nanoparticles encapsulated in carbon cages obtained by co-sputtering of the metal and graphite 409 (1998) 358

Bach Aaen, A., E. Lægsgaard, A.V. Ruban and I. Stensgaard, Submonolayer growth of Pd on Cu(111) studied by scanning tunneling microscopy 408 (1998) 43

Baddeley, C., see Gießel 406 (1998) 90

Baddorf, A.P., see Okada 410 (1998) 237

Badziag, P., Energetics of the α-SiC(0001)-(3×3) surface reconstruction 402–404 (1998) 822

Baer, Y., see Hengsberger 405 (1998) L491

Baer, Y., see Purdie 407 (1998) L671

Bagus, P.S., see García-Hernández 409 (1998) 69

Bailes III, A.A., M.A. Boshart and L.E. Seiberling, Dimer elongation on the monohydride-covered Ge/Si(100) surface 410 (1998) L762

Bailey, P., see Wincott 402–404 (1998) 705

Baker, S.H., see Jones 409 (1998) 27

Balzarotti, A., see Motta 406 (1998) 254

Balzer, F., R. Gerlach, M. Schober and H.-G. Rubahn, An HAS study of laser irradiation of alkali-covered dielectrics 402–404 (1998) 841

Banouni, M., see Oueini 410 (1998) 132

Bansenaur, B., see Peck 410 (1998) 214

Bansmann, J., M. Getzlaff, G. Schönhense, M. Fluchtmann and J. Braun, Valence band photoemission from thin iron films – a comparison of experimental and theoretical results 402–404 (1998) 365

Bansmann, J., L. Lu and M. Getzlaff, Magnetic dichroism in photoemission from oxygen atoms adsorbed on cobalt surfaces 402–404 (1998) 371

Bao, S., see Gießel 406 (1998) 90

Bao, X., see Uchida 401 (1998) 469

Baraldi, A., G. Comelli, S. Lizzit, D. Cocco, G. Paolucci and R. Rosei, Reply to 'Comment on 'Temperature programmed X-ray photoelectron spectroscopy: a new technique for the study of surface kinetics" by S. Nettesheim, M. Handschuh and R. Zenobi 401 (1998) L455

Baraldi, A., see Lizzit 410 (1998) 228

Barbier, A., see Robach 401 (1998) 227

Barbier, A., G. Renaud and A. Stierle, The NiO(111)-(1×1) surface 402–404 (1998) 757

Barbier, A., P. Ohresser, V. Da Costa, B. Carriere and J.-P. Deville, Preparation and characterization of $Co(10\bar{1}0)$ surfaces 405 (1998) 298

Barbier, A., Generalized model for interface description 406 (1998) 69

Barbier, L., see Goapper 409 (1998) 81

Bardi, U., see Ceelen 406 (1998) 264

Bare, S.R., see Ranney 401 (1998) 1

Barlow, S.M., K.J. Kitching, S. Haq and N.V. Richardson, A study of glycine adsorption on a Cu{110} surface using reflection absorption infrared spectroscopy 401 (1998) 322

Baroni, S., see Alfè 410 (1998) 151

Bartelt, M.C., see Zhang 406 (1998) 178

Bartoš, I., M.A. Van Hove, W.F. Chung, Z. He and M.S. Altman, Ag(111) electron band structure and channeling by VLEED 402–404 (1998) 697

Bates, S.P., G. Kresse and M.J. Gillan, The adsorption and dissociation of ROH molecules on TiO_2(110) 409 (1998) 336
Batteas, J.D., see Holbert 401 (1998) L437
Baucom, K.C., see Creighton 409 (1998) 372
Bauer, M., S. Pawlik, R. Burgermeister and M. Aeschlimann, Symmetry properties of an electronic alkali excitation at a noble metal surface as investigated by two-photon photoemission 402–404 (1998) 62
Bauer, M., see Pawlik 402–404 (1998) 556
Baumann, P.K. and R.J. Nemanich, Surface cleaning, electronic states and electron affinity of diamond(100), (111) and (110) surfaces 409 (1998) 320
Bäumer, M., see Stempel 402–404 (1998) 424
Bäumer, M., see Wolter 402–404 (1998) 428
Baurichter, A., see Diekhöner 409 (1998) 384
Beben, J., see Suchorski 405 (1998) L477
Becca, F., see Santoro 402–404 (1998) 802
Bechstedt, F., see Schmidt 409 (1998) 474
Beck, D.E., see Peck 410 (1998) 170
Beck, D.E., see Peck 410 (1998) 214
Becker, C., see Linke 402–404 (1998) 76
Beckmann, I., see Rosenfeld 402–404 (1998) 401
Beeby, J.L., see Hart 410 (1998) L757
Behm, R.J., see Braun 409 (1998) L715
Behrens, K.-M., E.-D. Klinkenberg, J. Finster and K.-H. Meiwes-Broer, Geometric structure of thin SiO_xN_y films on Si(100) 402–404 (1998) 729
Bei der Kellen, S., see Fluchtmann 402–404 (1998) 663
Beitia, C. and Y. Borensztein, Formation and stability of small particles of potassium studied by real-time surface differential reflectance 402–404 (1998) 445
Belk, J.G., D.W. Pashley, C.F. McConville, B.A. Joyce and T.S. Jones, Surface morphology during strain relaxation in the growth of InAs on GaAs(110) 410 (1998) 82
Belkhou, R., see Layet 402–404 (1998) 724
Bell, G.R., N.S. Kaijaks, R.J. Dixon and C.F. McConville, Atomic hydrogen cleaning of polar III–V semiconductor surfaces 401 (1998) 125
Bell, G.R., T.S. Jones and C.F. McConville, Spatial variation of plasmon damping near the polar surfaces of InAs in InSb 405 (1998) 280
Bencok, P., S. Andrieu, P. Arcade, C. Richter, V. Ilakovac, O. Heckmann, M. Vesely and K. Hricovini, Growth of vanadium ultrathin films on Fe(100) studied by RHEED 402–404 (1998) 327
Bencok, P., see Huttel 402–404 (1998) 609
Benedek, G., A. Glebov, W. Silvestri, J.G. Skofronick and J.P. Toennies, Reply to M.C. Vargas and W.L. Mochán's Comment on 'Evidence for a deep bound-state level in the ^{4}He–NaCl(001) potential' 406 (1998) L621
Benítez, G., see López-Carreño 402–404 (1998) 174
Benndorf, C., see Hadenfeldt 402–404 (1998) 227
Benndorf, C., see Mundt 405 (1998) 121
Benneker, A., see Jiang 405 (1998) L554
Bennett, R.A., S. Poulston, I.Z. Jones and M. Bowker, High-temperature scanning tunneling microscopy studies of oxygen-induced reconstructions of Pd(110) 401 (1998) 72
Bennett, R.A., see Jones 402–404 (1998) 595
Bennett, S.L., see Jones 409 (1998) 27
Bennewitz, R., see Puchina 402–404 (1998) 687
Bensebaa, F., Y. Zhou, Y. Deslandes, E. Kruus and T.H. Ellis, XPS study of metal–sulfur bonds in metal–alkanethiolate materials 405 (1998) L472
Bent, B.E., see Gleason 405 (1998) 238
Berg, C., see Venvik 402–404 (1998) 57
Berg, C., H.J. Venvik, F. Strisland, A. Ramstad and A. Borg, Nucleation and growth of Au overlayers on Pt(100)-hex-R0.7° studied by STM and photoelectron spectroscopy 409 (1998) 1
Berg, C., see Strisland 410 (1998) 344
Berger, H., see Aebi 402–404 (1998) 614
Berlouis, L.E.A., D.A. Mamman and I.G. Azpuru, The electrochemical behaviour of copper in alkaline solutions containing fluoride, studied by in situ ellipsometry 408 (1998) 173
Bernasek, S.L., see Dooley 406 (1998) 206
Berndt, R., see Glöckler 405 (1998) 1
Berndt, R., see Böhringer 408 (1998) 72
Berndt, W., see Gießel 406 (1998) 90
Bernhardt, T.M., B. Kaiser and K. Rademann, Formation of superperiodic patterns on highly oriented pyrolytic graphite by manipulation of nanosized graphite sheets with the STM tip 408 (1998) 86
Bertoni, C.M., see Marcellini 402–404 (1998) 47
Besenbacher, F., see Linderoth 402–404 (1998) 308
Besenbacher, F., see Rosenfeld 402–404 (1998) 401
Beton, P.H., see Moriarty 405 (1998) 21
Beton, P.H., see Upward 405 (1998) L526
Beton, P.H., see Moriarty 407 (1998) 27
Bettac, A., L. Köller, V. Rank and K.-H. Meiwes-Broer, Scanning tunneling spectroscopy on deposited platinum clusters 402–404 (1998) 475
Betti, M.G., see Gavioli 409 (1998) 207
Beutler, A., see Strisland 410 (1998) 330
Biagi, R., L. Rettighieri, U. del Pennino, V. Panella and P. Dumas, Charge accumulation layer induced by potassium adsorption on hydrogen terminated Si(111)(1×1) 402–404 (1998) 547
Bihlmayer, G., R. Eibler and R. Podloucky, Ab initio study of the CO adsorption on NiAl(110) and Pt(100) 402–404 (1998) 794
Bird, D.M., see Gülseren 402–404 (1998) 827
Birkenheuer, U., U. Gutdeutsch and N. Rösch, Geometrical structure of benzene absorbed on Si(001) 409 (1998) 213
Birkett, P.R., see Upward 405 (1998) L526
Bischoff, J.L., see Dentel 402–404 (1998) 211
Bischoff, J.L., see Dentel 402–404 (1998) 304
Blagov, E.V., G.L. Klimchitskaya and V.M. Mostepanenko, Impact of atomic relaxation on the breaks of constant force surfaces in AFM 410 (1998) 158
Bludau, H., see Setzer 402–404 (1998) 782

Bludau, H., K. Wu, M.S. Zei, M. Eiswirth, H. Over and G. Ertl, The structure of the underpotential deposition of copper on to Pt(111) in the presence of chloric anions: a LEED structure analysis 402–404 (1998) 786
Bludau, H., see Kleine 410 (1998) 15
Bluhm, H., see Xu 407 (1998) 251
Bode, M., see Getzlaff 410 (1998) 189
Böhmisch, M., see Rettenberger 402–404 (1998) 409
Bohnen, K.P. and D.M. Kolb, Charge- versus adsorbate-induced lifting of the Au(100)-(hex) reconstruction in an electrochemical environment 407 (1998) L629
Böhringer, M., see Glöckler 405 (1998) 1
Böhringer, M., W.-D. Schneider and R. Berndt, Scanning tunneling microscope-induced molecular motion and its effect on the image formation 408 (1998) 72
Boisgard, R., D. Michel and J.P. Aimé, Hysteresis generated by attractive interaction: oscillating behavior of a vibrating tip–microlever system near a surface 401 (1998) 199
Boishin, G., Alkali–germanium surface compound formation on a Ge(100)-(2×1) surface 402–404 (1998) 96
Boland, J.J., see Grube 407 (1998) 152
Bolmont, D., see Dentel 402–404 (1998) 304
Bolzan, A., see Singh 409 (1998) 272
Boneberg, J., see Rettenberger 402–404 (1998) 409
Boness, J., G. Marowsky, J. Braun, G. Witte and H.-G. Rubahn, Second-harmonic generation from sodium covered Si(111)7×7 surfaces 402–404 (1998) 513
Boness, J., see Kravetsky 402–404 (1998) 542
Bonnet, J., see Oueini 409 (1998) 445
Bonzel, H.P., see Pirug 405 (1998) 87
Bonzel, H.P., see Emundts 410 (1998) L727
Booth, N.A., see Lindsay 405 (1998) L566
Boragno, C., see Giudice 405 (1998) L561
Borensztein, Y., see Martin 402–404 (1998) 433
Borensztein, Y., see Beitia 402–404 (1998) 445
Borg, A., see Venvik 402–404 (1998) 57
Borg, A., see Berg 409 (1998) 1
Borghi, A., see Gazzadi 402–404 (1998) 632
Borgmann, D., see Kleyna 402–404 (1998) 131
Borisov, A.G., see Goryunov 401 (1998) 206
Borisov, A.G., see Hecht 406 (1998) L607
Börner, R., see Medvedev 401 (1998) L371
Borstel, G., see Fluchtmann 402–404 (1998) 663
Bos, C., see Limburg 409 (1998) 541
Boshart, M.A., see Bailes III 410 (1998) L762
Bottani, C.E., see Libassi 402–404 (1998) 441
Böttcher, A. and T. Gießel, Dissociative chemisorption of N_2O molecules on Cs layers monitored via exoelectron emission 408 (1998) 212
Boughaleb, Y., see Mazroui 409 (1998) 528
Bourgeois, S., see Pétigny 410 (1998) 250
Bovensiepen, U., P. Poulopoulos, M. Farle and K. Baberschke, The Curie temperature in ultrathin Ni/Cu(001) films determined by ac susceptibility and MOKE 402–404 (1998) 396
Bovet, M., see Aebi 402–404 (1998) 614
Böwering, N., see Brandt 402–404 (1998) 160
Bowker, M., see Bennett 401 (1998) 72
Bowker, M., see Jones 402–404 (1998) 595
Bowker, M., see Poulston 402–404 (1998) 599
Bowler, D.R., see Goringe 407 (1998) L681
Bradshaw, A.M., see Lindsay 405 (1998) L566
Bradshaw, A.M., see Gießel 406 (1998) 90
Bradshaw, A.M., see Tammaro 407 (1998) 162
Bradshaw, A.M., see Doering 410 (1998) L736
Brako, R. and D. Šokčević, Adsorbate interactions of CO chemisorbed on Pt(111) 401 (1998) L388
Brandt, M., T. Greber, F. Kuhlmann, N. Böwering and U. Heinzmann, State- and orientation-dependent N_2 emission in the N_2O+Cs reaction 402–404 (1998) 160
Bratu, P., see Raschke 410 (1998) 351
Brault, P., A.-L. Thomann and C. Andreazza-Vignolle, Percolative growth of palladium ultrathin films deposited by plasma sputtering 406 (1998) L597
Brault, P., see Guo 409 (1998) 452
Braun, J., see Bansmann 402–404 (1998) 365
Braun, J., see Boness 402–404 (1998) 513
Braun, J., see Fluchtmann 402–404 (1998) 663
Braun, J., H. Rauscher and R.J. Behm, Comment on 'STM study of low pressure adsorption of silane on Si(111)-(7×7)' by D. Albertini, F. Thibaudau, L. Masson and F. Salvan [Surf. Sci 350 (1996) L216] 409 (1998) L715
Brause, M., see Takami 407 (1998) 140
Brazdeikis, A., see Jiang 405 (1998) L554
Bredow, T., Embedded cluster study of water adsorption at Cr_2O_3(0001) 401 (1998) 82
Brena, B., see Wilde 405 (1998) 215
Brena, B., see Polop 407 (1998) 268
Breton, G., M. Nouaoura, C. Gautier, M. Cambon, S. Charar, M. Averous and V. Ribes, Annealing under vacuum and Se flux of CaF_2 molecular beam epitaxy surfaces prior to PbSe/CaF_2/Si growth 406 (1998) 63
Breuer, K., see Hengsberger 405 (1998) L491
Briggs, G.A.D., see Muggelberg 402–404 (1998) 673
Briggs, G.A.D., see Nörenberg 402–404 (1998) 734
Briggs, G.A.D., see Nörenberg 402–404 (1998) 738
Brillo, J., H. Kuhlenbeck and H.-J. Freund, Interaction of O_2 with WC(0001) 409 (1998) 199
Briner, B.G., see Doering 410 (1998) L736
Brivio, G.P., see Trioni 401 (1998) L383
Brizuela, G. and N.J. Castellani, C_5H_n rings adsorbed on Pt(111): a theoretical study 401 (1998) 297
Broekmann, P., see Wilms 402–404 (1998) 83
Brongersma, H.H., see Ceelen 406 (1998) 264
Brown, W.A., see Kose 402–404 (1998) 856
Bruker, P., see Rettenberger 402–404 (1998) 409
Brüning, K., J. Granow, M. Reiniger, W. Heiland, M. Vicanek and T. Schlathölter, Dissociation of fast N_2 molecules at a Pd(110) surface 402–404 (1998) 215
Burgermeister, R., see Bauer 402–404 (1998) 62
Burgermeister, R., see Pawlik 402–404 (1998) 556
Burghaus, U., see Vattuone 408 (1998) L693

Busch, B.W. and T. Gustafsson, Temperature dependent structure of clean Ag(110) studied by medium energy ion scattering 407 (1998) 7

Butler, D.A., see Diekhöner 409 (1998) 384

Cabioc'h, T., see Babonneau 409 (1998) 358

Cafolla, A.A., A new stochastic optimisation strategy for quantitative analysis of core level photoemission data 402–404 (1998) 561

Cafolla, A.A., see Power 402–404 (1998) 566

Cai, W.B., B. Ren, X.Q. Li, C.X. She, F.M. Liu, X.W. Cai and Z.Q. Tian, Investigation of surface-enhanced Raman scattering from platinum electrodes using a confocal Raman microscope: dependence of surface roughening pretreatment 406 (1998) 9

Cai, X.W., see Cai 406 (1998) 9

Çakmak, M. and G.P. Srivastava, Theoretical study of the GaAs(110)-(1×1)–H_2S surface 402–404 (1998) 658

Calarco, R., see Motta 406 (1998) 254

Caloi, R., see Magnano 402–404 (1998) 223

Calvayrac, F., see Kohl 405 (1998) 74

Calzado, C.J., see San Miguel 409 (1998) 92

Camarero, J., J.J. de Miguel, T. Graf, R. Miranda, W. Kuch, M. Zharnikov, A. Dittschar, C.M. Schneider and J. Kirschner, Tailoring epitaxial growth of low-dimensional magnetic structures by using surfactants 402–404 (1998) 346

Cambon, M., see Breton 406 (1998) 63

Campbell, C.T., see Yoshihara 406 (1998) 235

Campbell, C.T., see Yoshihara 407 (1998) 256

Campbell, J.M., see Yoshihara 406 (1998) 235

Campbell, P.A., L.J. Sinnamon, C.E. Thompson and D.G. Walmsley, Atomic force microscopy evidence for K^+ domains on freshly cleaved mica 410 (1998) L768

Canepa, M., see Ferro 407 (1998) 212

Car, R., see Musolino 402–404 (1998) 413

Carbone, M., M.N. Piancastelli, R. Zanoni, G. Comtet, G. Dujardin and L. Hellner, A low symmetry adsorption state of benzene on Si(111)7×7 studied by photoemission and photodesorption 407 (1998) 275

Carley, A.F., P.R. Davies and G.G. Mariotti, The oxidation of formic acid to carbonate at Cu(110) surfaces 401 (1998) 400

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Carpinelli, J.M., H.H. Weitering and E. Ward Plummer, Charge rearrangement in the Ge_xPb_{1-x}/Ge(111) interface 401 (1998) L457

Carrère, M., see Layet 402–404 (1998) 724

Carriere, B., see Barbier 405 (1998) 298

Casagrande, D., G.P. Srivastava and A.C. Ferraz, Theoretical calculations for Si(001)-(2×1)Cl 402–404 (1998) 653

Casanova, R., see Raza 402–404 (1998) 710

Casey, S.M., see Ott 405 (1998) 228

Castell, M.R., see Muggelberg 402–404 (1998) 673

Castellani, N.J., see Brizuela 401 (1998) 297

Castro Cal, J., see Motta 406 (1998) 254

Cavanagh, M., see Kravetsky 402–404 (1998) 542

Cederbaum, L.S., see Dobrodey 402–404 (1998) 508

Ceelen, W.C.A.N., A.W. Denier van der Gon, M.A. Reijme, H.H. Brongersma, I. Spolveri, A. Atrei and U. Bardi, Domain structure, segregation and morphology of the Pt_3Sn(111) surface 406 (1998) 264

Celestini, F., D. Passerone, F. Ercolessi and E. Tosatti, Realistic grand canonical Monte Carlo surface simulation: application to Ar(111) 402–404 (1998) 886

Cepek, C., see Libassi 402–404 (1998) 441

Cepek, C., see Laine 402–404 (1998) 871

Cepek, C., see Laine 402–404 (1998) 875

Cerdá, J., M.A. Van Hove, P. Sautet and M. Salmeron, The role of surface relaxations in determining the STM images of sulfur adatoms and clusters on Re(0001): theory versus experiment 409 (1998) 145

Ceva, T., see Madih-Ayadi 405 (1998) 192

Chambers, S.A., see Thevuthasan 401 (1998) 261

Champion, R.L., see Tucek 410 (1998) 258

Chan, C.T., see Che 401 (1998) L432

Chan, Y.L., P. Chuang, T.J. Chuang and R. Klauser, Vibrational study of methylene radical interaction on the Cu(111) surface 402–404 (1998) 125

Chandola, S., see Kravetsky 402–404 (1998) 542

Chang, C.-H., see Chen 406 (1998) 167

Chang, T.-C., see Hwang 410 (1998) L741

Charar, S., see Breton 406 (1998) 63

Chassé, A., see Niebergall 402–404 (1998) 628

Chassé, T., see Zerulla 402–404 (1998) 604

Chaturvedi, S. and J.A. Rodriguez, Interactions between Cs and noble metals (Cu, Ag, Au) on ZnO surfaces: electronic perturbations and alloy formation 401 (1998) 282

Chaturvedi, S., see Rodriguez 407 (1998) 171

Che, J.G. and C.T. Chan, Possible faceting transformation of Mo from (111) to {110} 401 (1998) L432

Chelikowsky, J.R., see Kim 409 (1998) 435

Chelly, R., see Angot 402–404 (1998) 52

Chen, C.-T., J.-R. Maa, Y.-M. Yang and C.-H. Chang, Effects of electrolytes and polarity of organic liquids on the coalescence of droplets at aqueous-organic interfaces 406 (1998) 167

Chen, C.L., see Jiang 405 (1998) L554

Chen, X., see Shen 408 (1998) 128

Chen, Y.F., Inelastic electron interactions in overlayers on substrates 407 (1998) 73

Cheng, C.-F., see Zhao 409 (1998) L703

Chey, S.J., Y. Gong and J.H. Weaver, Surface morphologies of Br-etched Ge/Si(001) 409 (1998) 421

Cheyssac, P., see Haderbache 410 (1998) L748

Chiarotti, G.L., see Scandolo 402–404 (1998) 808

Chilla, E., see Wedler 402–404 (1998) 290

Chorkendorff, I., see Larsen 405 (1998) 62

Chos, T., see Tabata 408 (1998) 137
Choso, T., see Tabata 402–404 (1998) 487
Choutov, D.A., see Winningham 406 (1998) 221
Christoph, J., see Colen 408 (1998) 310
Chu, C.W., see Jiang 405 (1998) L554
Chuang, P., see Chan 402–404 (1998) 125
Chuang, T.J., see Klauser 402–404 (1998) 87
Chuang, T.J., see Chan 402–404 (1998) 125
Chumak, A.A. and A.A. Tarasenko, The effect of reconstructed-surface order-parameter disturbances on adatom diffusion 409 (1998) 137
Chung, W.F., see Bartoš 402–404 (1998) 697
Clancy, P., see Levine 401 (1998) 112
Cobden, P.D., Y. van Breugel and B.E. Nieuwenhuys, Local independent oscillation centres present on an iridium field emitter during the NO–H_2 reaction 402–404 (1998) 155
Cocco, D., see Baraldi 401 (1998) L455
Cocco, D., see Wilde 405 (1998) 215
Cocco, D., see Polop 407 (1998) 268
Cocco, D., see Lizzit 410 (1998) 228
Colen, R.E.R., J. Christoph, F. Peña and H.H. Rotermund, Oxidation of CO on Pt(111) at intermediate pressures 408 (1998) 310
Coluzza, C., see Almeida 402–404 (1998) 470
Comelli, G., see Baraldi 401 (1998) L455
Comelli, G., see Wilde 405 (1998) 215
Comelli, G., see Lizzit 410 (1998) 228
Companò, R., see del Pennino 409 (1998) 258
Comsa, G., see Esser 402–404 (1998) 341
Comsa, G., see Rosenfeld 402–404 (1998) 401
Comsa, G., see Yinnon 410 (1998) L721
Comtet, G., see Carbone 407 (1998) 275
Contini, G., V. Di Castro, N. Motta and A. Sgarlata, Formation of a two-dimensional alloy/surface phase: Auger and STM study of Cu(Sn)(111) 405 (1998) L509
Convert, P., see Madih-Ayadi 405 (1998) 192
Cowie, B.C.C., see Dhanak 410 (1998) 321
Creighton, J.R. and K.C. Baucom, Reflectance-difference spectroscopy of adsorbate-covered GaAs(100) surfaces: a combined surface science and in-situ OMVPE study 409 (1998) 372
Cricenti, A., P. Perfetti and G. Le Lay, High-resolution Si 2p core-level photoemission spectroscopy on Sb-terminated Si(100) surfaces: evidence for a strong interfacial component 401 (1998) 427
Critchley, J.T.S., see De Asha 405 (1998) 201
Croset, B., see Madih-Ayadi 405 (1998) 192
Croset, B. and C. de Beauvais, Diffraction by a surface with terraces distribution: the Phase Matrix Method 409 (1998) 403
Cuesta, A., see Sistiaga 410 (1998) 312

Da Costa, V., see Barbier 405 (1998) 298
Da Silveira, E.F., S.B. Duarte and E.A. Schweikert, Multiplicity analysis: a study of secondary particle distribution and correlation 408 (1998) 28
Daimon, H., R. Ynzunza, J. Palomares, H. Takabi and Ch.S. Fadley, Direct structure analysis of W(110)-(1×1)-O by full solid-angle X-ray photoelectron diffraction with chemical-state resolution 408 (1998) 260
Danani, A., R. Ferrando, E. Scalas and M. Torri, Collective surface diffusion on a triangular lattice in presence of ordered phases 402–404 (1998) 281
Danani, A., R. Ferrando, E. Scalas and M. Torri, Collective surface diffusion on triangular and square interacting lattice gases 409 (1998) 117
Dastoor, P., see Quinton 402–404 (1998) 66
David, R., see Wetzig 402–404 (1998) 232
Davies, P.R., see Carley 401 (1998) 400
Davies, P.R., see Carley 406 (1998) L587
Dávila, M.E., see Lu 408 (1998) 326
Davydov, S.Y., On the concentration dependence of alkali metal desorption from the oxygen monolayer-covered tungsten surface 407 (1998) L652
Davydov, S.Y., Low-energy (⟨10 eV) O^+ ions transmission through alkali-metal submonolayers 408 (1998) 21
Däweritz, L., P. Schützendübe, M. Reiche and K.H. Ploog, Real-time analysis of Si monolayer formation on GaAs(001) during MBE 402–404 (1998) 257
De Asha, A.M., J.T.S. Critchley and R.M. Nix, Molecular adsorption characteristics of lanthanum oxide surfaces: the interaction of water with oxide overlayers grown on Cu(111) 405 (1998) 201
De Beauvais, C., see Croset 409 (1998) 403
De Crescenzi, M., see Motta 406 (1998) 254
De Gironcoli, S., see Lazzeri 402–404 (1998) 715
De Gironcoli, S., see Alfè 410 (1998) 151
De Haan, P., see Zemek 402–404 (1998) 529
De Miguel, J.J., see Camarero 402–404 (1998) 346
De Souza, L.M.M., see Giacomini 409 (1998) 465
Degroote, S., see Speller 405 (1998) L542
Dekoster, J., see Speller 405 (1998) L542
Del Pennino, U., see Biagi 402–404 (1998) 547
Del Pennino, U., R. Companò, B. Salvarani and C. Mariani, Alkali metal/GaAs(110) interfaces: correlation effects and sub-gap electron energy loss spectra 409 (1998) 258
Demirdjian, B., see Ferry 409 (1998) 101
Denanot, M.F., see Babonneau 409 (1998) 358
Deng, J.-F., see Shen 408 (1998) 128
Denier van der Gon, A.W., see Ceelen 406 (1998) 264
Dentel, D., J.L. Bischoff, T. Angot and L. Kubler, The influence of hydrogen during the growth of Ge films on Si(001) by solid source molecular beam epitaxy 402–404 (1998) 211
Dentel, D., J.L. Bischoff, D. Bolmont and L. Kubler, Reflection high-energy electron diffraction intensity oscillations during Si growth on Ge(001) by solid source molecular beam epitaxy 402–404 (1998) 304
DeSeta, M., see Laine 402–404 (1998) 871
DeSeta, M., see Laine 402–404 (1998) 875
Deslandes, Y., see Bensebaa 405 (1998) L472
Deville, J.-P., see Barbier 405 (1998) 298
Dhanak, V.R., see Shard 407 (1998) L623

Dhanak, V.R., A.G. Shard, B.C.C. Cowie and A. Santoni, The structures of sulphur on Pd(111) studied by X-ray standing wavefield absorption and surface EXAFS 410 (1998) 321
Di Bona, A., see Gazzadi 402–404 (1998) 632
Di Castro, V., see Contini 405 (1998) L509
Diekhöner, L., D.A. Butler, A. Baurichter and A.C. Luntz, Parallel pathways in methanol decomposition on Pt(111) 409 (1998) 384
Dippel, M., see Kohl 407 (1998) 104
Dittschar, A., see Camarero 402–404 (1998) 346
Dixon, R.J., see Bell 401 (1998) 125
Dixon, R.J., see Jenkins 402–404 (1998) 645
Dmitrieva, O., see Ollonqvist 402–404 (1998) 678
Dobrodey, N.V., L.S. Cederbaum and F. Tarantelli, Strong dynamical screening in weak chemisorption systems 402–404 (1998) 508
Doege, T., see Hagendorf 402–404 (1998) 581
Doering, M., H.-P. Rust, B.G. Briner and A.M. Bradshaw, Imaging benzene on nickel and copper {110} surfaces with low temperature STM: the adsorption site 410 (1998) L736
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Domenichini, B., see Pétigny 410 (1998) 250
Dooley, P. and S.L. Bernasek, Pooling analysis of scanning probe microscopy images 406 (1998) 206
Dorna, V., Z. Wang and U. Köhler, Gas source homoepitaxy on Si(113) – the interrelation of H-induced reconstructions and growth morphology 401 (1998) L375
Dose, V., see von der Linden 409 (1998) 290
Douglas, K., see Winningham 406 (1998) 221
Douillard, L., V.Yu. Aristov, F. Semond and P. Soukiassian, Pairs of Si atomic lines self-assembling on the β-SiC(100) surface: an 8×2 reconstruction 401 (1998) L395
Duarte, S.B., see da Silveira 408 (1998) 28
Dudek, M.R., J.-F. Gouyet and M. Kolb, Q+1 state Potts model of late stage sintering 401 (1998) 220
Dujardin, G., see Carbone 407 (1998) 275
Dumas, P., see Biagi 402–404 (1998) 547
Dunn, A.W., see Moriarty 405 (1998) 21
Dupont-Pavlovsky, N., see Madih-Ayadi 402–404 (1998) 836
Dupont-Pavlovsky, N., see Madih-Ayadi 405 (1998) 192
Durukanoğlu, S. and T.S. Rahman, Atomic relaxations and thermodynamics on Cu(410) 409 (1998) 395
Duval, X., see Madih-Ayadi 402–404 (1998) 836

Egebjerg, T., see Møller 402–404 (1998) 719
Eggeling, J., see Mulcahy 406 (1998) 294
Eibler, R., see Bihlmayer 402–404 (1998) 794
Eiswirth, M., see Bludau 402–404 (1998) 786
Ellis, T.H., see Bensebaa 405 (1998) L472
Elsayed-Ali, H.E., see Zhang 405 (1998) 271
Eltsov, K.N., see Andryushechkin 407 (1998) L633
Emery, D.A., P.H. Middleton and I.S. Metcalfe, The effect of electrochemical current pumping on the work function of solid electrolyte supported catalysts 405 (1998) 308
Emundts, A., G. Pirug, J. Werner and H.P. Bonzel, Large solid angle X-ray photoelectron intensity distributions from CO, methoxy, and formate adsorbed on Ni(110) 410 (1998) L727
Enders, A., see Sander 402–404 (1998) 351
Enders, A., see Schmidthals 402–404 (1998) 636
Engelmann, G.E., J.C. Ziegler and D.M. Kolb, Electrochemical fabrication of large arrays of metal nanoclusters 401 (1998) L420
Engstrom, J.R., see Levine 401 (1998) 112
Engstrom, J.R., see Zhang 402–404 (1998) 480
Ercolessi, F., see Celestini 402–404 (1998) 886
Erdös, D., see Wollschläger 402–404 (1998) 272
Erley, W., see Hsiao 405 (1998) L465
Ertl, G., see Bludau 402–404 (1998) 786
Esaulov, V.A., see Maazouz 409 (1998) 189
Esaulov, V.A., see Lacombe 410 (1998) 70
Espinós, J.P., see López-Carreño 402–404 (1998) 174
Esser, M., K. Morgenstern, G. Rosenfeld and G. Comsa, Dynamics of vacancy islands coalescence on Ag(111) 402–404 (1998) 341
Etterich, W., see Wetzig 402–404 (1998) 232
Evans, D.A., see Xue 401 (1998) L401
Evans, J.W., see Zhang 406 (1998) 178
Evans, J.W., see Tammaro 407 (1998) 162
Evans, M.M.R., J.C. Glueckstein and J. Nogami, Indium on Si(001): growth beyond the first atomic layer 406 (1998) 246

Fadley, Ch.S., see Thevuthasan 401 (1998) 261
Fadley, Ch.S., see Daimon 408 (1998) 260
Fahsold, G., W. Keller, O. Krauth and A. Lehmann, Infrared absorption of Fe ultrathin films on ionic crystals 402–404 (1998) 790
Fan, K., see Shen 408 (1998) 128
Faraci, G. and A.R. Pennisi, Ge(100)2×1 substoichiometric oxidation states promoted by a Cs overlayer 409 (1998) 46
Farle, M., see Bovensiepen 402–404 (1998) 396
Fasel, R., see Aebi 402–404 (1998) 614
Feliu, J.M., see Gómez 410 (1998) 48
Feng, H.H., see Jiang 405 (1998) L554
Fernandez, V., see Gießel 406 (1998) 90
Ferrando, R., see Danani 402–404 (1998) 281
Ferrando, R., F. Hontinfinde and A.C. Levi, Cluster morphology transitions in the submonolayer epitaxial growth of Ag on Ag(110) 402–404 (1998) 286
Ferrando, R., see Danani 409 (1998) 117
Ferrari, A., see Libassi 402–404 (1998) 441
Ferrario, M., see Marcellini 402–404 (1998) 47
Ferraz, A.C., see Casagrande 402–404 (1998) 653
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Fick, D., see Kleine 410 (1998) 15
Filleböck, G., see Kohl 407 (1998) 104
Finster, J., see Behrens 402–404 (1998) 729
Fischer, R., see von der Linden 409 (1998) 290
Flodström, A., see Yu 401 (1998) 236
Flores, F., see Jurczyszyn 402–404 (1998) 459
Fluchtmann, M., see Bansmann 402–404 (1998) 365
Fluchtmann, M., S. Bei der Kellen, J. Braun and G. Borstel, Relativistic full-potential photoemission for Cu(111) 402–404 (1998) 663
Foord, J.S., see Singh 409 (1998) 272
Franco, N., see Laine 402–404 (1998) 871
Franco, N., see Laine 402–404 (1998) 875
Frechard, F. and R.A. van Santen, Theoretical study of the adsorption of the atomic oxygen on the Cu(110) surface 407 (1998) 200
Frederick, B.G., see Perry 409 (1998) 512
French, C.R., see Gleason 405 (1998) 238
Freund, H.-J., see Stempel 402–404 (1998) 424
Freund, H.-J., see Wolter 402–404 (1998) 428
Freund, H.-J., see Brillo 409 (1998) 199
Friedrich, K.A., see Petukhov 402–404 (1998) 182
Friedrich, K.A., see Akemann 402–404 (1998) 571
Friemelt, K., see Rettenberger 402–404 (1998) 409
Friend, C.M., see Holbert 401 (1998) L437
Friend, C.M., see Queeney 407 (1998) 293
Fuchs, H., see Seidel 408 (1998) 223
Fujii, Y., T. Nakamura, M. Kai and K. Yoshida, In situ observation of layer-by-layer growth by surface X-ray scattering using a rotating-anode source 405 (1998) L549
Fujishima, A., see Jiang 408 (1998) 112
Fujita, T., see Tanaka 401 (1998) L407
Fujitani, T., see Nakamura 402–404 (1998) 92
Fukaya, Y., see Shigeta 402–404 (1998) 313
Fukuhara, T., see Hongo 402–404 (1998) 192
Fukui, M., see Hanamoto 409 (1998) 413

Gadzuk, J.W., see Persson 410 (1998) L779
Gai, Z., R.G. Zhao, H. Ji and W.S. Yang, Atomic structure of the Ge(001)-(7×5.5)-Ga surface 405 (1998) L484
Gao, J.N., see Zhao 406 (1998) L614
Gao, J.N., see Yang 406 (1998) 229
Garcia, N., J. Przeslawski and M. Sharonov, Giant conductance response to light pulses in metallic nanowires 407 (1998) L665
García de Abajo, F.J., see Aizpurua 402–404 (1998) 418
García-Hernández, M., P.S. Bagus and F. Illas, A new analysis of image charge theory 409 (1998) 69
Garnier, M., see Hengsberger 405 (1998) L491
Garnier, M., see Purdie 407 (1998) L671
Garrigos, R., see Haderbache 410 (1998) L748
Gautier, C., see Breton 406 (1998) 63
Gauyacq, J.-P., see Lorente 402–404 (1998) 197
Gauyacq, J.P., see Goryunov 401 (1998) 206
Gavioli, L., M.G. Betti and C. Mariani, Electronic properties of the Bi/Si(100) interface 409 (1998) 207
Gay, S.C.A., S.J. Jenkins and G.P. Srivastava, Ab-initio density functional calculations for Si(001)/Bi(1 ML)-(2×1) 402–404 (1998) 641
Gazzadi, G.C., A. Borghi, A. di Bona and S. Valeri, Epitaxial growth of CoO on the (001) surface of bct cobalt 402–404 (1998) 632
Gellman, A.J., see McFadden 409 (1998) 171
Gerber, R.B., see Yinnon 410 (1998) L721
Gergely, G., see Krawczyk 402–404 (1998) 491
Gerlach, R., see Balzer 402–404 (1998) 841
Getzlaff, M., see Bansmann 402–404 (1998) 365
Getzlaff, M., see Bansmann 402–404 (1998) 371
Getzlaff, M., M. Bode and R. Wiesendanger, Hydrogen adsorption on Gd(0001) 410 (1998) 189
Gewinner, G., see Schieffer 402–404 (1998) 318
Gewinner, G., see Angot 409 (1998) 350
Ghazali, A., see Vedmedenko 402–404 (1998) 391
Ghiaia, G., see Karlsson 407 (1998) L687
Giacomini, M.T., L.M.M. de Souza and E.A. Ticianelli, Spectroscopic ellipsometry investigation of the redox process of polypyrrole in several aqueous solutions 409 (1998) 465
Gibbs, D., see Watson 407 (1998) 59
Gierer, M., see Setzer 402–404 (1998) 782
Gießel, T., see Lindsay 405 (1998) L566
Gießel, T., O. Schaff, C.J. Hirschmugl, V. Fernandez, K.-M. Schindler, A. Theobald, S. Bao, R. Lindsay, W. Berndt, A.M. Bradshaw, C. Baddeley, A.F. Lee, R.M. Lambert and D.P. Woodruff, A photoelectron diffraction study of ordered structures in the chemisorption system Pd{111}-CO 406 (1998) 90
Gießel, T., see Böttcher 408 (1998) 212
Gil, F.P., see Aebi 402–404 (1998) 614
Gillan, M.J., see Bates 409 (1998) 336
Gillis, H.P., see Winningham 406 (1998) 221
Gilmore, C.J., see Landree 408 (1998) 300
Giordano, L., see Ferry 409 (1998) 101
Giovanelli, L., see Libassi 402–404 (1998) 441
Girard, J.C., see Babonneau 409 (1998) 358
Girardet, C., see Ferry 409 (1998) 101
Giudice, E., E. Magnano, S. Rusponi, C. Boragno and U. Valbusa, Morphology of C60 thin films grown on Ag(001) 405 (1998) L561
Gland, J.L., see Ranney 401 (1998) 1
Glans, P.-A., see Johansson 405 (1998) 288
Gleason, N.R., C.J. Jenks, C.R. French, B.E. Bent and F. Zaera, Adsorption and thermal decomposition of n-azopropane on Pt(111) 405 (1998) 238
Glebov, A., see Benedek 406 (1998) L621
Glöckler, K., see Umbach 402–404 (1998) 20
Glöckler, K., C. Seidel, A. Soukopp, M. Sokolowski, E. Umbach, M. Böhringer, R. Berndt and W.-D. Schneider, Highly ordered structures and submolecular scanning tunnelling microscopy

contrast of PTCDA and DM-PBDCI monolayers on Ag(111) and Ag(110) 405 (1998) 1
Glueckstein, J.C., see Evans 406 (1998) 246
Goapper, S., L. Barbier and B. Salanon, Step pairing induced by surface alloying: Pd/Cu(1, 1, 11) 409 (1998) 81
Goddard, D.T., see Muggelberg 402–404 (1998) 673
Goldoni, A., see Laine 402–404 (1998) 871
Goldoni, A., see Laine 402–404 (1998) 875
Gomer, R., see Whitten 409 (1998) 16
Gómez, R., J.M. Feliu, A. Aldaz and M.J. Weaver, Validity of double-layer charge-corrected voltammetry for assaying carbon monoxide coverages on ordered transition metals: comparisons with adlayer structures in electrochemical and ultrahigh vacuum environments 410 (1998) 48
Gómez-Rodriguez, J.-M., see Veuillen 402–404 (1998) 295
Gong, Y., see Chey 409 (1998) 421
González-Elipe, A.R., see López-Carreño 402–404 (1998) 174
González Velasco, J., A theoretical explanation of the surface diffusion mechanism in metal electrodes in contact with electrolytes 410 (1998) 283
Goodman, D.W., see Street 407 (1998) 296
Goringe, C.M. and D.R. Bowler, Rotation of a silicon dimer over the trench between dimer rows on the Si(001) surface 407 (1998) L681
Goryunov, D.G., A.G. Borisov, G.E. Makhmetov, D. Teillet-Billy and J.P. Gauyacq, Li^+ neutralisation in back-scattering from alkali/Al(100) surfaces: comparison between the various alkalis 401 (1998) 206
Göthelid, M., see Lu 408 (1998) 326
Gotoh, Y., see Kawanowa 410 (1998) 141
Gouyet, J.-F., see Dudek 401 (1998) 220
Graf, T., see Camarero 402–404 (1998) 346
Granow, J., see Brüning 402–404 (1998) 215
Granozzi, G., see Møller 402–404 (1998) 719
Grätzel, M., see Selloni 402–404 (1998) 219
Greber, T., see Brandt 402–404 (1998) 160
Greber, T., see Wetli 402–404 (1998) 551
Greenlief, C.M., see Lee 410 (1998) L773
Grioni, M., see Vobornik 402–404 (1998) 761
Grube, H. and J.J. Boland, Origin of homoepitaxial faulted island growth on the Si(111) surface 407 (1998) 152
Grüne, M., J. Radnik and K. Wandelt, Reaction of nitrogen with fcc- and bcc-iron films on copper(100) 402–404 (1998) 236
Grupp, C. and A. Taleb-Ibrahimi, Huge charge transfer from potassium on H:Si(111)-(1×1) 408 (1998) 160
Guillemot, L., see Maazouz 409 (1998) 189
Guillemot, L., see Lacombe 410 (1998) 70
Gülseren, O., D.M. Bird and S.E. Humphreys, A mixed-basis approach for the efficient calculation of potential energy surfaces 402–404 (1998) 827
Guo, L.W., Q. Huang, Y.K. Li, S.L. Ma, C.S. Peng and J.M. Zhou, Critical Ge concentration for $2\times n$ reconstruction appearing on GeSi covered Si(100) 406 (1998) L592
Guo, X.-Y., B. Zhong and P. Brault, Growth and ripening of two-dimensional palladium islands on Ni(111) surface 409 (1998) 452
Gustafsson, T., see Busch 407 (1998) 7
Gutdeutsch, U., see Birkenheuer 409 (1998) 213
Gutiérrez, C., see Sistiaga 410 (1998) 312

Ha, J.S., see Park 405 (1998) 46
Haack, N., see Srivastava 402–404 (1998) 818
Haase, J., see Polcik 405 (1998) 112
Haase, J., see Wilde 405 (1998) 215
Habraken, F.H.P.M., see Roosendaal 402–404 (1998) 135
Hadenfeldt, S. and C. Benndorf, Adsorption of fluorine and chlorine on the diamond (100) surface 402–404 (1998) 227
Haderbache, L., R. Garrigos, R. Kofman, E. Søndergard and P. Cheyssac, Numerical and experimental investigations of the size ordering of nanocrystals 410 (1998) L748
Hafner, J., see Raybaud 407 (1998) 237
Haftel, M.I. and M. Rosen, New ballistically and thermally activated exchange processes in the vapor deposition of Au on Ag(111): a molecular dynamics study 407 (1998) 16
Hagen, C.W., see Aristov 402–404 (1998) 337
Hagendorf, Ch., K.-M. Schindler, T. Doege and H. Neddermeyer, An STM, XPS and LEED investigation of the $BaTiO_3$(111) surface 402–404 (1998) 581
Hamers, R.J., see Hovis 402–404 (1998) 1
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Handschuh, M., see Nettesheim 401 (1998) L452
Hanf, M.C., see Schieffer 402–404 (1998) 318
Hansen, P.E., see Kirilyuk 402–404 (1998) 356
Haq, S., see Barlow 401 (1998) 322
Haq, S., see Perry 409 (1998) 512
Harada, M., see Suto 402–404 (1998) 523
Haraguchi, M., see Hanamoto 409 (1998) 413
Harbsmeier, F., see Kravetsky 402–404 (1998) 542
Hardman, P.J., see Wincott 402–404 (1998) 705
Hart, J.F. and J.L. Beeby, A multiple-scattering approach to X-ray photoelectron diffraction 410 (1998) L757
Hasegawa, S., M. Maruyama, Y. Hirata, D. Abe and H. Nakashima, New model for Si(111)-(3×1)Li through determination of its surface Si atom density with the use of scanning tunneling microscopy 405 (1998) L503
Hasegawa, S., see Tong 408 (1998) 146
Hashimoto, K., see Jiang 408 (1998) 112
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Hausmann, S., see Limburg 409 (1998) 541
Hayoz, J., see Aebi 402–404 (1998) 614

He, Z., see Bartoš 402–404 (1998) 697
Hebenstreit, W., see Hofer 405 (1998) L514
Hecht, T., H. Winter and A.G. Borisov, Auger transition rates for the neutralization of He^+ ions in front of an aluminium surface 406 (1998) L607
Heckmann, O., see Bencok 402–404 (1998) 327
Heckmann, O., see Huttel 402–404 (1998) 609
Heiland, W., see Brüning 402–404 (1998) 215
Heiland, W., see Kuntze 402–404 (1998) 764
Heiland, W., see Aschoff 402–404 (1998) 770
Heiland, W., see Limburg 409 (1998) 541
Heinz, B. and H. Morgner, A metastable induced electron spectroscopy study of graphite. The k-vector dependence of the ionization probability 405 (1998) 104
Heinz, K., see Prieto 401 (1998) 248
Heinz, K., see Hammer 401 (1998) 455
Heinzmann, U., see Brandt 402–404 (1998) 160
Heitmann, D., see Schumacher 408 (1998) 203
Held, G., W. Sklarek, M. Mayan and H.-P. Steinrück, Characterization of thin copper films on Ni(111) by CO titration 402–404 (1998) 322
Hellgren, N., see Johansson 405 (1998) 288
Hellner, L., see Carbone 407 (1998) 275
Hellwig, O., K. Theiss-Bröhl, G. Wilhelmi and H. Zabel, Growth of fcc(111) on bcc(110): Influence of growth and annealing temperature on epitaxy and surface morphology for Pd on Cr 410 (1998) 362
Henderson, M.A., see Overbury 410 (1998) 106
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Hengsberger, M., see Purdie 407 (1998) L671
Henzler, M., see Malaske 408 (1998) 237
Heras, J.M., see López-Carreño 402–404 (1998) 174
Herman, G.S., see Thevuthasan 401 (1998) 261
Herman, G.S., see Overbury 410 (1998) 106
Hervieu, Y.Y. and M.P. Ruzaikin, Surface processes of impurity incorporation during MBE growth 408 (1998) 57
Hesjedal, T., see Wedler 402–404 (1998) 290
Heskett, D., see Strisland 410 (1998) 330
Hibma, T., see James 402–404 (1998) 332
Himpsel, F.J., see Petrovykh 407 (1998) 189
Hinnen, C., see Kitakatsu 407 (1998) 36
Hirata, Y., see Hasegawa 405 (1998) L503
Hirsch, G., P. Krüger and J. Pollmann, Surface passivation of GaAs(001) by sulfur: ab-initio studies 402–404 (1998) 778
Hirschmugl, C.J., see Gießel 406 (1998) 90
Hirsimäki, M., S. Suhonen, J. Pere, M. Valden and M. Pessa, Adsorption, desorption and surface reactions of CO and NO on Pd{320} 402–404 (1998) 187
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Hoang, P.N.M., see Ferry 409 (1998) 101
Hochstrasser, M., see Wetli 402–404 (1998) 551
Hoekstra, R., see Limburg 409 (1998) 541
Höfer, U., see Raschke 410 (1998) 351
Hofer, W., see Mezey 402–404 (1998) 845
Hofer, W.A., G. Ritz, W. Hebenstreit, M. Schmid, P. Varga, J. Redinger and R. Podloucky, Scanning tunneling microscopy of binary-alloy surfaces: is chemical contrast a consequence of alloying? 405 (1998) L514
Hoffmann, S.V., see Nerlov 401 (1998) 56
Hogan, C.D. and C.H. Patterson, Reflectance anisotropies of silicon surfaces: analysis of spectra in terms of surface excess susceptibilities 402–404 (1998) 586
Holbert, A.W., J.D. Batteas, A. Wong-Foy, T.S. Rufael and C.M. Friend, Passivation of Fe(110) via phosphorus deposition: the reactions of trimethylphosphite 401 (1998) L437
Hollering, M., see Xue 401 (1998) L401
Holroyd, R.P., see Poulston 402–404 (1998) 599
Holze, R., see Kania 408 (1998) 252
Hongo, S., see Ojima 402–404 (1998) 150
Hongo, S., S. Kaneko, T. Fukuhara and T. Urano, Coadsorption of lithium and hydrogen on Si(100)2×1 surfaces studied by metastable de-excitation spectroscopy and thermal desorption spectroscopy 402–404 (1998) 192
Hongo, S., see Takeda 402–404 (1998) 692
Hongo, S., see Tamiya 408 (1998) 268
Hontinfinde, F., see Ferrando 402–404 (1998) 286
Horch, S., see Linderoth 402–404 (1998) 308
Horley, G., see Mulcahy 406 (1998) 294
Horn-von Hoegen, M., H. Minoda, K. Yagi, F. Meyer zu Heringdorf and D. Kähler, Macroscopic one-dimensional faceting of Si(100) upon Au adsorption 402–404 (1998) 464
Hovis, J.S., H. Liu and R.J. Hamers, Cycloaddition chemistry and formation of ordered organic monolayers on silicon (001) surfaces 402–404 (1998) 1
Hrbek, J., see Rodriguez 407 (1998) 171
Hricovini, K., see Bencok 402–404 (1998) 327
Hricovini, K., see Huttel 402–404 (1998) 609
Hsiao, G.S., W. Erley and H. Ibach, Probing the surface acidity of single crystal alumina surfaces: CO adsorption as measured by infrared reflection absorption spectroscopy 405 (1998) L465
Hsieh, M.L., see Zhang 402–404 (1998) 480
Hu, Z.-M., H. Nakai and H. Nakatsuji, Oxidation mechanism of propylene on an Ag surface: dipped adcluster model study 401 (1998) 371
Huang, Q., see Guo 406 (1998) L592
Huang, Z.J., see Jiang 405 (1998) L554
Huisinga, M., see Reichling 402–404 (1998) 145
Huisinga, M., see Puchina 402–404 (1998) 687
Huisman, W.J. and J.F. van der Veen, Modelling the atomic density across a solid–liquid interface 402–404 (1998) 866
Humphreys, S.E., see Gülseren 402–404 (1998) 827
Huntley, D.R., see Mullins 409 (1998) 307
Hüsken, H., B. Schröter and Wo. Richter, Surface state dispersion on the β-SiC(111)-(3×3) surface 407 (1998) L676

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Hyland, Jr., R.W., see Lee 408 (1998) 288

Ibach, H., see Kröger 402–404 (1998) 496
Ibach, H., see Hsiao 405 (1998) L465
Ichikawa, M., see Watanabe 408 (1998) 95
Ichimura, S., see Nakamura 402–404 (1998) 165
Igel, T., R. Pfandzelter and H. Winter, Proton-induced Auger electrons from ultrathin Mn films on Fe(100) 405 (1998) 182
Ihm, H., see Lee 410 (1998) L773
Iimori, T., see Hattori 402–404 (1998) 170
Ikeda, A., see Nishimura 409 (1998) 183
Ilakovac, V., see Bencok 402–404 (1998) 327
Ilakovac, V., see Huttel 402–404 (1998) 609
Illas, F., see García-Hernández 409 (1998) 69
Imanishi, A., see Matsui 401 (1998) L413
Imanishi, A., K. Isawa, F. Matsui, T. Tsuduki, T. Yokoyama, H. Kondoh, Y. Kitajima and T. Ohta, Structural studies of adsorbed alkanethiols on Cu(111) by use of S and C K-edge X-ray absorption fine structures 407 (1998) 282
Imbihl, R., see Suchorski 401 (1998) 392
Imbihl, R., see Suchorski 405 (1998) L477
Imbihl, R., see Tammaro 407 (1998) 162
Inenaga, H., see Naitoh 402–404 (1998) 623
Ino, S., see Takami 407 (1998) 140
Ino, S., see Tong 408 (1998) 146
Isawa, K., see Matsui 401 (1998) L413
Isawa, K., see Imanishi 407 (1998) 282
Itoh, K., see Akita 405 (1998) 172
Iwasawa, Y., Dynamic oxide interfaces by microscopic techniques at high resolutions 402–404 (1998) 8
Iyoda, T., see Jiang 408 (1998) 112

Jablonski, A., see Krawczyk 402–404 (1998) 491
Jacobi, K., see Setzer 402–404 (1998) 782
Jacobs, K., see Kohl 407 (1998) 104
Jaegermann, W., see Kamaratos 402–404 (1998) 37
James, M.A., F.C. Voogt, L. Niesen, O.C. Rogojanu and T. Hibma, The role of interfacial structure in determining magnetic behaviour in MBE-grown Fe_3O_4–MgO multilayers on MgO(001) 402–404 (1998) 332
Janda, P., see Zemek 402–404 (1998) 529
Janin, E., see Lu 408 (1998) 326
Jankowski, Z., see Mróz 402–404 (1998) 263
Jaworowski, A.J., see Strisland 410 (1998) 330
Jenkins, S.J., see Tütüncü 402–404 (1998) 42
Jenkins, S.J., see Gay 402–404 (1998) 641
Jenkins, S.J., G.P. Srivastava, R.J. Dixon and C.F. McConville, Ab initio calculation of geometry and bonding for overlaid and inlaid models of Si(001)/Sb(0.25 ML)-c(4×4) 402–404 (1998) 645
Jenks, C.J., see Gleason 405 (1998) 238
Jenks, C.J., see Zhang 406 (1998) 178
Jenniches, H., see Lin 410 (1998) 290
Jenniskens, H.G., W. van Essenberg, M. Kadodwala and A.W. Kleyn, The adsorption of tert-butyl nitrite on Ag(111) 402–404 (1998) 140
Ji, H., see Gai 405 (1998) L484
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Jin, P., see Jiang 405 (1998) L554
Jirsak, T., see Rodriguez 407 (1998) 171
Johansson, L.I., P.-A. Glans and N. Hellgren, A core level and valence band photoemission study of 6H-SiC(000$\bar{1}$) 405 (1998) 288
Johnson, A.D., see Jones 409 (1998) 27
Johnson, R.L., see Layet 402–404 (1998) 724
Jones, A.C., see Mulcahy 406 (1998) 294
Jones, I.Z., see Bennett 401 (1998) 72
Jones, I.Z., R.A. Bennett and M. Bowker, CO adsorption on Pd(110) 402–404 (1998) 595
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Jones, T.S., see Bell 405 (1998) 280
Jones, T.S., see Mulcahy 406 (1998) 294
Jones, T.S., see Belk 410 (1998) 82
Joyce, B.A., see Zhang 402–404 (1998) 480
Joyce, B.A., see Tejedor 407 (1998) 82
Joyce, B.A., see Belk 410 (1998) 82
Jung, D., D.-K. Seo, J. Ren and M.-H. Whangbo, Simulation of the scanning tunneling and atomic force microscopy images of a xanthine monolayer on graphite 401 (1998) 476
Jung, T., see Petrovykh 407 (1998) 189
Jupille, J., see Martin 402–404 (1998) 433
Jurczyszyn, L., N. Mingo and F. Flores, Influence of the atomic and electronic structure of the tip on STM images and STS spectra 402–404 (1998) 459

Kadodwala, M., see Jenniskens 402–404 (1998) 140
Kageshima, H. and K. Shiraishi, Theoretical study of the band offset at silicon-oxide/silicon interfaces with interfacial defects 407 (1998) 133
Kähler, D., see Horn-von Hoegen 402–404 (1998) 464
Kai, M., see Fujii 405 (1998) L549
Kaijaks, N.S., see Bell 401 (1998) 125
Kaiser, B., see Bernhardt 408 (1998) 86

Kakizaki, A., see An 401 (1998) 336
Kallinger, C., see Roy 407 (1998) 1
Kamakura, N., see An 401 (1998) 336
Kamaratos, M., V. Saltas, C.A. Papageorgopoulos, W. Jaegermann, C. Pettenkofer and D. Tonti, Interaction of Na and Cl_2 on WSe_2(0001) surfaces: chlorine-induced Na deintercalation 402–404 (1998) 37
Kamaratos, M., see Papageorgopoulos 402–404 (1998) 120
Kamberský, V., see Zemek 402–404 (1998) 529
Kamei, M., see Kawanowa 410 (1998) 141
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Kanayama, T., see Tanaka 406 (1998) L603
Kaneko, S., see Hongo 402–404 (1998) 192
Kang, H.C., see Yang 409 (1998) 521
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Kardinal, I., F.P. Netzer and M.G. Ramsey, Determination of azimuthal orientation with impact scattering? Bithiophene on Ni(110) p(4×1)-S 405 (1998) L520
Karis, O., see Hasselström 407 (1998) 221
Karkin, A., see Vobornik 402–404 (1998) 761
Karlsson, H.S., R. Viselga and U.O. Karlsson, Electron accumulation at the InAs(110) cleavage surface 402–404 (1998) 590
Karlsson, H.S., G. Ghiaia and U.O. Karlsson, Electron dynamics and accumulation on the InAs(110) surface 407 (1998) L687
Karlsson, U.O., see Karlsson 402–404 (1998) 590
Karlsson, U.O., see Karlsson 407 (1998) L687
Kasai, H., see Kawahito 409 (1998) L709
Kasaya, M., H. Tabata and T. Kawai, Scanning tunneling microscopy and molecular orbital calculation of organic molecules adsorbed on the Si(100)2×1 surface 406 (1998) 302
Kasemo, B., see Zhdanov 405 (1998) 27
Kasuya, A., see Suto 402–404 (1998) 523
Katayama, M., see Ryu 401 (1998) L425
Katayama, T., see Kirilyuk 402–404 (1998) 356
Kato, M., see Sonoda 402–404 (1998) 241
Kawahito, Y., H. Kasai, H. Nakanishi and A. Okiji, Effects of intrasite Coulomb interaction on quantized conductance in a quantum wire between an STM tip and a metal surface 409 (1998) L709
Kawai, T., see Kasaya 406 (1998) 302
Kawanowa, H., M. Kamei and Y. Gotoh, Surface structures of Si deposited on W(110) surface 410 (1998) 141
Kazmiruk, V.V., see Aristov 402–404 (1998) 337
Keller, W., see Fahsold 402–404 (1998) 790
Kelley, R.J., see Vobornik 402–404 (1998) 761
Kempter, V., see Reichling 402–404 (1998) 145
Kempter, V., see Takami 407 (1998) 140
Kern, K., see Kampshoff 406 (1998) 103
Kern, K., see Kampshoff 406 (1998) 117
Kido, Y., see Nishimura 409 (1998) 183
Kikuchi, A. and S. Tsuneyuki, Electronic structure and charge density wave state in polytypes of $NbSe_2$ 409 (1998) 458
Kim, H. and J.R. Chelikowsky, Electronic and structural properties of the As vacancy on the (110) surface of GaAs 409 (1998) 435
Kim, H.J., see Layet 402–404 (1998) 724
Kim, K.-S., Y. Takakuwa, T. Abukawa and S. Kono, RHEED-AES observation of In desorption on a single-domain Si(001)-(1×2) surface 410 (1998) 99
Kim, Y.J., see Thevuthasan 401 (1998) 261
Kimpara, H., see Watanabe 402–404 (1998) 100
Kimura, A., see An 401 (1998) 336
King, D.A., see Kose 402–404 (1998) 856
Kino, N., see Jiang 408 (1998) 112
Kinzel, W., see Schinzer 401 (1998) 96
Kirilyuk, A., P.E. Hansen, S. Yuasa, T. Katayama and Th. Rasing, Nonlinear magneto-optical response from quantum well states in an Fe(001) wedge 402–404 (1998) 356
Kirschner, J., see Camarero 402–404 (1998) 346
Kirschner, J., see Sander 402–404 (1998) 351
Kirschner, J., see Schmidthals 402–404 (1998) 636
Kirschner, J., see Shen 407 (1998) 90
Kirschner, J., see Lin 410 (1998) 290
Kiskinova, M., see Lizzit 410 (1998) 228
Kitajima, Y., see Imanishi 407 (1998) 282
Kitakatsu, N., V. Maurice, C. Hinnen and P. Marcus, Surface hydroxylation and local structure of NiO thin films formed on Ni(111) 407 (1998) 36
Kitazawa, K., see Jiang 408 (1998) 112
Kitching, K.J., see Barlow 401 (1998) 322
Kladny, R., see Popp 401 (1998) 105
Klamroth, T. and P. Saalfrank, A tight-binding Green's function approach to adsorbate electronic ground and excited states and their lifetimes 410 (1998) 21
Klaua, M., see Lin 410 (1998) 290
Klauser, R., P.S. Asoka Kumar and T.J. Chuang, The interaction of Ga and N on SiC and $LiGaO_2$ surfaces studied by synchrotron radiation photoemission 402–404 (1998) 87
Klauser, R., see Chan 402–404 (1998) 125
Kleine, H., H. Bludau, H. Over and D. Fick, The 3×1-Li to 7×7 structural transformation of Si(111) due to Li desorption 410 (1998) 15
Kleyn, A.W., see Jenniskens 402–404 (1998) 140
Kleyna, R., D. Borgmann and G. Wedler, Adsorption and reaction of propene on Ni(100) 402–404 (1998) 131
Klimchitskaya, G.L., see Blagov 410 (1998) 158
Klinkenberg, E.-D., see Behrens 402–404 (1998) 729
Klivényi, G., see Solymosi 409 (1998) 241
Kobayashi, E., T. Wakasugi, G. Mizutani and S. Ushioda, Optical second harmonic spectroscopy of rutile TiO_2(110) in air 402–404 (1998) 537
Koch, R., see Wedler 402–404 (1998) 290

Koch, R. and M. Sturmat, High-temperature STM of the phase transitions of Au(110) and Pt(110) 402–404 (1998) 861
Kocinski, J., see Wierzbicki 402–404 (1998) 382
Koel, B.E., see Peck 410 (1998) 170
Koel, B.E., see Peck 410 (1998) 200
Koel, B.E., see Peck 410 (1998) 214
Koel, B.E., see Saliba 410 (1998) 270
Kofman, R., see Haderbache 410 (1998) L748
Koguchi, N., see Shimoda 402–404 (1998) 669
Kohl, C., F. Calvayrac, P.-G. Reinhard and E. Suraud, Optical response of Na clusters on NaCl surfaces 405 (1998) 74
Kohl, U., M. Dippel, G. Filleböck, K. Jacobs, B.-U. Runge and G. Schatz, Local magnetism of ultrathin fcc-Co films on Cu(100) investigated by ^{111}In probes 407 (1998) 104
Köhler, U., see Dorna 401 (1998) L375
Kolb, D.M., see Engelmann 401 (1998) L420
Kolb, D.M., see Bohnen 407 (1998) L629
Kolb, M., see Dudek 401 (1998) 220
Köller, L., see Bettac 402–404 (1998) 475
Komeda, T. and Y. Nishioka, Atomic structure of segregated boron on Si(001) surface; scanning tunneling microscopy and cluster model calculation study 405 (1998) 38
Komori, F., see Hattori 402–404 (1998) 170
Kondoh, H., see Nakamura 402–404 (1998) 701
Kondoh, H., see Imanishi 407 (1998) 282
Konishi, A., see Naitoh 402–404 (1998) 623
Kono, S., see Kim 410 (1998) 99
Kortlüke, O. and W. von Niessen, A Monte Carlo simulation of the CO+NO surface reaction involving molecular NO adsorption and several reaction paths 401 (1998) 185
Kose, R., W.A. Brown and D.A. King, Calorimetric heats of dissociative adsorption for O_2 on Rh{100} 402–404 (1998) 856
Koshikawa, T., see Nishimura 409 (1998) 183
Kosobukin, V.A., Magneto-optics via the near field 406 (1998) 32
Koto, K., see Hanamoto 409 (1998) 413
Kotrla, M., M. Předota and F. Slanina, Kinetic roughening and phase ordering in the two-component growth model 402–404 (1998) 249
Kottcke, M., see Hammer 401 (1998) 455
Kovac, J., see Magnano 402–404 (1998) 223
Krapf, P., see Phaner-Goutorbe 402–404 (1998) 268
Krauth, O., see Fahsold 402–404 (1998) 790
Kravetsky, I.V., L.L. Kulyuk, J.F. McGilp, M. Cavanagh, S. Chandola, J. Boness, G. Marowsky and F. Harbsmeier, A study of ion-implanted Si(111) and Si(111)/silicon oxide by optical second harmonic generation 402–404 (1998) 542
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Krembel, C., see Schieffer 402–404 (1998) 318
Kresse, G., see Raybaud 407 (1998) 237
Kresse, G., see Bates 409 (1998) 336
Kreutz, T.J., see Wetli 402–404 (1998) 551
Kreutz, T.J., see Aebi 402–404 (1998) 614
Kröger, J., S. Lehwald and H. Ibach, Substrate surface phonons in the cases of saturated (1×1)H/Mo(110) and p(2×2)O/Mo(110) – a critical comparison 402–404 (1998) 496
Kronik, L., see Aphek 409 (1998) 485
Kroto, H.W., see Upward 405 (1998) L526
Kruft, M., see Wilms 402–404 (1998) 83
Krüger, P., see Vogel 402–404 (1998) 774
Krüger, P., see Hirsch 402–404 (1998) 778
Kruit, P., see Aristov 402–404 (1998) 337
Kruse, N., see Medvedev 401 (1998) L371
Kruse, N., see Voss 409 (1998) 252
Kruus, E., see Bensebaa 405 (1998) L472
Kryzowski, M.A., see Yinnon 410 (1998) L721
Kubler, L., see Dentel 402–404 (1998) 211
Kubler, L., see Dentel 402–404 (1998) 304
Kuch, W., see Camarero 402–404 (1998) 346
Kuch, W., see Lin 410 (1998) 290
Kucherenko, Yu., see Niebergall 402–404 (1998) 628
Kudryashov, V.A., see Aristov 402–404 (1998) 337
Kuhlenbeck, H., see Wolter 402–404 (1998) 428
Kuhlenbeck, H., see Brillo 409 (1998) 199
Kuhlmann, F., see Brandt 402–404 (1998) 160
Kui, K., see Ryu 401 (1998) L425
Kulyuk, L.L., see Kravetsky 402–404 (1998) 542
Kunimori, K., see Watanabe 402–404 (1998) 100
Kunimori, K., see Kuriyama 402–404 (1998) 178
Kuntze, J., S. Speller and W. Heiland, The Ir(110) surface studied by STM 402–404 (1998) 764
Küppers, J., see Popp 401 (1998) 105
Kuriyama, T., K. Kunimori and H. Nozoye, Interaction of CO with the SmO_X/Ru(001) interface 402–404 (1998) 178
Kurokawa, A., see Nakamura 402–404 (1998) 165
Kuwahara, M., see Hanamoto 409 (1998) 413

Lacharme, J.-P., see Zaïbi 402–404 (1998) 206
Lacharme, J.-P., see Akremi 402–404 (1998) 746
Lacombe, S., L. Guillemot, M. Maazouz, N. Mandarino, E. Sanchez and V.A. Esaulov, Scattering of He and Ne atoms and ions on a Na surface 410 (1998) 70
Ladas, S., see Sotiropoulou 408 (1998) 182
Laine, A.D., M. DeSeta, C. Cepek, S. Vandré, A. Goldoni, N. Franco, J. Avila, M.C. Asensio and M. Sancrotti, Surface phase transitions of Ge(100) studied via valence band photoemission 402–404 (1998) 871
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Laio, A., see Santoro 402–404 (1998) 880
Lam, H.T., N. Venkateswaran and J.M. Vohs, The reactions of diethylzinc on gallium-rich and arsenic-rich reconstructions of GaAs(100) 401 (1998) 34
Lambert, R.M., see Gießel 406 (1998) 90

Landree, E., L.D. Marks, P. Zschack and C.J. Gilmore, Structure of the TiO_{2-x}(100)-1×3 surface by direct methods 408 (1998) 300
Langouche, G., see Speller 405 (1998) L542
Larese, J.Z., see Asmussen 406 (1998) 138
Larsen, J.H. and I. Chorkendorff, Increased dissociation probability of CH_4 on Co/Cu(111) 405 (1998) 62
Latyshev, A.V., H. Minoda, Y. Tanishiro and K. Yagi, Electromigration and gold-induced step bunching on the Si(111) surface 401 (1998) 22
Layet, J.M., M. Carrère, H.J. Kim, R.L. Johnson, R. Belkhou, V. Zhilin, V.Yu. Aristov and G. Le Lay, Two-dimensional electron gas at InAs(100)1×2/1×4 Pb 402–404 (1998) 724
Lazzeri, M. and S. de Gironcoli, Ab-initio dynamical properties of the Be(0001) surface 402–404 (1998) 715
Le Lay, G., see Cricenti 401 (1998) 427
Le Lay, G., see Layet 402–404 (1998) 724
Leckey, R.C.G., see Xue 401 (1998) L401
Lee, A.F., see Gießel 406 (1998) 90
Lee, E.-H., see Park 405 (1998) 46
Lee, H.K., R.W. Hyland, Jr., H.I. Aaronson and P.P. Wynblatt, Surface segregation in an Al–4.2 at% Ag alloy 408 (1998) 288
Lee, S.W., L.N. Nelen, H. Ihm, T. Scoggins and C.M. Greenlief, Reaction of 1, 3-cyclohexadiene with the Ge(100) surface 410 (1998) L773
Lees, A.K., see Zhang 402–404 (1998) 480
Lehmann, A., see Fahsold 402–404 (1998) 790
Lehwald, S., see Kröger 402–404 (1998) 496
Leibovitch, M., see Aphek 409 (1998) 485
Leibsle, F.M., Clues to identifying methoxy and formate structures in scanning tunneling microscopy experiments 401 (1998) 153
Leiderer, P., see Rettenberger 402–404 (1998) 409
Leising, G., see Resel 409 (1998) 302
Leone, S.R., see Ott 405 (1998) 228
Lesniewska, E., see Pétigny 410 (1998) 250
Leung, K.T., see Yu 401 (1998) 269
Levashov, V.I., see Aristov 402–404 (1998) 337
Lévêque, G., see Oueini 410 (1998) 132
Levi, A.C., see Ferrando 402–404 (1998) 286
Levine, S.W., J.R. Engstrom and P. Clancy, A kinetic Monte Carlo study of the growth of Si on Si(100) at varying angles of incident deposition 401 (1998) 112
Lévy, J.-C.S., see Vedmedenko 402–404 (1998) 391
Ley, L., see Xue 401 (1998) L401
Lægsgaard, E., see Linderoth 402–404 (1998) 308
Lægsgaard, E., see Rosenfeld 402–404 (1998) 401
Lægsgaard, E., see Bach Aaen 408 (1998) 43
Li, X.Q., see Cai 406 (1998) 9
Li, Y., C. Polaczyk and D. Riegel, Thickness and magnetic field dependence of the ferromagnetism of ultrathin Gd films in Gd/W multilayers 402–404 (1998) 386
Li, Y.K., see Guo 406 (1998) L592
Li, Z.Q., Y. Qin and H. Shen, Surface structure variation caused by annealing 408 (1998) 123
Li, Z.S., see Møller 402–404 (1998) 719
Li, Z.Y., see Luo 402–404 (1998) 437
Libassi, A., P. Piseri, P. Milani, A. Ferrari, C.E. Bottani, C. Cepek, L. Giovanelli, E. Magnano and M. Sancrotti, Carbon-based nanostructured materials via cluster beam deposition: a multi technique investigation 402–404 (1998) 441
Libuda, J., see Wolter 402–404 (1998) 428
Lidar (Hamburger), D.A., see Yinnon 410 (1998) L721
Limburg, J., C. Bos, T. Schlathölter, R. Hoekstra, R. Morgenstern, S. Hausmann, W. Heiland and A. Närmann, Energy loss of keV He^{2+} scattered off an Al(110) surface 409 (1998) 541
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Lin, J.-C., see Su 406 (1998) 149
Lin, M.-T., J. Shen, W. Kuch, H. Jenniches, M. Klaua, C.M. Schneider and J. Kirschner, Growth, morphology, and crystalline structure of ultrathin Fe films on Cu_3Au(100) 410 (1998) 290
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Lindsay, R., see Gießel 406 (1998) 90
Linke, R., Th. Pelster, M. Tanemura, C. Becker and K. Wandelt, Adsorption of CO on the ordered Ni_3Al(111) surface 402–404 (1998) 76
Linke, U., see Akemann 402–404 (1998) 571
Liu, F.M., see Cai 406 (1998) 9
Liu, H., see Hovis 402–404 (1998) 1
Liu, S. and H. Metiu, A kinetic model for island shape variations under epitaxial growth conditions 405 (1998) L497
Lizzit, S., see Baraldi 401 (1998) L455
Lizzit, S., A. Baraldi, D. Cocco, G. Comelli, G. Paolucci, R. Rosei and M. Kiskinova, NO adsorption on the Rh(110) surface: kinetics and composition of the adlayer studied by fast XPS 410 (1998) 228
López-Carreño, L.D., G. Benítez, L. Viscido, J.M. Heras, F. Yubero, J.P. Espinós and A.R. González-Elipe, Different oxidation states of polycrystalline molybdenum treated by O_2-plasma or O_2-ion bombardment 402–404 (1998) 174
Lorente, N., D. Teillet-Billy and J.-P. Gauyacq, Charge transfer as responsible for H_2^+ dissociation on aluminum surfaces 402–404 (1998) 197
Lou, L., see Akpati 401 (1998) 47
Louis, P., see Angot 409 (1998) 350
Lozzi, L., see Ottaviano 402–404 (1998) 518
Lu, D.-l. and K. Tanaka, Mechanism for the formation of Au–Cu alloy multiply twinned particles formed in the region of UPD of Cu^{2+} in perchloric acid solution 409 (1998) 283
Lu, H., E. Janin, M.E. Dávila, C.M. Pradier and M. Göthelid, Reaction of oxygen and sulphur dioxide with Cu(100)-c(2×2)-Mn surface alloy 408 (1998) 326
Lu, L., see Bansmann 402–404 (1998) 371

Lu, T.-M., see Zhao 409 (1998) L703
Luntz, A.C., see Diekhöner 409 (1998) 384
Luo, M.F., Z.Y. Li and W. Allison, Initial stages of C_{60} thin film growth on graphite 402–404 (1998) 437
Luo, Y., see Pettersson 408 (1998) 1

Ma, S.L., see Guo 406 (1998) L592
Ma, Y.-R., see Moriarty 405 (1998) 21
Ma, Y.R., see Moriarty 407 (1998) 27
Maa, J.-R., see Chen 406 (1998) 167
Maazouz, M., S. Ustaze, L. Guillemot and V.A. Esaulov, Electron capture and loss in the scattering of fluorine and chlorine atoms and ions on metal surfaces 409 (1998) 189
Maazouz, M., see Lacombe 410 (1998) 70
Madey, T.E., see Tao 407 (1998) L640
Madih-Ayadi, K., N. Dupont-Pavlovsky, X. Duval, A. Ayadi and J.F. Marêché, Methane adsorption on dichloromethane preplated graphite: 2D phase transitions on dual surfaces 402–404 (1998) 836
Madih-Ayadi, K., N. Dupont-Pavlovsky, T. Ceva, P. Convert, B. Croset and A. Ayadi, Krypton adsorption on graphite preplated with dichloromethane 405 (1998) 192
Magnano, E., S. Vandré, J. Kovac, E. Narducci, R. Caloi, P. Manini and M. Sancrotti, Surface and subsurface properties of a $BaLi_4$ gettering alloy studied using X-ray photoemission spectroscopy 402–404 (1998) 223
Magnano, E., see Libassi 402–404 (1998) 441
Magnano, E., see Giudice 405 (1998) L561
Mahon, D.I., see Peck 410 (1998) 170
Mahon, D.I., see Peck 410 (1998) 200
Mahon, D.I., see Peck 410 (1998) 214
Makhmetov, G.E., see Goryunov 401 (1998) 206
Malaske, U., C. Tegenkamp, M. Henzler and H. Pfnür, Defect-induced band gap states and the contact charging effect in wide band gap insulators 408 (1998) 237
Mallet, P., see Veuillen 402–404 (1998) 295
Mamman, D.A., see Berlouis 408 (1998) 173
Mandarino, N., see Lacombe 410 (1998) 70
Manini, P., see Magnano 402–404 (1998) 223
Marcellini, A., C.A. Pignedoli, M. Ferrario and C.M. Bertoni, Interaction of Cl_2 molecules with GaAs(110) surface 402–404 (1998) 47
Marcus, P., see Kitakatsu 407 (1998) 36
Marêché, J.F., see Madih-Ayadi 402–404 (1998) 836
Margaritondo, G., see Almeida 402–404 (1998) 470
Margaritondo, G., see Vobornik 402–404 (1998) 761
Mariani, C., see Gavioli 409 (1998) 207
Mariani, C., see del Pennino 409 (1998) 258
Mariotti, G.G., see Carley 401 (1998) 400
Marks, L.D., see Landree 408 (1998) 300
Marowsky, G., see Boness 402–404 (1998) 513
Marowsky, G., see Kravetsky 402–404 (1998) 542
Martin, D., J. Jupille and Y. Borensztein, Silver particle sizes and shapes as determined during a deposit by in situ surface differential reflectance 402–404 (1998) 433
Martin, K.P., see Winningham 406 (1998) 221
Martín-Gago, J.A., see Polop 402–404 (1998) 245
Martín-Gago, J.A., see Polop 407 (1998) 268
Maruyama, M., see Hasegawa 405 (1998) L503
Mascaraque, A., J. Avila, M.C. Asensio and E.G. Michel, Band structure and gap opening in Pb/Ge(111) 402–404 (1998) 742
Masel, R.I., see Nigg 409 (1998) 428
Masson, L., see Thibaudau 409 (1998) L718
Matsuda, I., see Matsui 401 (1998) L413
Matsui, F., H.W. Yeom, A. Imanishi, K. Isawa, I. Matsuda and T. Ohta, Adsorption of acetylene and ethylene on the Si(001)2×1 surface studied by NEXAFS and UPS 401 (1998) L413
Matsui, F., see Imanishi 407 (1998) 282
Matsumoto, D., see Natori 409 (1998) 160
Matsumoto, M., see Nakamura 402–404 (1998) 701
Matsuura, T., T. Sugiyama and J. Murota, Atomic-layer surface reaction of chlorine on Si and Ge assisted by an ultraclean ECR plasma 402–404 (1998) 202
Matsuura, T., see Yamamoto 408 (1998) 190
Mattera, L., see Ferro 407 (1998) 212
Matthes, Th.W., see Rettenberger 402–404 (1998) 409
Maurice, V., see Kitakatsu 407 (1998) 36
Maus-Friedrichs, W., see Takami 407 (1998) 140
Mayan, M., see Held 402–404 (1998) 322
Mazroui, M., A. Asaklil and Y. Boughaleb, Conductivity of two-dimensional systems of interacting Brownian particles within the effective potential description 409 (1998) 528
McConville, C.F., see Bell 401 (1998) 125
McConville, C.F., see Jenkins 402–404 (1998) 645
McConville, C.F., see Bell 405 (1998) 280
McConville, C.F., see Belk 410 (1998) 82
McFadden, C.F. and A.J. Gellman, Metallic friction: the effect of molecular adsorbates 409 (1998) 171
McGilp, J.F., see Kravetsky 402–404 (1998) 542
Medvedev, V.K., R. Börner and N. Kruse, Nickeltetracarbonyl formation on non-equilibrium Ni surfaces 401 (1998) L371
Medvedev, V.K., see Suchorski 401 (1998) 392
Meinel, K., see Ammer 401 (1998) 138
Meinel, K., H. Wolter, Ch. Ammer and H. Neddermeyer, Metastable misfit-induced relaxation structures of close-packed heteroepitaxial films 401 (1998) 434
Meinel, K., H. Wolter, Ch. Ammer and H. Neddermeyer, A misfit-induced relaxation structure of epitaxial Cu films on Ru(0001) and its potential use for nanostructuring 402–404 (1998) 299
Meiwes-Broer, K.-H., see Bettac 402–404 (1998) 475
Meiwes-Broer, K.-H., see Behrens 402–404 (1998) 729
Memmel, N., see Steltenpohl 402–404 (1998) 277
Memmel, N., see von der Linden 409 (1998) 290
Merikoski, J., see Hjelt 402–404 (1998) 253
Metcalfe, I.S., see Emery 405 (1998) 308
Metiu, H., see Liu 405 (1998) L497
Metzler, M., see Rettenberger 402–404 (1998) 409
Meyer zu Heringdorf, F., see Horn-von Hoegen 402–404 (1998) 464

Mezey, L.Z. and W. Hofer, Thermodynamic calculation of global and local surface compositions of PtRh: a case of surface clustering even with bulk ordering 402–404 (1998) 845
Michel, D., see Boisgard 401 (1998) 199
Michel, E.G., see Segovia 402–404 (1998) 377
Michel, E.G., see Mascaraque 402–404 (1998) 742
Middleton, P.H., see Emery 405 (1998) 308
Miki, K., K. Sakamoto and T. Sakamoto, Surface preparation of Si substrates for epitaxial growth 406 (1998) 312
Milani, P., see Libassi 402–404 (1998) 441
Mingo, N., see Jurczyszyn 402–404 (1998) 459
Minoda, H., see Latyshev 401 (1998) 22
Minoda, H., see Horn-von Hoegen 402–404 (1998) 464
Minoda, H., see Shimakura 407 (1998) L657
Minoda, H., see Aoki 408 (1998) 101
Minot, C., see Ahdjoudj 402–404 (1998) 104
Minot, C., see Sonnet 402–404 (1998) 751
Minot, C., see Sonnet 407 (1998) 121
Miranda, R., see Prieto 401 (1998) 248
Miranda, R., see Camarero 402–404 (1998) 346
Mishina, E.D., see Aktsipetrov 402–404 (1998) 576
Misuryaev, T.V., see Aktsipetrov 402–404 (1998) 576
Mitchell, P.C.H., see Poulston 402–404 (1998) 599
Mitrovic, B.C. and D.J. O'Connor, Negative direct recoil spectroscopy study of the initial oxidation of Al(111) 405 (1998) 261
Mitsui, H., see Shigeta 402–404 (1998) 313
Miyamoto, N., see Niwano 401 (1998) 364
Mizutani, G., see Tanaka 402–404 (1998) 533
Mizutani, G., see Kobayashi 402–404 (1998) 537
Mochán, W.L., see Vargas 406 (1998) L619
Mochán, W.L., see Vargas 409 (1998) 130
Mochrie, S.G.J., see Watson 407 (1998) 59
Møller, P.J., see Nerlov 401 (1998) 56
Møller, P.J., Z.S. Li, T. Egebjerg, M. Sambi and G. Granozzi, Synchrotron-radiation-induced photoemission study of VO_2 ultrathin films deposited on TiO_2(110) 402–404 (1998) 719
Montalenti, F., see Trioni 401 (1998) L383
Moore, J.T., see Winningham 406 (1998) 221
Morais, J., see Thevuthasan 401 (1998) 261
Morgenstern, K., see Esser 402–404 (1998) 341
Morgenstern, K., see Rosenfeld 402–404 (1998) 401
Morgenstern, R., see Limburg 409 (1998) 541
Morgner, H., see Heinz 405 (1998) 104
Morgner, H., see Andersson 405 (1998) 138
Moriarty, P., M.D. Upward, Y.-R. Ma, A.W. Dunn, P.H. Beton, D. Teehan and D.A. Woolf, Reconstruction dependent adsorption of C_{60} on GaAs(111)B 405 (1998) 21
Moriarty, P., see Upward 405 (1998) L526
Moriarty, P., Y.R. Ma, M.D. Upward and P.H. Beton, Translation, rotation and removal of C_{60} on Si(100)–2×1 using anisotropic molecular manipulation 407 (1998) 27
Moroni, R., see Ferro 407 (1998) 212
Mostéfa-Sba, H., see Pétigny 410 (1998) 250
Mostepanenko, V.M., see Blagov 410 (1998) 158
Motta, N., see Contini 405 (1998) L509
Motta, N., A. Sgarlata, R. Calarco, Q. Nguyen, J. Castro Cal, F. Patella, A. Balzarotti and M. De Crescenzi, Growth of Ge–Si(111) epitaxial layers: intermixing, strain, relaxation and island formation 406 (1998) 254
Mróz, S., H. Otop and Z. Jankowski, On the role of Pb in epitaxial growth of thin Co films on Cu(111) 402–404 (1998) 263
Mugele, F., see Rettenberger 402–404 (1998) 409
Muggelberg, C., M.R. Castell, G.A.D. Briggs and D.T. Goddard, The atomic structure of the UO_{2+x}(110) surface and the effects of interstitial oxygen: an elevated-temperature STM study 402–404 (1998) 673
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Müller, S., see Prieto 401 (1998) 248
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Mundt, C. and C. Benndorf, H_2O adsorption on alkali (Li, Na and K) precovered Ni(775) 405 (1998) 121
Murakami, A., see Tabata 402–404 (1998) 487
Murakami, Y., see Shibata 405 (1998) 153
Murayama, M., see Natori 409 (1998) 160
Murota, J., see Matsuura 402–404 (1998) 202
Murota, J., see Yamamoto 408 (1998) 190
Muryn, C.A., see Wincott 402–404 (1998) 705
Musolino, V., A. Selloni and R. Car, Atomic and electronic structure of Cu clusters on MgO 402–404 (1998) 413

Nagao, T., see Tong 408 (1998) 146
Naitoh, M., A. Konishi, H. Inenaga, S. Nishigaki, N. Oishi and F. Shoji, Ga-rich GaP(001)(2×4) surface structure studied by low-energy ion scattering spectroscopy 402–404 (1998) 623
Naitoh, M., see Yamada 402–404 (1998) 683
Nakabayashi, S., see Yagi 406 (1998) 1
Nakai, H., see Hu 401 (1998) 371
Nakajima, S., see Oku 407 (1998) L647
Nakakura, C.Y., G. Zheng and E.I. Altman, Atomic-scale mechanisms of the halogenation of Cu(100) 401 (1998) 173
Nakamura, I., H. Nakano, T. Fujitani, T. Uchijima and J. Nakamura, Evidence for a special formate species adsorbed on the Cu–Zn active site for methanol synthesis 402–404 (1998) 92
Nakamura, J., see Nakamura 402–404 (1998) 92
Nakamura, K., A. Kurokawa and S. Ichimura, Increased rate of ozone adsorption on Si(111)-(7×7) with nitrogen preadsorption 402–404 (1998) 165
Nakamura, K., see Shigeta 402–404 (1998) 313
Nakamura, T., H. Kondoh, M. Matsumoto and H. Nozoye, Formation of a novel honeycomb structure consisting of 2-mercaptomethylthiophene derivatives on Au(111). Building units to form the unique structure 402–404 (1998) 701
Nakamura, T., see Fujii 405 (1998) L549
Nakanishi, H., see Kawahito 409 (1998) L709
Nakano, H., see Nakamura 402–404 (1998) 92
Nakashima, H., see Hasegawa 405 (1998) L503

Nakatsuji, H., see Hu 401 (1998) 371
Narducci, E., see Magnano 402–404 (1998) 223
Narkiewicz, U., see Arabczyk 402–404 (1998) 502
Närmann, A., see Speller 405 (1998) L542
Närmann, A., see Limburg 409 (1998) 541
Natori, A., M. Murayama, D. Matsumoto and H. Yasunaga, Decay process of a crater/hillock and step structure transformation 409 (1998) 160
Naudon, A., see Babonneau 409 (1998) 358
Naumović, D., see Aebi 402–404 (1998) 614
Neddermeyer, H., see Ammer 401 (1998) 138
Neddermeyer, H., see Meinel 401 (1998) 434
Neddermeyer, H., see Meinel 402–404 (1998) 299
Neddermeyer, H., see Hagendorf 402–404 (1998) 581
Nelen, L.N., see Lee 410 (1998) L773
Nemanich, R.J., see Baumann 409 (1998) 320
Nerlov, J., S.V. Hoffmann, M. Shimomura and P.J. Møller, Coadsorption of Na and CO_2 on the $Fe_3O_4(111)$ termination of α-$Fe_2O_3(0001)$: relations between structure and activation 401 (1998) 56
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Netzer, F.P., see Kardinal 405 (1998) L520
Ney, A., see Srivastava 402–404 (1998) 818
Nguyen, Q., see Motta 406 (1998) 254
Nicklin, C.L., see Jones 409 (1998) 27
Niebergall, L., P. Rennert, A. Chassé and Yu. Kucherenko, Angle-resolved PED and AED calculations for different structures of the diamond C(111) surface 402–404 (1998) 628
Niemantsverdriet, J.W., see Siokou 402–404 (1998) 110
Nieminen, J.A. and S. Paavilainen, Adsorption site and STM image of O_2 on Pt{111} 405 (1998) L573
Niesen, L., see James 402–404 (1998) 332
Nieuwenhuys, B.E., see Cobden 402–404 (1998) 155
Nigg, H.L. and R.I. Masel, The surface chemistry of hexafluoroacetylacetone on clean and oxygen pre-covered Cu(210): a temperature-programmed desorption study 409 (1998) 428
Nikulin, A.A., see Aktsipetrov 402–404 (1998) 576
Nilsson, A., see Hasselström 407 (1998) 221
Nishigaki, S., see Naitoh 402–404 (1998) 623
Nishigaki, S., see Yamada 402–404 (1998) 683
Nishijima, M., see Okuyama 401 (1998) 344
Nishimura, T., A. Ikeda, T. Koshikawa, T. Yasue and Y. Kido, Direct detection of H(D) on Si(001) and Si(111) surfaces by medium-energy recoil spectroscopy 409 (1998) 183
Nishioka, Y., see Komeda 405 (1998) 38
Niwano, M., M. Terashi, M. Shinohara, D. Shoji and N. Miyamoto, Oxidation processes on the H_2O-chemisorbed Si(100) surface studied by in-situ infrared spectroscopy 401 (1998) 364
Nix, R.M., see De Asha 405 (1998) 201
Noda, K., see Ryu 401 (1998) L425
Nogami, J., see Evans 406 (1998) 246
Nordlander, P., see Akpati 401 (1998) 47
Nörenberg, H. and G.A.D. Briggs, Surface structure of $CeO_2(111)$ studied by low current STM and electron diffraction 402–404 (1998) 734
Nörenberg, H. and G.A.D. Briggs, Surface structure of the most oxygen deficient Magnéli phase – an STM study of Ti_4O_7 402–404 (1998) 738
Noro, H., see Persaud 401 (1998) 12
Norris, C., see Jones 409 (1998) 27
Nouaoura, M., see Breton 406 (1998) 63
Novak, V.R., see Aktsipetrov 402–404 (1998) 576
Nowicki, M. and J. Osterwalder, Crystalline structure of surface layers for Ag/Cu(001) studied by incident beam electron diffraction 408 (1998) 165
Nozoye, H., see Kuriyama 402–404 (1998) 178
Nozoye, H., see Nakamura 402–404 (1998) 701
Nyberg, M., see Hasselström 407 (1998) 221
Nyholm, R., see Strisland 410 (1998) 330

O'Brien, P., see Mulcahy 406 (1998) 294
Ochs, D., see Reichling 402–404 (1998) 145
Ochs, D., see Takami 407 (1998) 140
O'Connor, D.J., see Mitrovic 405 (1998) 261
O'Connor, D.J., see Shen 406 (1998) 23
O'Connor, D.J., see Shen 410 (1998) 1
Ohnuma, H., see Watanabe 402–404 (1998) 100
Ohresser, P., see Barbier 405 (1998) 298
Ohta, T., see Matsui 401 (1998) L413
Ohta, T., see Imanishi 407 (1998) 282
Ohtani, T., see Takeda 402–404 (1998) 692
Ohtani, T., see Tamiya 408 (1998) 268
Oishi, N., see Naitoh 402–404 (1998) 623
Ojima, K., S. Hongo and T. Urano, Low temperature decomposition mechanism of BaH_2 formed on Si(100) surfaces 402–404 (1998) 150
Okabe, T., see Yoneda 410 (1998) 62
Okada, M., A.P. Baddorf and D.M. Zehner, Hydrogen adsorption on $Mo_{1-x}Re_x(110)$ (x=0–0.25) surfaces 410 (1998) 237
Okamoto, M., T. Yokoyama and K. Takayanagi, Strain field around a single-dimer vacancy of Si(100) surface studied by a Monte Carlo simulation 402–404 (1998) 851
Okamoto, T., see Hanamoto 409 (1998) 413
Okawa, Y., see Tanaka 401 (1998) L407
Okiji, A., see Kawahito 409 (1998) L709
Oku, T. and S. Nakajima, Surface structures of (Hg, Tl)-based oxides studied by high-resolution electron microscopy 407 (1998) L647
Okuyama, H., W. Siga, N. Takagi, M. Nishijima and T. Aruga, Path and mechanism of hydrogen absorption at Pd(100) 401 (1998) 344
Oliva, A.I., see Aguilar 409 (1998) 501
Ollonqvist, T., M. Punkkinen, J. Väyrynen and O. Dmitrieva, Inverse photoemission spectra of the Nb(111) surface 402–404 (1998) 678
Onellion, M., see Vobornik 402–404 (1998) 761
Ono, K., see An 401 (1998) 336
Ortega, J.E., see Segovia 402–404 (1998) 377

Ortega, J.E., see Speller 405 (1998) L542
Osaka, N., see Akita 405 (1998) 172
Osterwalder, J., see Wetli 402–404 (1998) 551
Osterwalder, J., see Aebi 402–404 (1998) 614
Osterwalder, J., see Nowicki 408 (1998) 165
Ota, K., M. Tanaka and S. Usami, Oxygen adsorption on a W(100) surface studied by reflectance spectroscopy and electron energy-loss fine structure 402–404 (1998) 813
Otop, H., see Mróz 402–404 (1998) 263
Ott, A.K., S.M. Casey and S.R. Leone, Arsenic desorption kinetics from Si(100) 405 (1998) 228
Ottaviano, L., L. Lozzi, F. Rispoli and S. Santucci, Hexadecafluoro-copper-phthalocyanine UHV deposited onto Si(111) 7×7 substrate: an XPS study 402–404 (1998) 518
Otto, A., see Pohl 406 (1998) 125
Oueini, W., M. Rouanet and J. Bonnet, Formation of the Al–GaSb(110) interface 409 (1998) 445
Oueini, W., M. Banouni and G. Lévêque, Surface valence bands of GaSb(110) investigated by UV photoemission 410 (1998) 132
Oura, K., see Ryu 401 (1998) L425
Over, H., see Setzer 402–404 (1998) 782
Over, H., see Bludau 402–404 (1998) 786
Over, H., see Kleine 410 (1998) 15
Overbury, S.H., see Mullins 409 (1998) 307
Overbury, S.H., P.V. Radulovic, S. Thevuthasan, G.S. Herman, M.A. Henderson and C.H.F. Peden, Ion scattering study of the Zn and oxygen-terminated basal plane surfaces of ZnO 410 (1998) 106

Paavilainen, S., see Nieminen 405 (1998) L573
Palomares, J., see Daimon 408 (1998) 260
Panella, V., see Biagi 402–404 (1998) 547
Pang, S.J., see Zhao 406 (1998) L614
Pang, S.J., see Yang 406 (1998) 229
Paolucci, G., see Baraldi 401 (1998) L455
Paolucci, G., see Wilde 405 (1998) 215
Paolucci, G., see Polop 407 (1998) 268
Paolucci, G., see Lizzit 410 (1998) 228
Papageorgopoulos, A., see Papageorgopoulos 402–404 (1998) 120
Papageorgopoulos, C.A., see Kamaratos 402–404 (1998) 37
Papageorgopoulos, C.A., M. Kamaratos and A. Papageorgopoulos, Coadsorption of Na and elemental S on Ni(100) 402–404 (1998) 120
Park, C.Y., see An 401 (1998) 336
Park, K.-H., J.S. Ha, W.S. Yun and E.-H. Lee, Initial stage of Ag epitaxial growth on Sb-terminated Si(111) surface 405 (1998) 46
Park, Z., see Wilms 402–404 (1998) 83
Parker, D.H., see Saliba 410 (1998) 270
Parker, S.F., see Poulston 402–404 (1998) 599
Pashley, D.W., see Belk 410 (1998) 82
Passerone, D., see Celestini 402–404 (1998) 886
Patella, F., see Motta 406 (1998) 254
Patterson, C.H., see Hogan 402–404 (1998) 586
Patthey, F., see Schaffner 402–404 (1998) 450
Patthey, L., see Aebi 402–404 (1998) 614
Paulus, B., Correlation calculations for the reconstruction of the Si(100) surface 408 (1998) 195
Pawlik, S., see Bauer 402–404 (1998) 62
Pawlik, S., R. Burgermeister, M. Bauer and M. Aeschlimann, Direct transition in the system Ag(111) studied by one- and two-photon photoemission 402–404 (1998) 556
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Peck, J.W., D.I. Mahon and B.E. Koel, A temperature programmed desorption study of the reaction of methylacetylene on Pt(111) and Sn/Pt(111) surface alloys 410 (1998) 200
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Peden, C.H.F., see Thevuthasan 401 (1998) 261
Peden, C.H.F., see Overbury 410 (1998) 106
Pelster, Th., see Linke 402–404 (1998) 76
Peña, F., see Colen 408 (1998) 310
Peng, C.S., see Guo 406 (1998) L592
Pennisi, A.R., see Faraci 409 (1998) 46
Pere, J., see Hirsimäki 402–404 (1998) 187
Perfetti, P., see Cricenti 401 (1998) 427
Perry, C.C., S. Haq, B.G. Frederick and N.V. Richardson, Face specificity and the role of metal adatoms in molecular reorientation at surfaces 409 (1998) 512
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Persson, C., see Carlsson 406 (1998) 48
Pessa, M., see Hirsimäki 402–404 (1998) 187
Pétigny, S., H. Mostéfa-Sba, B. Domenichini, E. Lesniewska, A. Steinbrunn and S. Bourgeois, Superficial defects induced by argon and oxygen bombardments on (110) TiO_2 surfaces 410 (1998) 250
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Pettenkofer, C., see Kamaratos 402–404 (1998) 37
Pettersson, L.G.M., see Schaffner 402–404 (1998) 450
Pettersson, L.G.M., see Hasselström 407 (1998) 221
Pettersson, L.G.M., H. Ågren, Y. Luo and L. Triguero, Benzene adsorbed on Cu(110): theoretical X-ray absorption, emission and shake calculations 408 (1998) 1
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Petukhov, A.V. and Th. Rasing, A new linear-optical tool for surface magnetism? 402–404 (1998) 360
Pfandzelter, R., see Igel 405 (1998) 182

Pfnür, H., see Malaske 408 (1998) 237
Phaner-Goutorbe, M., Y. Robach, P. Krapf, A. Solère and L. Porte, Strain effect on the growth of 3D In(Ga)As wire structures on InP(001) 402–404 (1998) 268
Piancastelli, M.N., see Carbone 407 (1998) 275
Piaszenski, G., see Aschoff 402–404 (1998) 770
Picaud, S., see Ferry 409 (1998) 101
Pierna, A.R., see Sistiaga 410 (1998) 312
Pignedoli, C.A., see Marcellini 402–404 (1998) 47
Pillo, Th., see Aebi 402–404 (1998) 614
Pirug, G. and H.P. Bonzel, UHV simulation of the electrochemical double layer: adsorption of $HClO_4/H_2O$ on Au(111) 405 (1998) 87
Pirug, G., see Emundts 410 (1998) L727
Piseri, P., see Libassi 402–404 (1998) 441
Platen, J., see Setzer 402–404 (1998) 782
Ploog, K.H., see Däweritz 402–404 (1998) 257
Podloucky, R., see Bihlmayer 402–404 (1998) 794
Podloucky, R., see Vogtenhuber 402–404 (1998) 798
Podloucky, R., see Hofer 405 (1998) L514
Pohl, M. and A. Otto, Adsorption and reaction of carbon dioxide on pure and alkali-metal promoted cold-deposited copper films 406 (1998) 125
Polaczyk, C., see Li 402–404 (1998) 386
Polaczyk, C., T. Schneider, J. Schöfer and E. Santner, Microtribological behavior of Au(001) studied by AFM/FFM 402–404 (1998) 454
Polcik, M., L. Wilde and J. Haase, Surface melting of Al(110) studied by surface extended X-ray absorption fine structure 405 (1998) 112
Polcik, M., see Wilde 405 (1998) 215
Pollmann, J., see Vogel 402–404 (1998) 774
Pollmann, J., see Hirsch 402–404 (1998) 778
Polop, C., J.L. Sacedón and J.A. Martín-Gago, STM studies of the growth of the Si/Cu(110) surface alloy 402–404 (1998) 245
Polop, C., C. Rojas, E. Roman, J.A. Martín-Gago, B. Brena, D. Cocco and G. Paolucci, LEED structural determination of the c(2×2) Si/Cu(110) surface alloy 407 (1998) 268
Pölzl, H., see Premm 401 (1998) L444
Popp, V., R. Kladny, Th. Schimmel and J. Küppers, Structuring of mica surfaces with a vibrating AFM tip 401 (1998) 105
Poppensieker, J., see Seidel 408 (1998) 223
Porte, L., see Phaner-Goutorbe 402–404 (1998) 268
Poulopoulos, P., see Bovensiepen 402–404 (1998) 396
Poulston, S., see Bennett 401 (1998) 72
Poulston, S., R.P. Holroyd, M. Bowker, S.F. Parker and P.C.H. Mitchell, An inelastic neutron scattering study of formate on copper surfaces 402–404 (1998) 599
Power, J.R., P. Weightman and A.A. Cafolla, The initial stages of Ge–GaAs(100) interface formation studied by reflectance anisotropy spectroscopy and low-energy electron diffraction 402–404 (1998) 566
Pradier, C.M., see Lu 408 (1998) 326
Předota, M., see Kotrla 402–404 (1998) 249
Premm, H., H. Pölzl and A. Winkler, Dynamics and kinetics of subsurface absorption and desorption for the system hydrogen (deuterium)–Ni(111) 401 (1998) L444
Press, W., see Asmussen 406 (1998) 138
Prieto, J.E., Ch. Rath, S. Müller, R. Miranda and K. Heinz, A structural analysis of the Co(0001) surface and the early stages of the epitaxial growth of Cu on it 401 (1998) 248
Prime, A.F., see Wincott 402–404 (1998) 705
Przeslawski, J., see Garcia 407 (1998) L665
Puchin, V.E., see Puchina 402–404 (1998) 687
Puchina, A.V., V.E. Puchin, M. Huisinga, R. Bennewitz and M. Reichling, Theoretical modelling of steps and surface oxidation on CaF_2(111) 402–404 (1998) 687
Punkkinen, M., see Ollonqvist 402–404 (1998) 678
Purdie, D., see Hengsberger 405 (1998) L491
Purdie, D., M. Hengsberger, M. Garnier and Y. Baer, An outlook for high-resolution UV photoelectron spectroscopy of solids at low temperature 407 (1998) L671

Qin, Y., see Li 408 (1998) 123
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Quintana, P., see Aguilar 409 (1998) 501
Quinton, J., P. Dastoor and W. Allison, PTMS on iron and aluminum oxide surfaces: a study of damped adsorption kinetics 402–404 (1998) 66
Quitmann, C., see Vobornik 402–404 (1998) 761

Raaen, S., see Strisland 410 (1998) 344
Rademann, K., see Bernhardt 408 (1998) 86
Radke, U., see Reissner 402–404 (1998) 71
Radnik, J., see Grüne 402–404 (1998) 236
Radulovic, P.V., see Overbury 410 (1998) 106
Rahman, T.S., see Durukanoğlu 409 (1998) 395
Ramsey, M.G., see Kardinal 405 (1998) L520
Ramstad, A., see Berg 409 (1998) 1
Ramstad, A., see Strisland 410 (1998) 344
Rank, V., see Bettac 402–404 (1998) 475
Ranney, J.T., J.L. Gland and S.R. Bare, The desorption of propylene oxide from oxygen atom and hydroxyl covered Ag(110) 401 (1998) 1
Raschke, M.B., P. Bratu and U. Höfer, Optical second-harmonic investigations of the isothermal desorption of SiO from the Si(100) and Si(111) surfaces 410 (1998) 351
Rasing, Th., see Kirilyuk 402–404 (1998) 356
Rasing, Th., see Petukhov 402–404 (1998) 360
Rasing, Th., see Aktsipetrov 402–404 (1998) 576
Rastomjee, C.S., see Tammaro 407 (1998) 162
Rath, Ch., see Prieto 401 (1998) 248
Rauscher, H., see Braun 409 (1998) L715
Raybaud, P., J. Hafner, G. Kresse and H. Toulhoat, Structural and electronic properties of the $MoS_2(10\bar{1}0)$ edge-surface 407 (1998) 237
Raza, H., P.L. Wincott, G. Thornton, R. Casanova and A. Ro-

driguez, Photoemission studies of the reaction of benzene with $TiO_2(100)1\times1$ and 1×3 402–404 (1998) 710
Rea, C., see Schumacher 408 (1998) 203
Redinger, J., see Vogtenhuber 402–404 (1998) 798
Redinger, J., see Hofer 405 (1998) L514
Red'kin, S.I., see Aristov 402–404 (1998) 337
Reiche, M., see Däweritz 402–404 (1998) 257
Reichling, M., M. Huisinga, D. Ochs and V. Kempter, Electron- and photon-stimulated metallization and oxidation of the $CaF_2(111)$ surface 402–404 (1998) 145
Reichling, M., see Puchina 402–404 (1998) 687
Reijme, M.A., see Ceelen 406 (1998) 264
Reinhard, P.-G., see Kohl 405 (1998) 74
Reiniger, M., see Brüning 402–404 (1998) 215
Reissner, R., U. Radke, M. Schulze and E. Umbach, Water coadsorbed with oxygen and potassium on thin NiO(100) films 402–404 (1998) 71
Ren, B., see Cai 406 (1998) 9
Ren, J., see Jung 401 (1998) 476
Renaud, G., see Robach 401 (1998) 227
Renaud, G., see Barbier 402–404 (1998) 757
Rennert, P., see Niebergall 402–404 (1998) 628
Resel, R. and G. Leising, High resolution X-ray diffraction studies on hexaphenyl thin films 409 (1998) 302
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Rettighieri, L., see Biagi 402–404 (1998) 547
Reuter, D., see Sander 402–404 (1998) 351
Ribes, V., see Breton 406 (1998) 63
Richardson, N.V., see Barlow 401 (1998) 322
Richardson, N.V., see Perry 409 (1998) 512
Richter, C., see Bencok 402–404 (1998) 327
Richter, C., see Huttel 402–404 (1998) 609
Richter, Wo., see Hüsken 407 (1998) L676
Richter, Wo., see Hüsken 407 (1998) 114
Riegel, D., see Li 402–404 (1998) 386
Righini, M., see Almeida 402–404 (1998) 470
Riley, J.D., see Xue 401 (1998) L401
Rispoli, F., see Ottaviano 402–404 (1998) 518
Ritz, G., see Hofer 405 (1998) L514
Rivacoba, A., see Aizpurua 402–404 (1998) 418
Robach, O., G. Renaud and A. Barbier, Very-high-quality MgO(001) surfaces: roughness, rumpling and relaxation 401 (1998) 227
Robach, Y., see Phaner-Goutorbe 402–404 (1998) 268
Roberts, M.W., see Carley 406 (1998) L587
Rocca, M., see Vattuone 408 (1998) L693
Rodriguez, A., see Raza 402–404 (1998) 710
Rodriguez, J., see Aray 405 (1998) L532
Rodriguez, J.A., see Chaturvedi 401 (1998) 282
Rodriguez, J.A., T. Jirsak, S. Chaturvedi and J. Hrbek, The interaction of H_2S and S_2 with Cs and Cs/ZnO surfaces: photoemission and molecular-orbital studies 407 (1998) 171
Rogojanu, O.C., see James 402–404 (1998) 332
Rojas, C., see Polop 407 (1998) 268
Roman, E., see Polop 407 (1998) 268
Roosendaal, S.J., A.M. Vredenburg and F.H.P.M. Habraken, The influence of adsorbed N in the initial stages of oxidation of iron 402–404 (1998) 135
Rösch, N., see Birkenheuer 409 (1998) 213
Rosei, R., see Baraldi 401 (1998) L455
Rosei, R., see Lizzit 410 (1998) 228
Rosen, M., see Haftel 407 (1998) 16
Rosenfeld, G., see Esser 402–404 (1998) 341
Rosenfeld, G., K. Morgenstern, I. Beckmann, W. Wulfhekel, E. Lægsgaard, F. Besenbacher and G. Comsa, Stability of two-dimensional clusters on crystal surfaces: from Ostwald ripening to single cluster decay 402–404 (1998) 401
Rotermund, H.H., see Colen 408 (1998) 310
Rouanet, M., see Oueini 409 (1998) 445
Rowe, J.E., see Tao 407 (1998) L640
Roy, H.-V., C. Kallinger and K. Sattler, Study of single and multiple foldings of graphitic sheets 407 (1998) 1
Rubahn, H.-G., see Boness 402–404 (1998) 513
Rubahn, H.-G., see Balzer 402–404 (1998) 841
Ruban, A.V., see Bach Aaen 408 (1998) 43
Rufael, T.S., see Holbert 401 (1998) L437
Runge, B.-U., see Kohl 407 (1998) 104
Rusponi, S., see Giudice 405 (1998) L561
Rust, H.-P., see Doering 410 (1998) L736
Rutkowski, M., see Wetzig 402–404 (1998) 232
Ruzaikin, M.P., see Hervieu 408 (1998) 57
Ryu, J.-T., K. Kui, K. Noda, M. Katayama and K. Oura, The effect of hydrogen termination on In growth on Si(100) surface 401 (1998) L425

Saalfrank, P., see Dohle 409 (1998) 37
Saalfrank, P., see Klamroth 410 (1998) 21
Sacedón, J.L., see Polop 402–404 (1998) 245
Sakamoto, K., see Suto 402–404 (1998) 523
Sakamoto, K., see Miki 406 (1998) 312
Sakamoto, T., see Miki 406 (1998) 312
Sakaue, K., see Yoneda 410 (1998) 62
Salanon, B., see Goapper 409 (1998) 81
Saliba, N., D.H. Parker and B.E. Koel, Adsorption of oxygen on Au(111) by exposure to ozone 410 (1998) 270
Salmeron, M., see Xu 407 (1998) 251
Salmeron, M., see Cerdá 409 (1998) 145
Saltas, V., see Kamaratos 402–404 (1998) 37
Salvan, F., see Thibaudau 409 (1998) L718
Salvarani, B., see del Pennino 409 (1998) 258
Salvietti, M., see Ferro 407 (1998) 212
Samant, M.G., see Hasselström 407 (1998) 221
Sambi, M., see Møller 402–404 (1998) 719
San Miguel, M.A., C.J. Calzado and J.F. Sanz, Molecular dynamics simulations of Na deposition on the $TiO_2(110)$ surface 409 (1998) 92
Sanchez, E., see Lacombe 410 (1998) 70
Sancrotti, M., see Magnano 402–404 (1998) 223
Sancrotti, M., see Libassi 402–404 (1998) 441

Sancrotti, M., see Laine 402–404 (1998) 871
Sancrotti, M., see Laine 402–404 (1998) 875
Sander, D., A. Enders, C. Schmidthals, D. Reuter and J. Kirschner, Mechanical stress and magnetism of ferromagnetic monolayers 402–404 (1998) 351
Sander, D., see Schmidthals 402–404 (1998) 636
Santner, E., see Polaczyk 402–404 (1998) 454
Santoni, A., see Dhanak 410 (1998) 321
Santoro, G., S. Sorella, F. Becca, S. Scandolo and E. Tosatti, Metallic charge density waves and surface Mott insulators for adlayer structures on semiconductors: extended Hubbard modeling 402–404 (1998) 802
Santoro, G., see Scandolo 402–404 (1998) 808
Santoro, G., A. Laio and E. Tosatti, Step–step interactions and correlations from 1D hard-core boson mapping 402–404 (1998) 880
Santra, A.K., see Carley 406 (1998) L587
Santucci, S., see Ottaviano 402–404 (1998) 518
Sanz, J.F., see San Miguel 409 (1998) 92
Sasaki, N., see Tsukada 401 (1998) 355
Sasaki, T.A., see Baba 402–404 (1998) 115
Sato, N., see Tsukada 401 (1998) 355
Sattler, K., see Roy 407 (1998) 1
Sautet, P., see Cerdá 409 (1998) 145
Scalas, E., see Danani 402–404 (1998) 281
Scalas, E., see Danani 409 (1998) 117
Scandolo, S., see Santoro 402–404 (1998) 802
Scandolo, S., F. Ancilotto, G.L. Chiarotti, G. Santoro, S. Serra and E. Tosatti, First principles calculations of charge and spin density waves of $\sqrt{3}$-adsorbates on semiconductors 402–404 (1998) 808
Schaff, O., see Lindsay 405 (1998) L566
Schaff, O., see Gießel 406 (1998) 90
Schaffner, M.-H., F. Patthey, W.-D. Schneider and L.G.M. Pettersson, Electron energy loss spectroscopy (EELS) of thermally evaporated Cu deposited on MgO(100)/Mo(100) 402–404 (1998) 450
Scharnberg, K., see Schumacher 408 (1998) 203
Schatz, G., see Kohl 407 (1998) 104
Schieffer, P., C. Krembel, M.C. Hanf and G. Gewinner, Growth of pseudomorphic body centered tetragonal Mn films with an abrupt interface on Ag(001) 402–404 (1998) 318
Schimmel, Th., see Popp 401 (1998) 105
Schindler, K.-M., see Hagendorf 402–404 (1998) 581
Schindler, K.-M., see Gießel 406 (1998) 90
Schinzer, S. and W. Kinzel, Modelling sublimation by computer simulation: morphology-dependent effective energies 401 (1998) 96
Schlapbach, L., see Aebi 402–404 (1998) 614
Schlathölter, T., see Brüning 402–404 (1998) 215
Schlathölter, T., see Limburg 409 (1998) 541
Schlögl, R., see Uchida 401 (1998) 469
Schmid, H., see Wetli 402–404 (1998) 551
Schmid, M., see Hofer 405 (1998) L514
Schmidt, W.G. and F. Bechstedt, Geometry and electronic structure of InP(001)(2×4) reconstructions 409 (1998) 474
Schmidthals, C., see Sander 402–404 (1998) 351
Schmidthals, C., A. Enders, D. Sander and J. Kirschner, Coexistence of pseudomorphic and coincidence phases in nickel monolayers 402–404 (1998) 636
Schmidthals, C., see Shen 407 (1998) 90
Schneider, C.M., see Camarero 402–404 (1998) 346
Schneider, C.M., see Lin 410 (1998) 290
Schneider, T., see Polaczyk 402–404 (1998) 454
Schneider, W.-D., see Schaffner 402–404 (1998) 450
Schneider, W.-D., see Glöckler 405 (1998) 1
Schneider, W.-D., see Böhringer 408 (1998) 72
Schnellinger, A., see Zhang 402–404 (1998) 480
Schober, M., see Balzer 402–404 (1998) 841
Schöfer, J., see Polaczyk 402–404 (1998) 454
Scholte, P.M.L.O., see Steinfort 409 (1998) 229
Schönhense, G., see Bansmann 402–404 (1998) 365
Schröder, K.-M., see Wollschläger 402–404 (1998) 272
Schröter, B., see Hüsken 407 (1998) L676
Schröter, B., see Hüsken 407 (1998) 114
Schulze, M., see Reissner 402–404 (1998) 71
Schumacher, D., C. Rea, D. Heitmann and K. Scharnberg, Surface plasmons and Sommerfeld–Zenneck waves on corrugated surfaces. Application to high-T_c superconductors 408 (1998) 203
Schützendübe, P., see Däweritz 402–404 (1998) 257
Schweikert, E.A., see da Silveira 408 (1998) 28
Scoggins, T., see Lee 410 (1998) L773
Sébenne, C.A., see Zaïbi 402–404 (1998) 206
Sébenne, C.A., see Akremi 402–404 (1998) 746
Segovia, P., E.G. Michel and J.E. Ortega, Quantum well states and interface quality in Cu/Co(100)/Cu(100) system 402–404 (1998) 377
Seiberling, L.E., see Bailes III 410 (1998) L762
Seidel, C., see Glöckler 405 (1998) 1
Seidel, C., J. Poppensieker and H. Fuchs, Real-time monitoring of phase transitions of vacuum deposited organic films by molecular beam deposition LEED 408 (1998) 223
Seifert, W., see Carlsson 406 (1998) 48
Seiferth, O., see Wolter 402–404 (1998) 428
Selci, S., see Almeida 402–404 (1998) 470
Selloni, A., A. Vittadini and M. Grätzel, The adsorption of small molecules on the TiO_2 anatase (101) surface by first-priciples molecular dynamics 402–404 (1998) 219
Selloni, A., see Musolino 402–404 (1998) 413
Semond, F., see Douillard 401 (1998) L395
Seo, D.-K., see Jung 401 (1998) 476
Serra, S., see Scandolo 402–404 (1998) 808
Setlik, B., see Strisland 410 (1998) 330
Setzer, C., J. Platen, H. Bludau, M. Gierer, H. Over and K. Jacobi, LEED intensity and surface core level shift analysis of the MBE-prepared GaAs($\bar{1}\bar{1}\bar{1}$)B(2×2) surface 402–404 (1998) 782
Sgarlata, A., see Contini 405 (1998) L509
Sgarlata, A., see Motta 406 (1998) 254
Shapira, Y., see Aphek 409 (1998) 485

Shard, A.G. and V.R. Dhanak, Normal incidence X-ray standing wavefield (NIXSW) study of the Rh(111)-($\sqrt{7}\times\sqrt{7}$)R19.1°-P surface 407 (1998) L623
Shard, A.G., see Dhanak 410 (1998) 321
Sharonov, M., see Garcia 407 (1998) L665
She, C.X., see Cai 406 (1998) 9
Shen, B., X. Chen, K. Fan and J.-F. Deng, BOC-MP study on the mechanism of partial oxidation of CH_3OH to HCHO over a silver surface and the promoting effect of halogen to the catalyst 408 (1998) 128
Shen, H., see Li 408 (1998) 123
Shen, J., C. Schmidthals, J. Woltersdorf and J. Kirschner, Structural phase transformation under reversed strain: a comparative study of iron ultrathin film growth on nickel and copper (100) 407 (1998) 90
Shen, J., see Lin 410 (1998) 290
Shen, Y.G., D.J. O'Connor and K. Wandelt, Composition and structure of $Cu_3Pt(001)$: a (1×1) Cu termination with c(2×2) underlayer ordering 406 (1998) 23
Shen, Y.G., D.J. O'Connor and K. Wandelt, The surface composition, structure and oxygen-induced (2×1) reconstruction of $Cu_3Pt(110)$ 410 (1998) 1
Shevlyuga, V.M., see Andryushechkin 407 (1998) L633
Shibata, T., Y. Murakami, T. Watanuki and H. Suematsu, Crystal structures and magnetism of oxygen monolayers on hexagonal boron nitride 405 (1998) 153
Shigeta, Y., Y. Fukaya, H. Mitsui and K. Nakamura, Observation of RHEED rocking curves during Si/Si(111) film growth 402–404 (1998) 313
Shimakura, T., H. Minoda, Y. Tanishiro and K. Yagi, In-situ study of gold-induced surface structures and step rearrangements on the Si(001) surface by high-temperature STM 407 (1998) L657
Shimoda, M., S. Tsukamoto and N. Koguchi, Coverage analysis of a sulfur-terminated GaAs(001)-(2×6) surface: the effect of double sulfur-treatment 402–404 (1998) 669
Shimomura, M., see Nerlov 401 (1998) 56
Shinohara, M., see Niwano 401 (1998) 364
Shinya, A., see Hanamoto 409 (1998) 413
Shiraishi, K., see Kageshima 407 (1998) 133
Shoji, D., see Niwano 401 (1998) 364
Shoji, F., see Naitoh 402–404 (1998) 623
Shudo, K., see Hattori 402–404 (1998) 170
Siga, W., see Okuyama 401 (1998) 344
Silvestri, W., see Benedek 406 (1998) L621
Singh, N.K., A. Bolzan, J.S. Foord and H. Wright, Etching reactions of C_2H_5I on GaAs(100) 409 (1998) 272
Sinnamon, L.J., see Campbell 410 (1998) L768
Siokou, A., R.M. van Hardeveld and J.W. Niemantsverdriet, Surface reactions of nitrogen oxide on rhodium (100), adsorption, dissociation and desorption 402–404 (1998) 110
Sistiaga, M., A. Cuesta, A.R. Pierna and C. Gutiérrez, Characterization by electrolyte electroreflectance and X-ray photoelectron spectroscopy of amorphous $Ni_{59}Nb_{40}Pt_{1-x}Sn_x$ alloys and their activation by HF solutions 410 (1998) 312
Sklarek, W., see Held 402–404 (1998) 322
Skofronick, J.G., see Benedek 406 (1998) L621
Slanina, F., see Kotrla 402–404 (1998) 249
Šmilauer, P., see Tejedor 407 (1998) 82
Šokčević, D., see Brako 401 (1998) L388
Sokolowski, M., see Umbach 402–404 (1998) 20
Sokolowski, M., see Glöckler 405 (1998) 1
Solère, A., see Phaner-Goutorbe 402–404 (1998) 268
Solymosi, F. and G. Klivényi, Effects of potassium on the adsorption and dissociation of dimethyl ether on Rh(111) 409 (1998) 241
Søndergard, E., see Haderbache 410 (1998) L748
Sonnet, P., L. Stauffer and C. Minot, Comparison of the first stages of the adsorption of Pb and Ge on the Si(111)7×7 surface 402–404 (1998) 751
Sonnet, Ph., L. Stauffer and C. Minot, Adsorption and diffusion mechanisms of Pb on Si(111)-(7×7) in the initial stages of Pb chemisorption 407 (1998) 121
Sonoda, T. and M. Kato, Formation of Ti/O compositional gradient film on Ti–6Al–4V alloy by reactive DC sputtering 402–404 (1998) 241
Sorella, S., see Santoro 402–404 (1998) 802
Sotiropoulou, D. and S. Ladas, An XPS and XAES study of the Ni/ZrO_2 interface 408 (1998) 182
Soukiassian, P., see Douillard 401 (1998) L395
Soukopp, A., see Glöckler 405 (1998) 1
Speller, S., see Kuntze 402–404 (1998) 764
Speller, S., see Aschoff 402–404 (1998) 770
Speller, S., S. Degroote, J. Dekoster, G. Langouche, J.E. Ortega and A. Närmann, Low-temperature deposition of Co on Cu(111): effects on step etching 405 (1998) L542
Spolveri, I., see Ceelen 406 (1998) 264
Srinivasan, R. and I.I. Suni, Electroless deposition of Au onto Si(111) studied by surface second harmonic generation 408 (1998) L698
Srivastava, G.P., see Tütüncü 402–404 (1998) 42
Srivastava, G.P., see Gay 402–404 (1998) 641
Srivastava, G.P., see Jenkins 402–404 (1998) 645
Srivastava, G.P., see Tütüncü 402–404 (1998) 649
Srivastava, G.P., see Casagrande 402–404 (1998) 653
Srivastava, G.P., see Çakmak 402–404 (1998) 658
Srivastava, P., F. Wilhelm, A. Ney, N. Haack, H. Wende and K. Baberschke, Modifications in the electronic structure of 3d single-, bi- and tri-layers on Cu(001) 402–404 (1998) 818
Srivastava, P., see Agrawal 405 (1998) 54
Srivastava, P., see Agrawal 408 (1998) 275
Stampfl, A.P.J., see Xue 401 (1998) L401
Stauffer, L., see Sonnet 402–404 (1998) 751
Stauffer, L., see Sonnet 407 (1998) 121
Steadman, P., see Jones 409 (1998) 27
Steinbrunn, A., see Pétigny 410 (1998) 250
Steinfort, A.J., P.M.L.O. Scholte and F. Tuinstra , Characterisation of multilayers by X-ray reflection 409 (1998) 229
Steinrück, H.-P., see Held 402–404 (1998) 322
Steltenpohl, A. and N. Memmel, Homoepitaxial growth of Pd on Pd(111) – a search for the contribution of electronic surface states to the Ehrlich–Schwoebel barrier 402–404 (1998) 277

Stempel, S., M. Bäumer and H.-J. Freund, STM studies of rhodium deposits on an ordered alumina film-resolution and tip effects 402–404 (1998) 424
Stensgaard, I., see Linderoth 402–404 (1998) 308
Stensgaard, I., see Bach Aaen 408 (1998) 43
Stępień, Z.M. and T.T. Tsong, Formation of metal hydride ions in low-temperature field evaporation 409 (1998) 57
Stierle, A., see Barbier 402–404 (1998) 757
Stietz, F., M. Stuke, J. Viereck, T. Wenzel and F. Träger, Erratum to 'Observation of strong optical absorption at the surface of small particles' 409 (1998) 393
Stimming, U., see Petukhov 402–404 (1998) 182
Stimming, U., see Akemann 402–404 (1998) 571
Stockman, L. and H. van Kempen, Ballistic electron emission microscopy and spectroscopy of the Au/GaAs(110) interface 408 (1998) 232
Stöhr, J., see Hasselström 407 (1998) 221
Stolle, R., see Aktsipetrov 402–404 (1998) 576
Street, S.C. and D.W. Goodman, Response to Queeney and Friend's 'Comment on 'Methanol on O/Mo(110): specific site for methyl radical formation' ' 407 (1998) 296
Strisland, F., see Berg 409 (1998) 1
Strisland, F., A. Beutler, A.J. Jaworowski, R. Nyholm, B. Setlik, D. Heskett and J.N. Andersen, Adsorption sites in coadsorption systems determined by photoemission spectroscopy: K and CO coadsorbed on Rh(111) 410 (1998) 330
Strisland, F., A. Ramstad, C. Berg and S. Raaen, Valence variations in the monolayer regime of Sm on the Nb(110) surface 410 (1998) 344
Strzelczyk, M., see Asmussen 406 (1998) 138
Stuhlmann, C., see Wilms 402–404 (1998) 83
Stuke, M., see Stietz 409 (1998) 393
Sturmat, M., see Koch 402–404 (1998) 861
Su, C. and J.-C. Lin, Thermal desorption of hydrogen from the diamond C(100) surface 406 (1998) 149
Suchorski, Yu., R. Imbihl and V.K. Medvedev, Compatibility of field emitter studies of oscillating surface reactions with single crystal measurements: catalytic CO oxidation on Pt 401 (1998) 392
Suchorski, Yu., J. Beben and R. Imbihl, Local fluctuations during catalytic CO oxidation on Pt: a field emission study 405 (1998) L477
Suematsu, H., see Shibata 405 (1998) 153
Sugiura, Y., see Tong 408 (1998) 146
Sugiyama, T., see Matsuura 402–404 (1998) 202
Suhonen, S., see Hirsimäki 402–404 (1998) 187
Sun, Y.Y., see Jiang 405 (1998) L554
Suni, I.I., see Srinivasan 408 (1998) L698
Suraud, E., see Kohl 405 (1998) 74
Suto, S., K. Sakamoto, T. Wakita, M. Harada and A. Kasuya, Interaction of C_{60} with silicon dangling bonds on the Si(111)-(7×7) surface 402–404 (1998) 523
Suzanne, J., see Ferry 409 (1998) 101
Suzuki, E., see Tabata 402–404 (1998) 487
Suzuki, T., see Aoki 408 (1998) 101
Swiech, W., see Tammaro 407 (1998) 162
Szargan, R., see Zerulla 402–404 (1998) 604
Szulczewski, G.J. and J.M. White, Infrared spectroscopy and photodesorption of condensed phase ammonia 406 (1998) 194

Tabata, H., see Kasaya 406 (1998) 302
Tabata, K., T. Choso, A. Murakami and E. Suzuki, Topmost surface analysis of a z-cut $LiNbO_3$ by coaxial impact-collision ion scattering spectroscopy 402–404 (1998) 487
Tabata, K. and T. Chos, The topmost structure of annealed single crystal of $LiNbO_3$ 408 (1998) 137
Takabi, H., see Daimon 408 (1998) 260
Takagi, N., see Okuyama 401 (1998) 344
Takakuwa, Y., see Kim 410 (1998) 99
Takami, T., M. Brause, D. Ochs, W. Maus-Friedrichs, V. Kempter and S. Ino, Study of Au multiple-twinned particle micelles by X-ray photoelectron spectroscopy, ultraviolet photoelectron spectroscopy (HeI) and metastable impact electron spectroscopy 407 (1998) 140
Takami, T., see Tong 408 (1998) 146
Takayanagi, K., see Okamoto 402–404 (1998) 851
Takeda, S., see Tong 408 (1998) 146
Takeda, Y., T. Urano, T. Ohtani, K. Tamiya and S. Hongo, Adsorption structure and silicide formation of Ba on the Si(001) surface 402–404 (1998) 692
Takeda, Y., see Tamiya 408 (1998) 268
Taleb-Ibrahimi, A., see Grupp 408 (1998) 160
Tamiya, K., see Takeda 402–404 (1998) 692
Tamiya, K., T. Ohtani, Y. Takeda, T. Urano and S. Hongo, Adsorption structures of Te on Si(001) surface observed by low energy electron diffraction 408 (1998) 268
Tammaro, M., J.W. Evans, C.S. Rastomjee, W. Swiech, A.M. Bradshaw and R. Imbihl, Reaction–diffusion front propagation across stepped surfaces during catalytic oxidation of CO on Pt(100) 407 (1998) 162
Tanaka, H., G. Mizutani and S. Ushioda, A new resonance of the surface SHG from GaAs(001) in air 402–404 (1998) 533
Tanaka, H. and T. Kanayama, Low-temperature desorption of Si clusters from a graphite surface stabilized by Si desorption 406 (1998) L603
Tanaka, K., T. Fujita and Y. Okawa, Oxygen induced order–disorder restructuring of a Cu(100) surface 401 (1998) L407
Tanaka, K., see An 401 (1998) 336
Tanaka, K., see Lu 409 (1998) 283
Tanaka, M., see Ota 402–404 (1998) 813
Tanemura, M., see Linke 402–404 (1998) 76
Tanishiro, Y., see Latyshev 401 (1998) 22
Tanishiro, Y., see Shimakura 407 (1998) L657
Tanishiro, Y., see Aoki 408 (1998) 101
Tao, H.-S., T.E. Madey and J.E. Rowe, W(111)-based bimetallic systems: core-level photoelectron spectroscopy studies 407 (1998) L640
Tarantelli, F., see Dobrodey 402–404 (1998) 508
Tarasenko, A.A., see Chumak 409 (1998) 137
Taylor, A.G., see Zhang 402–404 (1998) 480
Taylor, R., see Upward 405 (1998) L526

Teehan, D., see Moriarty 405 (1998) 21
Tegenkamp, C., see Malaske 408 (1998) 237
Teillet-Billy, D., see Goryunov 401 (1998) 206
Teillet-Billy, D., see Lorente 402–404 (1998) 197
Tejedor, P., F.E. Allegretti, P. Šmilauer and B.A. Joyce, Temperature-dependent unstable homoepitaxy on vicinal GaAs(110) surfaces 407 (1998) 82
Terashi, M., see Niwano 401 (1998) 364
Terauchi, H., see Yoneda 410 (1998) 62
Tétényi, P., see Hlavathy 410 (1998) 39
Theiss-Bröhl, K., see Hellwig 410 (1998) 362
Theobald, A., see Lindsay 405 (1998) L566
Theobald, A., see Gießel 406 (1998) 90
Thevuthasan, S., G.S. Herman, Y.J. Kim, S.A. Chambers, C.H.F. Peden, Z. Wang, R.X. Ynzunza, E.D. Tober, J. Morais and Ch.S. Fadley, The structure of formate on TiO_2(110) by scanned-energy and scanned-angle photoelectron diffraction 401 (1998) 261
Thevuthasan, S., see Overbury 410 (1998) 106
Thibaudau, F., D. Albertini, L. Masson and F. Salvan, Reply to L. Braun, H. Rauscher, R.J. Behm 409 (1998) L718
Thiel, P.A., see Zhang 406 (1998) 178
Thomann, A.-L., see Brault 406 (1998) L597
Thomas, K.K., see Carley 406 (1998) L587
Thompson, C.E., see Campbell 410 (1998) L768
Thornton, G., see Wincott 402–404 (1998) 705
Thornton, G., see Raza 402–404 (1998) 710
Tian, Z.Q., see Cai 406 (1998) 9
Ticianelli, E.A., see Giacomini 409 (1998) 465
Tober, E.D., see Thevuthasan 401 (1998) 261
Toennies, J.P., see Benedek 406 (1998) L621
Tong, X., Y. Sugiura, T. Nagao, T. Takami, S. Takeda, S. Ino and S. Hasegawa, STM observations of Ag adsorption on the Si(111)–$\sqrt{3}\times3$-Ag surface at low temperatures 408 (1998) 146
Tonti, D., see Kamaratos 402–404 (1998) 37
Toofan, J. and P.R. Watson, The termination of the α-Al_2O_3 (0001) surface: a LEED crystallography determination 401 (1998) 162
Torri, M., see Danani 402–404 (1998) 281
Torri, M., see Danani 409 (1998) 117
Tosatti, E., see Santoro 402–404 (1998) 802
Tosatti, E., see Scandolo 402–404 (1998) 808
Tosatti, E., see Santoro 402–404 (1998) 880
Tosatti, E., see Celestini 402–404 (1998) 886
Toth, J., see Krawczyk 402–404 (1998) 491
Tougaard, S., see Krawczyk 402–404 (1998) 491
Toulhoat, H., see Raybaud 407 (1998) 237
Träger, F., see Stietz 409 (1998) 393
Triguero, L., see Pettersson 408 (1998) 1
Trioni, M.I., F. Montalenti and G.P. Brivio, Ab-initio adiabatic noble gas–metal interaction: the role of the induced polarization charge 401 (1998) L383
Tryk, D.A., see Jiang 408 (1998) 112
Tsong, T.T., see Stępień 409 (1998) 57
Tsong, T.T., see Hwang 410 (1998) L741
Tsuduki, T., see Imanishi 407 (1998) 282
Tsukada, M., N. Sasaki, R. Yamura, N. Sato and K. Abe, Features of cantilever motion in dynamic-mode AFM 401 (1998) 355
Tsukamoto, S., see Shimoda 402–404 (1998) 669
Tsuneyuki, S., see Kikuchi 409 (1998) 458
Tucek, J.C., S.G. Walton and R.L. Champion, Ion-induced secondary electron and negative ion emission from Mo/O 410 (1998) 258
Tuinstra, F., see Steinfort 409 (1998) 229
Tütüncü, H.M., S.J. Jenkins and G.P. Srivastava, A study of atomic vibrations on Si(001)/Sb(2×1) 402–404 (1998) 42
Tütüncü, H.M. and G.P. Srivastava, Vibrational properties of ZnSe(110) surface 402–404 (1998) 649

Uchida, Y., X. Bao, K. Weiss and R. Schlögl, Oxygen-induced restructuring of Au(111) observed by reflection electron microscopy 401 (1998) 469
Uchijima, T., see Nakamura 402–404 (1998) 92
Uebing, C., see Viljoen 410 (1998) 123
Ueta, M., see Hattori 402–404 (1998) 170
Uetsuka, H., see Watanabe 402–404 (1998) 100
Uhlig, I., see Zerulla 402–404 (1998) 604
Umbach, E., K. Glöckler and M. Sokolowski, Surface 'architecture' with large organic molecules: interface order and epitaxy 402–404 (1998) 20
Umbach, E., see Reissner 402–404 (1998) 71
Umbach, E., see Glöckler 405 (1998) 1
Uosaki, K., see Yagi 406 (1998) 1
Upward, M.D., see Moriarty 405 (1998) 21
Upward, M.D., P. Moriarty, P.H. Beton, P.R. Birkett, H.W. Kroto, D.R.M. Walton and R. Taylor, Functionalized fullerenes on silicon surfaces 405 (1998) L526
Upward, M.D., see Moriarty 407 (1998) 27
Urano, T., see Ojima 402–404 (1998) 150
Urano, T., see Hongo 402–404 (1998) 192
Urano, T., see Takeda 402–404 (1998) 692
Urano, T., see Tamiya 408 (1998) 268
Usami, S., see Ota 402–404 (1998) 813
Ushioda, S., see Tanaka 402–404 (1998) 533
Ushioda, S., see Kobayashi 402–404 (1998) 537
Ustaze, S., see Maazouz 409 (1998) 189
Uzer, T., see Dohle 409 (1998) 37

Valbusa, U., see Giudice 405 (1998) L561
Valbusa, U., see Vattuone 408 (1998) L693
Valden, M., see Hirsimäki 402–404 (1998) 187
Valeri, S., see Gazzadi 402–404 (1998) 632
Van Breugel, Y., see Cobden 402–404 (1998) 155
Van der Veen, J.F., see Huisman 402–404 (1998) 866
Van Essenberg, W., see Jenniskens 402–404 (1998) 140
Van Hardeveld, R.M., see Siokou 402–404 (1998) 110
Van Hove, M.A., see Bartoš 402–404 (1998) 697
Van Hove, M.A., see Cerdá 409 (1998) 145
Van Kempen, H., see Stockman 408 (1998) 232
Van Santen, R.A., see Frechard 407 (1998) 200
Vandré, S., see Magnano 402–404 (1998) 223

Vandré, S., see Laine 402–404 (1998) 871
Vandré, S., see Laine 402–404 (1998) 875
Varga, D., see Krawczyk 402–404 (1998) 491
Varga, P., see Hofer 405 (1998) L514
Vargas, M.C. and W.L. Mochán, Comment on: 'Evidence for a deep bound-state level in the ^{4}He–NaCl(001) potential' by G. Benedek, A. Glebov, W. Silvestri, J.G. Skofronick, J.P. Toennies [Surf. Sci. 381 (1997) L540] 406 (1998) L619
Vargas, M.C. and W.L. Mochán, Atom–surface band structure and bound-state resonances. A theoretical study 409 (1998) 130
Vattulainen, I., see Hjelt 402–404 (1998) 253
Vattuone, L., U. Burghaus, U. Valbusa and M. Rocca, Breakdown of normal energy scaling at high impact energy for O_2 on Ag(001) 408 (1998) L693
Väyrynen, J., see Ollonqvist 402–404 (1998) 678
Vedmedenko, E.Y., A. Ghazali and J.-C.S. Lévy, Magnetic structures of Ising and vector spins monolayers by Monte-Carlo simulations 402–404 (1998) 391
Veksler, V.I., Erratum to 'Electron-exchange mechanisms of the secondary ion emission of metals and some incompatible experimental data 409 (1998) 392
Venables, J.A., see Persaud 401 (1998) 12
Venkateswaran, N., see Lam 401 (1998) 34
Venvik, H.J., C. Berg and A. Borg, CO adsorption on Co(10$\bar{1}$2) – a STM study 402–404 (1998) 57
Venvik, H.J., see Berg 409 (1998) 1
Vesely, M., see Bencok 402–404 (1998) 327
Veuillen, J.Y., P. Mallet and J.-M. Gómez-Rodriguez, Growth of Si on disordered Si(111)(1×1) surfaces 402–404 (1998) 295
Vicanek, M., see Brüning 402–404 (1998) 215
Viereck, J., see Stietz 409 (1998) 393
Viljoen, E.C. and C. Uebing, Effect of nitrogen and sulphur on the segregation of molybdenum on single crystalline Fe–3.5%Mo–N, S alloys 410 (1998) 123
Viscido, L., see López-Carreño 402–404 (1998) 174
Viselga, R., see Karlsson 402–404 (1998) 590
Vittadini, A., see Selloni 402–404 (1998) 219
Vobornik, I., C. Quitmann, M. Zacchigna, F. Zwick, M. Grioni, A. Karkin, R.J. Kelley, M. Onellion and G. Margaritondo, Irradiation-induced disorder in high-T_c cuprates: electronic band structure study 402–404 (1998) 761
Vogel, D., P. Krüger and J. Pollmann, Ab-initio calculations of CdS, CdSe and CdTe surfaces 402–404 (1998) 774
Vogtenhuber, D., R. Podloucky and J. Redinger, Ab initio studies of H_2O adsorption on the TiO_2(110) rutile surface 402–404 (1998) 798
Vohs, J.M., see Lam 401 (1998) 34
Von der Linden, W., V. Dose, N. Memmel and R. Fischer, Probabilistic evaluation of growth models based on time-dependent Auger signals 409 (1998) 290
Von Niessen, W., see Kortlüke 401 (1998) 185
Voogt, F.C., see James 402–404 (1998) 332
Voss, C. and N. Kruse, Morphological changes of Rh crystallites in the presence of adsorbed oxygen 409 (1998) 252
Vredenburg, A.M., see Roosendaal 402–404 (1998) 135
W.F. Egelhoff, Jr.., , Fluorine as a surfactant in the deposition of a monolayer of Fe on Cu(100) 402–404 (1998) 32
Wakasugi, T., see Kobayashi 402–404 (1998) 537
Wakita, T., see Suto 402–404 (1998) 523
Wälchli, N., see Kampshoff 406 (1998) 103
Wälchli, N., see Kampshoff 406 (1998) 117
Wallenberg, L.R., see Carlsson 406 (1998) 48
Walmsley, D.G., see Campbell 410 (1998) L768
Walton, D.R.M., see Upward 405 (1998) L526
Walton, S.G., see Tucek 410 (1998) 258
Walz, J., see Wedler 402–404 (1998) 290
Wandelt, K., see Linke 402–404 (1998) 76
Wandelt, K., see Wilms 402–404 (1998) 83
Wandelt, K., see Grüne 402–404 (1998) 236
Wandelt, K., see Shen 406 (1998) 23
Wandelt, K., see Shen 410 (1998) 1
Wang, G.-C., see Zhao 409 (1998) L703
Wang, X.W., see Xu 408 (1998) 317
Wang, Z., see Dorna 401 (1998) L375
Wang, Z., see Thevuthasan 401 (1998) 261
Ward Plummer, E., see Carpinelli 401 (1998) L457
Wassdahl, N., see Hasselström 407 (1998) 221
Watanabe, H. and M. Ichikawa, Influence of the initial Si surface structures on SiO_2/Si(111) interfaces and thermal decomposition of the oxide films 408 (1998) 95
Watanabe, K., H. Ohnuma, H. Kimpara, H. Uetsuka and K. Kunimori, Dynamics and kinetics of CO oxidation on Pd(335): infrared chemiluminescence of CO_2 402–404 (1998) 100
Watanuki, T., see Shibata 405 (1998) 153
Watson, G.M., D. Gibbs, D.M. Zehner, M. Yoon and S.G.J. Mochrie, Orientational phase diagram of the stepped Au(001) surface 407 (1998) 59
Watson, P.R., see Toofan 401 (1998) 162
Weaver, J.H., see Chey 409 (1998) 421
Weaver, M.J., see Gómez 410 (1998) 48
Weber, J., see Zemek 402–404 (1998) 529
Wedler, G., see Kleyna 402–404 (1998) 131
Wedler, G., J. Walz, T. Hesjedal, E. Chilla and R. Koch, Intrinsic stress upon Stranski–Krastanov growth of Ge on Si(001) 402–404 (1998) 290
Weightman, P., see Power 402–404 (1998) 566
Weinelt, M., see Hasselström 407 (1998) 221
Weiss, K., see Uchida 401 (1998) 469
Weiss, W., see Hammer 401 (1998) 455
Weitering, H.H., see Carpinelli 401 (1998) L457
Wen, J.-M., see Zhang 406 (1998) 178
Wende, H., see Srivastava 402–404 (1998) 818
Wenzel, T., see Stietz 409 (1998) 393
Werner, J., see Emundts 410 (1998) L727
Wetli, E., T.J. Kreutz, H. Schmid, T. Greber, J. Osterwalder and M. Hochstrasser, High resolution photoemission study of hcp-Co(0001) 402–404 (1998) 551
Wetzig, D., M. Rutkowski, W. Etterich, R. David and H. Zacharias, Rotational alignment in associative desorption of H_2 from Pd(100) 402–404 (1998) 232

Whangbo, M.-H., see Jung 401 (1998) 476
White, J.M., see Szulczewski 406 (1998) 194
Whitten, J.E. and R. Gomer, The coadsorption of H and O on the W(110) plane 409 (1998) 16
Whitten, J.L., see Yang 401 (1998) 312
Wierzbicki, M. and J. Kocinski, Spatially modulated optical tensors in magnetic superlattices 402–404 (1998) 382
Wiesendanger, R., see Getzlaff 410 (1998) 189
Wilde, L., see Polcik 405 (1998) 112
Wilde, L., M. Polcik, J. Haase, B. Brena, D. Cocco, G. Comelli and G. Paolucci, Adsorption and temperature-dependent decomposition of SO_2 on Ni(110): an XPS and XAFS study 405 (1998) 215
Wilhelm, F., see Srivastava 402–404 (1998) 818
Wilhelmi, G., see Hellwig 410 (1998) 362
Williams, R.S., see Kamins 405 (1998) L580
Wilms, M., P. Broekmann, M. Kruft, Z. Park, C. Stuhlmann and K. Wandelt, STM investigation of specific anion adsorption on Cu(111) in sulfuric acid electrolyte 402–404 (1998) 83
Wimmer, A., see Hammer 401 (1998) 455
Wincott, P.L., A.F. Prime, P.J. Hardman, C.A. Muryn, G. Thornton and P. Bailey, Core level studies of sodium tungsten bronze, $Na_{0.64}WO_3(110)3\times1$ 402–404 (1998) 705
Wincott, P.L., see Raza 402–404 (1998) 710
Winkler, A., see Premm 401 (1998) L444
Winningham, T.A., H.P. Gillis, D.A. Choutov, K.P. Martin, J.T. Moore and K. Douglas, Formation of ordered nanocluster arrays by self-assembly on nanopatterned Si(100) surfaces 406 (1998) 221
Winter, H., see Igel 405 (1998) 182
Winter, H., see Hecht 406 (1998) L607
Witte, G., see Boness 402–404 (1998) 513
Wolfframm, D., see Xue 401 (1998) L401
Wollschläger, J., D. Erdös and K.-M. Schröder, The formation of mosaics during the reactive growth of MgO films on Ag(100) 402–404 (1998) 272
Wolter, H., see Ammer 401 (1998) 138
Wolter, H., see Meinel 401 (1998) 434
Wolter, H., see Meinel 402–404 (1998) 299
Wolter, K., O. Seiferth, J. Libuda, H. Kuhlenbeck, M. Bäumer and H.-J. Freund, Infrared study of CO adsorption on alumina supported palladium particles 402–404 (1998) 428
Woltersdorf, J., see Shen 407 (1998) 90
Wong-Foy, A., see Holbert 401 (1998) L437
Woodruff, D.P., see Lindsay 405 (1998) L566
Woodruff, D.P., see Gießel 406 (1998) 90
Woolf, D.A., see Moriarty 405 (1998) 21
Wright, H., see Singh 409 (1998) 272
Wu, K., see Bludau 402–404 (1998) 786
Wulfhekel, W., see Rosenfeld 402–404 (1998) 401
Wynblatt, P.P., see Lee 408 (1998) 288

Xu, J.G. and X.W. Wang, Study of copper underpotential deposition on Au(111) surfaces 408 (1998) 317
Xu, L., H. Bluhm and M. Salmeron, An AFM study of the tribological properties of NaCl(100) surfaces under moist air 407 (1998) 251
Xue, J.Y., A.P.J. Stampfl, D. Wolfframm, D.A. Evans, M. Hollering, L. Ley, J.D. Riley and R.C.G. Leckey, The surface valence band structure of the two phases of ZnSe(100) 401 (1998) L401
Xue, Z.Q., see Zhao 406 (1998) L614
Xue, Z.Q., see Yang 406 (1998) 229

Yagi, I., S. Nakabayashi and K. Uosaki, Real time monitoring of electrochemical deposition of tellurium on Au(111) electrode by optical second harmonic generation technique 406 (1998) 1
Yagi, K., see Latyshev 401 (1998) 22
Yagi, K., see Horn-von Hoegen 402–404 (1998) 464
Yagi, K., see Shimakura 407 (1998) L657
Yagi, K., see Aoki 408 (1998) 101
Yakovkin, I.N., Metallization of the monolayer Mg film with a linear atomic structure 406 (1998) 57
Yamada, K., J. Asanari, M. Naitoh and S. Nishigaki, Co-adsorption of cesium and oxygen on GaAs(001) surfaces studied by metastable de-excitation spectroscopy 402–404 (1998) 683
Yamamoto, Y., T. Matsuura and J. Murota, Surface reaction of alternately supplied WF_6 and SiH_4 gases 408 (1998) 190
Yamura, R., see Tsukada 401 (1998) 355
Yang, C. and H.C. Kang, Cluster study of the dimer geometry on the C(100) surface 409 (1998) 521
Yang, H. and J.L. Whitten, Chemisorption of OCN on Ni(100) – an ab initio study 401 (1998) 312
Yang, H.Q., see Zhao 406 (1998) L614
Yang, H.Q., J.N. Gao, Y.F. Zhao, Z.Q. Xue and S.J. Pang, Regular defects on the Si(111)-(7×7) surface studied by scanning tunneling microscopy 406 (1998) 229
Yang, W.S., see Gai 405 (1998) L484
Yang, Y.-M., see Chen 406 (1998) 167
Yasue, T., see Nishimura 409 (1998) 183
Yasunaga, H., see Natori 409 (1998) 160
Yeom, H.W., see Matsui 401 (1998) L413
Ying, S.C., see Hjelt 402–404 (1998) 253
Yinnon, A.T., D.A. Lidar (Hamburger), R.B. Gerber, P. Zeppenfeld, M.A. Kryzowski and G. Comsa, Structure determination of disordered metallic sub-monolayers by helium scattering: a theoretical and experimental study 410 (1998) L721
Ynzunza, R., see Daimon 408 (1998) 260
Ynzunza, R.X., see Thevuthasan 401 (1998) 261
Yokoyama, T., see Okamoto 402–404 (1998) 851
Yokoyama, T., see Imanishi 407 (1998) 282
Yoneda, Y., T. Okabe, K. Sakaue and H. Terauchi, Growth of ultrathin $BaTiO_3$ films on $SrTiO_3$ and MgO substrates 410 (1998) 62
Yoon, M., see Watson 407 (1998) 59
Yoshida, K., see Fujii 405 (1998) L549
Yoshihara, J., J.M. Campbell and C.T. Campbell, Cu films on a Zn-terminated ZnO(0001) surface: structure and electronic properties 406 (1998) 235
Yoshihara, J. and C.T. Campbell, Chemisorption of formic acid and

CO on Cu particles on the Zn-terminated ZnO(0001) surface 407 (1998) 256
Yoshii, K., see Baba 402–404 (1998) 115
Yu, H. and K.T. Leung, Generation of 'stabilized' surface species by low-energy interactions of ethylene ions with O- or N-precovered Cu(100) at room temperature 401 (1998) 269
Yu, Z. and A. Flodström, Orientation of (1×1)-surface free energies of crystals 401 (1998) 236
Yuasa, S., see Kirilyuk 402–404 (1998) 356
Yubero, F., see López-Carreño 402–404 (1998) 174
Yun, W.S., see Park 405 (1998) 46
Yurov, V.Yu., see Andryushechkin 407 (1998) L633

Zabala, N., see Aizpurua 402–404 (1998) 418
Zabel, H., see Hellwig 410 (1998) 362
Zacchigna, M., see Vobornik 402–404 (1998) 761
Zacharias, H., see Wetzig 402–404 (1998) 232
Zaera, F., see Gleason 405 (1998) 238
Zaïbi, M.-A., J.-P. Lacharme and C.A. Sébenne, The effect of temperature on NH_3–Si(111) interaction 402–404 (1998) 206
Zanoni, R., see Carbone 407 (1998) 275
Zehner, D.M., see Hammer 401 (1998) 455
Zehner, D.M., see Watson 407 (1998) 59
Zehner, D.M., see Okada 410 (1998) 237
Zei, M.S., see Bludau 402–404 (1998) 786
Zemek, J., V. Kamberský, P. de Haan, J. Weber and P. Janda, Surfaces and interfaces of Pd/Co multilayers 402–404 (1998) 529
Zenobi, R., see Nettesheim 401 (1998) L452
Zeppenfeld, P., see Yinnon 410 (1998) L721
Zerulla, D., I. Uhlig, R. Szargan and T. Chassé, Competing interaction of different thiol species on gold surfaces 402–404 (1998) 604
Zettler, Jh.-T., see Zhang 402–404 (1998) 480
Zhang, C.-M., M.C. Bartelt, J.-M. Wen, C.J. Jenks, J.W. Evans and P.A. Thiel, Submonolayer island formation and the onset of multilayer growth during Ag/Ag(100) homoepitaxy 406 (1998) 178
Zhang, J., A.K. Lees, A. Schnellinger, J.R. Engstrom, M.L. Hsieh, Jh.-T. Zettler, A.G. Taylor and B.A. Joyce, Kinetics and dynamics of Si GSMBE studied by reflectance anisotropy spectroscopy 402–404 (1998) 480
Zhang, Z.H. and H.E. Elsayed-Ali, Surface morphology of laser superheated Pb(111) 405 (1998) 271
Zhao, R.G., see Gai 405 (1998) L484
Zhao, Y.-P., C.-F. Cheng, G.-C. Wang and T.-M. Lu, Power law behavior in diffraction from fractal surfaces 409 (1998) L703
Zhao, Y.F., H.Q. Yang, J.N. Gao, Z.Q. Xue and S.J. Pang, Site-specific binding energy terms on Si(111)-7×7 surface. A reflection of local binding behavior of surface atoms 406 (1998) L614
Zhao, Y.F., see Yang 406 (1998) 229
Zharnikov, M., see Camarero 402–404 (1998) 346
Zhdanov, V.P., Domain growth and rate processes in adsorbed overlayers 401 (1998) 412
Zhdanov, V.P. and B. Kasemo, Monte Carlo simulation of the kinetics of rapid reactions on nanometer catalyst particles 405 (1998) 27
Zheng, G., see Nakakura 401 (1998) 173
Zhilin, V., see Layet 402–404 (1998) 724
Zhong, B., see Guo 409 (1998) 452
Zhou, J.M., see Guo 406 (1998) L592
Zhou, Y., see Bensebaa 405 (1998) L472
Ziegler, J.C., see Engelmann 401 (1998) L420
Zschack, P., see Landree 408 (1998) 300
Zwick, F., see Vobornik 402–404 (1998) 761

Surface Science 401–410 (1998) 29–70

Subject index to volumes 401–410

THEORETICAL METHODS, MODELS AND TECHNIQUES

Ab initio quantum chemical methods and calculations

H. Yang and J.L. Whitten, Chemisorption of OCN on Ni(100) – an ab initio study 401 (1998) 312

A. Marcellini, C.A. Pignedoli, M. Ferrario and C.M. Bertoni, Interaction of Cl_2 molecules with GaAs(110) surface 402–404 (1998) 47

V. Musolino, A. Selloni and R. Car, Atomic and electronic structure of Cu clusters on MgO 402–404 (1998) 413

N.V. Dobrodey, L.S. Cederbaum and F. Tarantelli, Strong dynamical screening in weak chemisorption systems 402–404 (1998) 508

A.V. Puchina, V.E. Puchin, M. Huisinga, R. Bennewitz and M. Reichling, Theoretical modelling of steps and surface oxidation on $CaF_2(111)$ 402–404 (1998) 687

D. Vogel, P. Krüger and J. Pollmann, Ab-initio calculations of CdS, CdSe and CdTe surfaces 402–404 (1998) 774

O. Gülseren, D.M. Bird and S.E. Humphreys, A mixed-basis approach for the efficient calculation of potential energy surfaces 402–404 (1998) 827

B.K. Agrawal, P. Srivastava and S. Agrawal, First-principles calculation of electron surface states of the zinc-blende GaN(110) surface 405 (1998) 54

A. Allouche, Water adsorption on NaCl(100): a quantum ab-initio cluster calculation 406 (1998) 279

J.A. Rodriguez, T. Jirsak, S. Chaturvedi and J. Hrbek, The interaction of H_2S and S_2 with Cs and Cs/ZnO surfaces: photoemission and molecular-orbital studies 407 (1998) 171

F. Frechard and R.A. van Santen, Theoretical study of the adsorption of the atomic oxygen on the Cu(110) surface 407 (1998) 200

L.G.M. Pettersson, H. Ågren, Y. Luo and L. Triguero, Benzene adsorbed on Cu(110): theoretical X-ray absorption, emission and shake calculations 408 (1998) 1

B. Paulus, Correlation calculations for the reconstruction of the Si(100) surface 408 (1998) 195

B.K. Agrawal, S. Agrawal and P. Srivastava, Electronic localized and resonance states of relaxed GaAs(110) surfaces – an ab initio LMTO approach 408 (1998) 275

M.A. San Miguel, C.J. Calzado and J.F. Sanz, Molecular dynamics simulations of Na deposition on the $TiO_2(110)$ surface 409 (1998) 92

S.P. Bates, G. Kresse and M.J. Gillan, The adsorption and dissociation of ROH molecules on $TiO_2(110)$ 409 (1998) 336

Atom–solid interactions, scattering, diffraction

M. Bauer, S. Pawlik, R. Burgermeister and M. Aeschlimann, Symmetry properties of an electronic alkali excitation at a noble metal surface as investigated by two-photon photoemission 402–404 (1998) 62

R. Lindsay, A. Theobald, T. Gießel, O. Schaff, A.M. Bradshaw, N.A. Booth and D.P. Woodruff, The structure of NO on Ni(111) at low coverage 405 (1998) L566

T. Hecht, H. Winter and A.G. Borisov, Auger transition rates for the neutralization of He^+ ions in front of an aluminium surface 406 (1998) L607

M.C. Vargas and W.L. Mochán, Comment on: 'Evidence for a deep bound-state level in the ^{4}He–NaCl(001) potential' by G. Benedek, A. Glebov, W. Silvestri, J.G. Skofronick, J.P. Toennies [Surf. Sci. 381 (1997) L540] 406 (1998) L619

A.T. Yinnon, D.A. Lidar (Hamburger), R.B. Gerber, P. Zeppenfeld, M.A. Kryzowski and G. Comsa, Structure determination of disordered metallic sub-monolayers by helium scattering: a theoretical and experimental study 410 (1998) L721

S. Lacombe, L. Guillemot, M. Maazouz, N. Mandarino, E. Sanchez and V.A. Esaulov, Scattering of He and Ne atoms and ions on a Na surface 410 (1998) 70

E.V. Blagov, G.L. Klimchitskaya and V.M. Mostepanenko, Impact of atomic relaxation on the breaks of constant force surfaces in AFM 410 (1998) 158

Atomistic dynamics

S.W. Levine, J.R. Engstrom and P. Clancy, A kinetic Monte Carlo study of the growth of Si on Si(100) at varying angles of incident deposition 401 (1998) 112

A. Natori, M. Murayama, D. Matsumoto and H. Yasunaga, Decay process of a crater/hillock and step structure transformation 409 (1998) 160

B.N.J. Persson and J.W. Gadzuk, Comments on vibrational dynamics of low-frequency adsorbate motion 410 (1998) L779

Computer simulations

S. Schinzer and W. Kinzel, Modelling sublimation by computer simulation: morphology-dependent effective energies 401 (1998) 96

Computer simulations (continued)

S.W. Levine, J.R. Engstrom and P. Clancy, A kinetic Monte Carlo study of the growth of Si on Si(100) at varying angles of incident deposition 401 (1998) 112

O. Kortlüke and W. von Niessen, A Monte Carlo simulation of the CO+NO surface reaction involving molecular NO adsorption and several reaction paths 401 (1998) 185

M.R. Dudek, J.-F. Gouyet and M. Kolb, Q+1 state Potts model of late stage sintering 401 (1998) 220

M. Tsukada, N. Sasaki, R. Yamura, N. Sato and K. Abe, Features of cantilever motion in dynamic-mode AFM 401 (1998) 355

V.P. Zhdanov, Domain growth and rate processes in adsorbed overlayers 401 (1998) 412

M. Kotrla, M. Předota and F. Slanina, Kinetic roughening and phase ordering in the two-component growth model 402–404 (1998) 249

T. Hjelt, I. Vattulainen, J. Merikoski, T. Ala-Nissila and S.C. Ying, Dynamical mean field theory: an efficient method to study surface diffusion coefficients 402–404 (1998) 253

A.A. Cafolla, A new stochastic optimisation strategy for quantitative analysis of core level photoemission data 402–404 (1998) 561

M. Naitoh, A. Konishi, H. Inenaga, S. Nishigaki, N. Oishi and F. Shoji, Ga-rich GaP(001)(2×4) surface structure studied by low-energy ion scattering spectroscopy 402–404 (1998) 623

F. Celestini, D. Passerone, F. Ercolessi and E. Tosatti, Realistic grand canonical Monte Carlo surface simulation: application to Ar(111) 402–404 (1998) 886

V.P. Zhdanov and B. Kasemo, Monte Carlo simulation of the kinetics of rapid reactions on nanometer catalyst particles 405 (1998) 27

J.A. Nieminen and S. Paavilainen, Adsorption site and STM image of O_2 on Pt{111} 405 (1998) L573

E. Landree, L.D. Marks, P. Zschack and C.J. Gilmore, Structure of the TiO_{2-x}(100)-1×3 surface by direct methods 408 (1998) 300

A. Natori, M. Murayama, D. Matsumoto and H. Yasunaga, Decay process of a crater/hillock and step structure transformation 409 (1998) 160

H. Kim and J.R. Chelikowsky, Electronic and structural properties of the As vacancy on the (110) surface of GaAs 409 (1998) 435

X.-Y. Guo, B. Zhong and P. Brault, Growth and ripening of two-dimensional palladium islands on Ni(111) surface 409 (1998) 452

M. Mazroui, A. Asaklil and Y. Boughaleb, Conductivity of two-dimensional systems of interacting Brownian particles within the effective potential description 409 (1998) 528

L. Haderbache, R. Garrigos, R. Kofman, E. Søndergard and P. Cheyssac, Numerical and experimental investigations of the size ordering of nanocrystals 410 (1998) L748

Construction and use of effective interatomic interactions

C. Kohl, F. Calvayrac, P.-G. Reinhard and E. Suraud, Optical response of Na clusters on NaCl surfaces 405 (1998) 74

H.-V. Roy, C. Kallinger and K. Sattler, Study of single and multiple foldings of graphitic sheets 407 (1998) 1

Density functional calculations

M.I. Trioni, F. Montalenti and G.P. Brivio, Ab-initio adiabatic noble gas–metal interaction: the role of the induced polarization charge 401 (1998) L383

A. Selloni, A. Vittadini and M. Grätzel, The adsorption of small molecules on the TiO_2 anatase (101) surface by first-priciples molecular dynamics 402–404 (1998) 219

V. Musolino, A. Selloni and R. Car, Atomic and electronic structure of Cu clusters on MgO 402–404 (1998) 413

S.C.A. Gay, S.J. Jenkins and G.P. Srivastava, Ab-initio density functional calculations for Si(001)/Bi(1 ML)-(2×1) 402–404 (1998) 641

S.J. Jenkins, G.P. Srivastava, R.J. Dixon and C.F. McConville, Ab initio calculation of geometry and bonding for overlaid and inlaid models of Si(001)/Sb(0.25 ML)-c(4×4) 402–404 (1998) 645

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S. Thevuthasan, G.S. Herman, Y.J. Kim, S.A. Chambers, C.H.F. Peden, Z. Wang, R.X. Ynzunza, E.D. Tober, J. Morais and Ch.S. Fadley, The structure of formate on $TiO_2(110)$ by scanned-energy and scanned-angle photoelectron diffraction 401 (1998) 261

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L. Jurczyszyn, N. Mingo and F. Flores, Influence of the atomic and electronic structure of the tip on STM images and STS spectra 402–404 (1998) 459

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Jellium models

M.I. Trioni, F. Montalenti and G.P. Brivio, Ab-initio adiabatic noble gas–metal interaction: the role of the induced polarization charge 401 (1998) L383

Models of non-equilibrium phenomena

V.P. Zhdanov, Domain growth and rate processes in adsorbed overlayers 401 (1998) 412
B.N.J. Persson, On the theory of rubber friction 401 (1998) 445
V.P. Zhdanov and B. Kasemo, Monte Carlo simulation of the kinetics of rapid reactions on nanometer catalyst particles 405 (1998) 27
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M. Tsukada, N. Sasaki, R. Yamura, N. Sato and K. Abe, Features of cantilever motion in dynamic-mode AFM 401 (1998) 355
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Models of surface chemical reactions

H.T. Lam, N. Venkateswaran and J.M. Vohs, The reactions of diethylzinc on gallium-rich and arsenic-rich reconstructions of GaAs(100) 401 (1998) 34
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M.A. San Miguel, C.J. Calzado and J.F. Sanz, Molecular dynamics simulations of Na deposition on the TiO_2(110) surface 409 (1998) 92

Models of surface kinetics

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C.Y. Nakakura, G. Zheng and E.I. Altman, Atomic-scale mechanisms of the halogenation of Cu(100) 401 (1998) 173
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S. Liu and H. Metiu, A kinetic model for island shape variations under epitaxial growth conditions 405 (1998) L497
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Molecular dynamics

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EXPERIMENTAL SAMPLE PREPARATION AND CHARACTERIZATION METHODS

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Chemical vapor deposition

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Scanning transmission electron microscopy (STEM)

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Electron microscopy (continued)

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Laser annealing

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Non-linear optical methods

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Photoelectron spectroscopy

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Surface roughening

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Surface segregation

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Surface segregation (continued)

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K. Miki, K. Sakamoto and T. Sakamoto, Surface preparation of Si substrates for epitaxial growth 406 (1998) 312

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H.-V. Roy, C. Kallinger and K. Sattler, Study of single and multiple foldings of graphitic sheets 407 (1998) 1

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Surface structure, morphology, roughness, and topography (continued)

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P. Raybaud, J. Hafner, G. Kresse and H. Toulhoat, Structural and electronic properties of the $MoS_2(10\bar{1}0)$ edge-surface 407 (1998) 237

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M.A. San Miguel, C.J. Calzado and J.F. Sanz, Molecular dynamics simulations of Na deposition on the TiO_2(110) surface 409 (1998) 92

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W. von der Linden, V. Dose, N. Memmel and R. Fischer, Probabilistic evaluation of growth models based on time-dependent Auger signals 409 (1998) 290

S. Durukanoğlu and T.S. Rahman, Atomic relaxations and thermodynamics on Cu(410) 409 (1998) 395

S.J. Chey, Y. Gong and J.H. Weaver, Surface morphologies of Br-etched Ge/Si(001) 409 (1998) 421

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Y.G. Shen, D.J. O'Connor and K. Wandelt, The surface composition, structure and oxygen-induced (2×1) reconstruction of Cu_3Pt(110) 410 (1998) 1

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O. Hellwig, K. Theiss-Bröhl, G. Wilhelmi and H. Zabel, Growth of fcc(111) on bcc(110): Influence of growth and annealing temperature on epitaxy and surface morphology for Pd on Cr 410 (1998) 362

Surface tension

H.K. Lee, R.W. Hyland, Jr., H.I. Aaronson and P.P. Wynblatt, Surface segregation in an Al–4.2 at% Ag alloy 408 (1998) 288

Surface thermodynamics (including phase transitions)

K. Tanaka, T. Fujita and Y. Okawa, Oxygen induced order–disorder restructuring of a Cu(100) surface 401 (1998) L407

J.G. Che and C.T. Chan, Possible faceting transformation of Mo from (111) to {110} 401 (1998) L432

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Surface thermodynamics (including phase transitions) (continued)
dimensional clusters on crystal surfaces: from Ostwald ripening to single cluster decay 402–404 (1998) 401
L.Z. Mezey and W. Hofer, Thermodynamic calculation of global and local surface compositions of PtRh: a case of surface clustering even with bulk ordering 402–404 (1998) 845
R. Koch and M. Sturmat, High-temperature STM of the phase transitions of Au(110) and Pt(110) 402–404 (1998) 861
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F. Celestini, D. Passerone, F. Ercolessi and E. Tosatti, Realistic grand canonical Monte Carlo surface simulation: application to Ar(111) 402–404 (1998) 886
J. Shen, C. Schmidthals, J. Woltersdorf and J. Kirschner, Structural phase transformation under reversed strain: a comparative study of iron ultrathin film growth on nickel and copper (100) 407 (1998) 90
D.Y. Petrovykh, F.J. Himpsel and T. Jung, Width distribution of nanowires grown by step decoration 407 (1998) 189
H.K. Lee, R.W. Hyland, Jr., H.I. Aaronson and P.P. Wynblatt, Surface segregation in an Al–4.2 at% Ag alloy 408 (1998) 288
A.A. Chumak and A.A. Tarasenko, The effect of reconstructed-surface order-parameter disturbances on adatom diffusion 409 (1998) 137
S. Durukanoğlu and T.S. Rahman, Atomic relaxations and thermodynamics on Cu(410) 409 (1998) 395

Surface waves

G.R. Bell, T.S. Jones and C.F. McConville, Spatial variation of plasmon damping near the polar surfaces of InAs in InSb 405 (1998) 280
D. Schumacher, C. Rea, D. Heitmann and K. Scharnberg, Surface plasmons and Sommerfeld–Zenneck waves on corrugated surfaces. Application to high-T_c superconductors 408 (1998) 203

Phonons

H.M. Tütüncü, S.J. Jenkins and G.P. Srivastava, A study of atomic vibrations on Si(001)/Sb(2×1) 402–404 (1998) 42
J. Kröger, S. Lehwald and H. Ibach, Substrate surface phonons in the cases of saturated (1×1)H/Mo(110) and p(2×2)O/Mo(110) – a critical comparison 402–404 (1998) 496
H.M. Tütüncü and G.P. Srivastava, Vibrational properties of ZnSe(110) surface 402–404 (1998) 649
M. Lazzeri and S. de Gironcoli, Ab-initio dynamical properties of the Be(0001) surface 402–404 (1998) 715

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G.R. Bell, N.S. Kaijaks, R.J. Dixon and C.F. McConville, Atomic hydrogen cleaning of polar III–V semiconductor surfaces 401 (1998) 125
R. Biagi, L. Rettighieri, U. del Pennino, V. Panella and P. Dumas, Charge accumulation layer induced by potassium adsorption on hydrogen terminated Si(111)(1×1) 402–404 (1998) 547
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G.R. Bell, T.S. Jones and C.F. McConville, Spatial variation of plasmon damping near the polar surfaces of InAs in InSb 405 (1998) 280
V.A. Kosobukin, Magneto-optics via the near field 406 (1998) 32
Y.F. Chen, Inelastic electron interactions in overlayers on substrates 407 (1998) 73
D. Schumacher, C. Rea, D. Heitmann and K. Scharnberg, Surface plasmons and Sommerfeld–Zenneck waves on corrugated surfaces. Application to high-T_c superconductors 408 (1998) 203

Thermal desorption

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S.M. Barlow, K.J. Kitching, S. Haq and N.V. Richardson, A study of glycine adsorption on a Cu{110} surface using reflection absorption infrared spectroscopy 401 (1998) 322
H. Okuyama, W. Siga, N. Takagi, M. Nishijima and T. Aruga, Path and mechanism of hydrogen absorption at Pd(100) 401 (1998) 344
K. Ojima, S. Hongo and T. Urano, Low temperature decomposition mechanism of BaH_2 formed on Si(100) surfaces 402–404 (1998) 150
S. Hongo, S. Kaneko, T. Fukuhara and T. Urano, Coadsorption of lithium and hydrogen on Si(100)2×1 şurfaces studied by metastable de-excitation spectroscopy and thermal desorption spectroscopy 402–404 (1998) 192
S. Hadenfeldt and C. Benndorf, Adsorption of fluorine and chlorine on the diamond (100) surface 402–404 (1998) 227
M.F. Luo, Z.Y. Li and W. Allison, Initial stages of C_{60} thin film growth on graphite 402–404 (1998) 437
I.Z. Jones, R.A. Bennett and M. Bowker, CO adsorption on Pd(110) 402–404 (1998) 595
J.H. Larsen and I. Chorkendorff, Increased dissociation probability of CH_4 on Co/Cu(111) 405 (1998) 62
H. Tanaka and T. Kanayama, Low-temperature desorption of Si clusters from a graphite surface stabilized by Si desorption 406 (1998) L603
C. Su and J.-C. Lin, Thermal desorption of hydrogen from the diamond C(100) surface 406 (1998) 149
J.E. Whitten and R. Gomer, The coadsorption of H and O on the W(110) plane 409 (1998) 16
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J.R. Creighton and K.C. Baucom, Reflectance-difference spectroscopy of adsorbate-covered GaAs(100) surfaces: a combined surface science and in-situ OMVPE study 409 (1998) 372

Thermal desorption (continued)

J.W. Peck, D.I. Mahon and B.E. Koel, A temperature programmed desorption study of the reaction of methylacetylene on Pt(111) and Sn/Pt(111) surface alloys 410 (1998) 200

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Tribology

A.W. Holbert, J.D. Batteas, A. Wong-Foy, T.S. Rufael and C.M. Friend, Passivation of Fe(110) via phosphorus deposition: the reactions of trimethylphosphite 401 (1998) L437

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C.F. McFadden and A.J. Gellman, Metallic friction: the effect of molecular adsorbates 409 (1998) 171

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Tunneling

D.G. Goryunov, A.G. Borisov, G.E. Makhmetov, D. Teillet-Billy and J.P. Gauyacq, Li^+ neutralisation in back-scattering from alkali/Al(100) surfaces: comparison between the various alkalis 401 (1998) 206

H. Okuyama, W. Siga, N. Takagi, M. Nishijima and T. Aruga, Path and mechanism of hydrogen absorption at Pd(100) 401 (1998) 344

L. Jurczyszyn, N. Mingo and F. Flores, Influence of the atomic and electronic structure of the tip on STM images and STS spectra 402–404 (1998) 459

M. Kasaya, H. Tabata and T. Kawai, Scanning tunneling microscopy and molecular orbital calculation of organic molecules adsorbed on the Si(100)2×1 surface 406 (1998) 302

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Vibrations of adsorbed molecules

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S. Suto, K. Sakamoto, T. Wakita, M. Harada and A. Kasuya, Interaction of C_{60} with silicon dangling bonds on the Si(111)-(7×7) surface 402–404 (1998) 523

G.S. Hsiao, W. Erley and H. Ibach, Probing the surface acidity of single crystal alumina surfaces: CO adsorption as measured by infrared reflection absorption spectroscopy 405 (1998) L465

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F. Solymosi and G. Klivényi, Effects of potassium on the adsorption and dissociation of dimethyl ether on Rh(111) 409 (1998) 241

B.N.J. Persson and J.W. Gadzuk, Comments on vibrational dynamics of low-frequency adsorbate motion 410 (1998) L779

M. Okada, A.P. Baddorf and D.M. Zehner, Hydrogen adsorption on $Mo_{1-x}Re_x$(110) (x=0–0.25) surfaces 410 (1998) 237

Wetting

L. Haderbache, R. Garrigos, R. Kofman, E. Søndergard and P. Cheyssac, Numerical and experimental investigations of the size ordering of nanocrystals 410 (1998) L748

Surface Science 401–410 (1998) 71–110

Materials index to volumes 401–410

ELEMENTAL AND CHEMICAL IDENTITY

Elements

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Alkali metals

J. Nerlov, S.V. Hoffmann, M. Shimomura and P.J. Møller, Coadsorption of Na and CO_2 on the $Fe_3O_4(111)$ termination of α-$Fe_2O_3(0001)$: relations between structure and activation 401 (1998) 56

S. Chaturvedi and J.A. Rodriguez, Interactions between Cs and noble metals (Cu, Ag, Au) on ZnO surfaces: electronic perturbations and alloy formation 401 (1998) 282

Yu. Suchorski, R. Imbihl and V.K. Medvedev, Compatibility of field emitter studies of oscillating surface reactions with single crystal measurements: catalytic CO oxidation on Pt 401 (1998) 392

M. Bauer, S. Pawlik, R. Burgermeister and M. Aeschlimann, Symmetry properties of an electronic alkali excitation at a noble metal surface as investigated by two-photon photoemission 402–404 (1998) 62

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M. Brandt, T. Greber, F. Kuhlmann, N. Böwering and U. Heinzmann, State- and orientation-dependent N_2 emission in the N_2O+Cs reaction 402–404 (1998) 160

S. Hongo, S. Kaneko, T. Fukuhara and T. Urano, Coadsorption of lithium and hydrogen on Si(100)2×1 surfaces studied by metastable de-excitation spectroscopy and thermal desorption spectroscopy 402–404 (1998) 192

F. Balzer, R. Gerlach, M. Schober and H.-G. Rubahn, An HAS study of laser irradiation of alkali-covered dielectrics 402–404 (1998) 841

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S.Y. Davydov, Low-energy ($\langle$10 eV) O^+ ions transmission through alkali-metal submonolayers 408 (1998) 21

K. Tabata and T. Chos, The topmost structure of annealed single crystal of $LiNbO_3$ 408 (1998) 137

C. Grupp and A. Taleb-Ibrahimi, Huge charge transfer from potassium on H:Si(111)-(1×1) 408 (1998) 160

M.A. San Miguel, C.J. Calzado and J.F. Sanz, Molecular dynamics simulations of Na deposition on the $TiO_2(110)$ surface 409 (1998) 92

F. Solymosi and G. Klivényi, Effects of potassium on the adsorption and dissociation of dimethyl ether on Rh(111) 409 (1998) 241

U. del Pennino, R. Companò, B. Salvarani and C. Mariani, Alkali metal/GaAs(110) interfaces: correlation effects and sub-gap electron energy loss spectra 409 (1998) 258

C.C. Perry, S. Haq, B.G. Frederick and N.V. Richardson, Face specificity and the role of metal adatoms in molecular reorientation at surfaces 409 (1998) 512

H. Kleine, H. Bludau, H. Over and D. Fick, The 3×1-Li to 7×7 structural transformation of Si(111) due to Li desorption 410 (1998) 15

Alkaline earth metals

K. Ojima, S. Hongo and T. Urano, Low temperature decomposition mechanism of BaH_2 formed on Si(100) surfaces 402–404 (1998) 150

I.N. Yakovkin, Metallization of the monolayer Mg film with a linear atomic structure 406 (1998) 57

Aluminum

J. Toofan and P.R. Watson, The termination of the α-Al_2O_3 (0001) surface: a LEED crystallography determination 401 (1998) 162

D.G. Goryunov, A.G. Borisov, G.E. Makhmetov, D. Teillet-Billy and J.P. Gauyacq, Li^+ neutralisation in back-scattering from alkali/Al(100) surfaces: comparison between the various alkalis 401 (1998) 206

R. Linke, Th. Pelster, M. Tanemura, C. Becker and K. Wandelt, Adsorption of CO on the ordered $Ni_3Al(111)$ surface 402–404 (1998) 76

N. Lorente, D. Teillet-Billy and J.-P. Gauyacq, Charge transfer as responsible for H_2^+ dissociation on aluminum surfaces 402–404 (1998) 197

T. Sonoda and M. Kato, Formation of Ti/O compositional gradient film on Ti–6Al–4V alloy by reactive DC sputtering 402–404 (1998) 241

S. Stempel, M. Bäumer and H.-J. Freund, STM studies of rhodium deposits on an ordered alumina film-resolution and tip effects 402–404 (1998) 424

Elements (continued)

L. Jurczyszyn, N. Mingo and F. Flores, Influence of the atomic and electronic structure of the tip on STM images and STS spectra 402–404 (1998) 459

G.S. Hsiao, W. Erley and H. Ibach, Probing the surface acidity of single crystal alumina surfaces: CO adsorption as measured by infrared reflection absorption spectroscopy 405 (1998) L465

M. Polcik, L. Wilde and J. Haase, Surface melting of Al(110) studied by surface extended X-ray absorption fine structure 405 (1998) 112

B.C. Mitrovic and D.J. O'Connor, Negative direct recoil spectroscopy study of the initial oxidation of Al(111) 405 (1998) 261

T. Hecht, H. Winter and A.G. Borisov, Auger transition rates for the neutralization of He^+ ions in front of an aluminium surface 406 (1998) L607

W. Oueini, M. Rouanet and J. Bonnet, Formation of the Al–GaSb(110) interface 409 (1998) 445

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J.C. Tucek, S.G. Walton and R.L. Champion, Ion-induced secondary electron and negative ion emission from Mo/O 410 (1998) 258

Antimony

A. Cricenti, P. Perfetti and G. Le Lay, High-resolution Si 2p core-level photoemission spectroscopy on Sb-terminated Si(100) surfaces: evidence for a strong interfacial component 401 (1998) 427

H.M. Tütüncü, S.J. Jenkins and G.P. Srivastava, A study of atomic vibrations on Si(001)/Sb(2×1) 402–404 (1998) 42

S.J. Jenkins, G.P. Srivastava, R.J. Dixon and C.F. McConville, Ab initio calculation of geometry and bonding for overlaid and inlaid models of Si(001)/Sb(0.25 ML)-c(4×4) 402–404 (1998) 645

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Arsenic

A.K. Ott, S.M. Casey and S.R. Leone, Arsenic desorption kinetics from Si(100) 405 (1998) 228

Barium

E. Magnano, S. Vandré, J. Kovac, E. Narducci, R. Caloi, P. Manini and M. Sancrotti, Surface and subsurface properties of a $BaLi_4$ gettering alloy studied using X-ray photoemission spectroscopy 402–404 (1998) 223

Y. Takeda, T. Urano, T. Ohtani, K. Tamiya and S. Hongo, Adsorption structure and silicide formation of Ba on the Si(001) surface 402–404 (1998) 692

Beryllium

M. Lazzeri and S. de Gironcoli, Ab-initio dynamical properties of the Be(0001) surface 402–404 (1998) 715

Bismuth

S.C.A. Gay, S.J. Jenkins and G.P. Srivastava, Ab-initio density functional calculations for Si(001)/Bi(1 ML)-(2×1) 402–404 (1998) 641

L. Gavioli, M.G. Betti and C. Mariani, Electronic properties of the Bi/Si(100) interface 409 (1998) 207

Boron

K. Miki, K. Sakamoto and T. Sakamoto, Surface preparation of Si substrates for epitaxial growth 406 (1998) 312

Bromine

C.Y. Nakakura, G. Zheng and E.I. Altman, Atomic-scale mechanisms of the halogenation of Cu(100) 401 (1998) 173

B. Shen, X. Chen, K. Fan and J.-F. Deng, BOC-MP study on the mechanism of partial oxidation of CH_3OH to HCHO over a silver surface and the promoting effect of halogen to the catalyst 408 (1998) 128

S.J. Chey, Y. Gong and J.H. Weaver, Surface morphologies of Br-etched Ge/Si(001) 409 (1998) 421

Carbon

W. Arabczyk and U. Narkiewicz, The effect of the real crystal structure of iron on the behaviour of surface contaminants 402–404 (1998) 502

G. Andersson and H. Morgner, Impact collision ion scattering spectroscopy (ICISS) and neutral impact collision ion scattering spectroscopy (NICISS) at surfaces of organic liquids 405 (1998) 138

P. Brault, A.-L. Thomann and C. Andreazza-Vignolle, Percolative growth of palladium ultrathin films deposited by plasma sputtering 406 (1998) L597

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PHYSICAL STATE

Surfaces

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Surfaces (continued)

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Interfaces

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Liquid–gas interfaces

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Single crystal epitaxy

S. Mróz, H. Otop and Z. Jankowski, On the role of Pb in epitaxial growth of thin Co films on Cu(111) 402–404 (1998) 263

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Heterostructures

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Non-epitaxial thin film structures

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Y.F. Zhao, H.Q. Yang, J.N. Gao, Z.Q. Xue and S.J. Pang, Site-specific binding energy terms on Si(111)-7×7 surface. A reflection of local binding behavior of surface atoms 406 (1998) L614

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L.G.M. Pettersson, H. Ågren, Y. Luo and L. Triguero, Benzene adsorbed on Cu(110): theoretical X-ray absorption, emission and shake calculations 408 (1998) 1

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M.A. San Miguel, C.J. Calzado and J.F. Sanz, Molecular dynamics simulations of Na deposition on the TiO_2(110) surface 409 (1998) 92

M.C. Vargas and W.L. Mochán, Atom–surface band structure and bound-state resonances. A theoretical study 409 (1998) 130

A.A. Chumak and A.A. Tarasenko, The effect of reconstructed-surface order-parameter disturbances on adatom diffusion 409 (1998) 137

F. Solymosi and G. Klivényi, Effects of potassium on the adsorption and dissociation of dimethyl ether on Rh(111) 409 (1998) 241

C.C. Perry, S. Haq, B.G. Frederick and N.V. Richardson, Face specificity and the role of metal adatoms in molecular reorientation at surfaces 409 (1998) 512

A.A. Bailes, III, M.A. Boshart and L.E. Seiberling, Dimer elongation on the monohydride-covered Ge/Si(100) surface 410 (1998) L762

B.N.J. Persson and J.W. Gadzuk, Comments on vibrational dynamics of low-frequency adsorbate motion 410 (1998) L779

M. Getzlaff, M. Bode and R. Wiesendanger, Hydrogen adsorption on Gd(0001) 410 (1998) 189

N. Saliba, D.H. Parker and B.E. Koel, Adsorption of oxygen on Au(111) by exposure to ozone 410 (1998) 270

Clusters

H. Yang and J.L. Whitten, Chemisorption of OCN on Ni(100) – an ab initio study 401 (1998) 312

K. Hattori, K. Shudo, M. Ueta, T. Iimori and F. Komori, Hydrogen–chlorine exchange reaction on Si(111)-7×7 studied with STM 402–404 (1998) 170

M. Esser, K. Morgenstern, G. Rosenfeld and G. Comsa, Dynamics of vacancy islands coalescence on Ag(111) 402–404 (1998) 341

G. Rosenfeld, K. Morgenstern, I. Beckmann, W. Wulfhekel, E. Lægsgaard, F. Besenbacher and G. Comsa, Stability of two-

Clusters (continued)

dimensional clusters on crystal surfaces: from Ostwald ripening to single cluster decay 402–404 (1998) 401

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V. Musolino, A. Selloni and R. Car, Atomic and electronic structure of Cu clusters on MgO 402–404 (1998) 413

K. Wolter, O. Seiferth, J. Libuda, H. Kuhlenbeck, M. Bäumer and H.-J. Freund, Infrared study of CO adsorption on alumina supported palladium particles 402–404 (1998) 428

A. Bettac, L. Köller, V. Rank and K.-H. Meiwes-Broer, Scanning tunneling spectroscopy on deposited platinum clusters 402–404 (1998) 475

C. Kohl, F. Calvayrac, P.-G. Reinhard and E. Suraud, Optical response of Na clusters on NaCl surfaces 405 (1998) 74

T.I. Kamins and R.S. Williams, A model for size evolution of pyramidal Ge islands on Si(001) during annealing 405 (1998) L580

P. Brault, A.-L. Thomann and C. Andreazza-Vignolle, Percolative growth of palladium ultrathin films deposited by plasma sputtering 406 (1998) L597

H. Tanaka and T. Kanayama, Low-temperature desorption of Si clusters from a graphite surface stabilized by Si desorption 406 (1998) L603

A. Barbier, Generalized model for interface description 406 (1998) 69

M. García-Hernández, P.S. Bagus and F. Illas, A new analysis of image charge theory 409 (1998) 69

D. Babonneau, T. Cabioc'h, A. Naudon, J.C. Girard and M.F. Denanot, Silver nanoparticles encapsulated in carbon cages obtained by co-sputtering of the metal and graphite 409 (1998) 358

A.T. Yinnon, D.A. Lidar (Hamburger), R.B. Gerber, P. Zeppenfeld, M.A. Kryzowski and G. Comsa, Structure determination of disordered metallic sub-monolayers by helium scattering: a theoretical and experimental study 410 (1998) L721

L. Haderbache, R. Garrigos, R. Kofman, E. Søndergard and P. Cheyssac, Numerical and experimental investigations of the size ordering of nanocrystals 410 (1998) L748

Coatings

T. Sonoda and M. Kato, Formation of Ti/O compositional gradient film on Ti–6Al–4V alloy by reactive DC sputtering 402–404 (1998) 241

ELECTRICAL AND MAGNETIC BEHAVIOR

Surfaces and/or films

Insulating films

Q.D. Jiang, Z.J. Huang, P. Jin, C.L. Chen, A. Brazdeikis, Y.Y. Sun, H.H. Feng, A. Benneker and C.W. Chu, Nucleation and surface morphology evolution of ferroelectric $SrBi_2Ta_2O_9$ films studied by atomic force microscopy 405 (1998) L554

Insulating surfaces

U. Malaske, C. Tegenkamp, M. Henzler and H. Pfnür, Defect-induced band gap states and the contact charging effect in wide band gap insulators 408 (1998) 237

D. Ferry, S. Picaud, P.N.M. Hoang, C. Girardet, L. Giordano, B. Demirdjian and J. Suzanne, Water monolayers on MgO(100): structural investigations by LEED experiments, tensor LEED dynamical analysis and potential calculations 409 (1998) 101

Magnetic films

G. Held, W. Sklarek, M. Mayan and H.-P. Steinrück, Characterization of thin copper films on Ni(111) by CO titration 402–404 (1998) 322

J. Bansmann, M. Getzlaff, G. Schönhense, M. Fluchtmann and J. Braun, Valence band photoemission from thin iron films – a comparison of experimental and theoretical results 402–404 (1998) 365

Y. Li, C. Polaczyk and D. Riegel, Thickness and magnetic field dependence of the ferromagnetism of ultrathin Gd films in Gd/W multilayers 402–404 (1998) 386

U. Bovensiepen, P. Poulopoulos, M. Farle and K. Baberschke, The Curie temperature in ultrathin Ni/Cu(001) films determined by ac susceptibility and MOKE 402–404 (1998) 396

T. Shibata, Y. Murakami, T. Watanuki and H. Suematsu, Crystal structures and magnetism of oxygen monolayers on hexagonal boron nitride 405 (1998) 153

V.A. Kosobukin, Magneto-optics via the near field 406 (1998) 32

K. Hanamoto, A. Shinya, M. Kuwahara, T. Okamoto, M. Haraguchi, M. Fukui and K. Koto, Optical constants and growth mode of Ni films deposited on evaporated Al, Ag and Cu films 409 (1998) 413

Magnetic surfaces

A.V. Petukhov and Th. Rasing, A new linear-optical tool for surface magnetism? 402–404 (1998) 360

J. Bansmann, L. Lu and M. Getzlaff, Magnetic dichroism in photoemission from oxygen atoms adsorbed on cobalt surfaces 402–404 (1998) 371

U. Kohl, M. Dippel, G. Filleböck, K. Jacobs, B.-U. Runge and G. Schatz, Local magnetism of ultrathin fcc-Co films on Cu(100) investigated by ^{111}In probes 407 (1998) 104

P. Ferro, R. Moroni, M. Salvietti, M. Canepa and L. Mattera, Surface magnetism of oxygen adsorbed on a Fe/Ag(100) film 407 (1998) 212

K. Hanamoto, A. Shinya, M. Kuwahara, T. Okamoto, M. Haraguchi, M. Fukui and K. Koto, Optical constants and growth mode of Ni films deposited on evaporated Al, Ag and Cu films 409 (1998) 413

Metallic films

J.G. Che and C.T. Chan, Possible faceting transformation of Mo from (111) to {110} 401 (1998) L432

Surfaces and/or films (continued)

V.V. Aristov, V.V. Kazmiruk, V.A. Kudryashov, V.I. Levashov, S.I. Red'kin, C.W. Hagen and P. Kruit, Microfabrication of ultrathin free-standing platinum foils 402–404 (1998) 337

P. Brault, A.-L. Thomann and C. Andreazza-Vignolle, Percolative growth of palladium ultrathin films deposited by plasma sputtering 406 (1998) L597

H.-S. Tao, T.E. Madey and J.E. Rowe, W(111)-based bimetallic systems: core-level photoelectron spectroscopy studies 407 (1998) L640

J. Shen, C. Schmidthals, J. Woltersdorf and J. Kirschner, Structural phase transformation under reversed strain: a comparative study of iron ultrathin film growth on nickel and copper (100) 407 (1998) 90

C. Argile, Interaction of oxygen with lead-precovered nickel(100) 409 (1998) 265

K. Hanamoto, A. Shinya, M. Kuwahara, T. Okamoto, M. Haraguchi, M. Fukui and K. Koto, Optical constants and growth mode of Ni films deposited on evaporated Al, Ag and Cu films 409 (1998) 413

Metallic surfaces

M.I. Trioni, F. Montalenti and G.P. Brivio, Ab-initio adiabatic noble gas–metal interaction: the role of the induced polarization charge 401 (1998) L383

K. Brüning, J. Granow, M. Reiniger, W. Heiland, M. Vicanek and T. Schlathölter, Dissociation of fast N_2 molecules at a Pd(110) surface 402–404 (1998) 215

M. Fluchtmann, S. Bei der Kellen, J. Braun and G. Borstel, Relativistic full-potential photoemission for Cu(111) 402–404 (1998) 663

K. Ota, M. Tanaka and S. Usami, Oxygen adsorption on a W(100) surface studied by reflectance spectroscopy and electron energy-loss fine structure 402–404 (1998) 813

M. Hengsberger, D. Purdie, M. Garnier, K. Breuer and Y. Baer, Observation of super-structure periodicity in angle-resolved photoemission from Cu(610) 405 (1998) L491

I.N. Yakovkin, Metallization of the monolayer Mg film with a linear atomic structure 406 (1998) 57

K. Hanamoto, A. Shinya, M. Kuwahara, T. Okamoto, M. Haraguchi, M. Fukui and K. Koto, Optical constants and growth mode of Ni films deposited on evaporated Al, Ag and Cu films 409 (1998) 413

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B.N.J. Persson and J.W. Gadzuk, Comments on vibrational dynamics of low-frequency adsorbate motion 410 (1998) L779

Semiconducting films

G. Wedler, J. Walz, T. Hesjedal, E. Chilla and R. Koch, Intrinsic stress upon Stranski–Krastanov growth of Ge on Si(001) 402–404 (1998) 290

P.J. Møller, Z.S. Li, T. Egebjerg, M. Sambi and G. Granozzi, Synchrotron-radiation-induced photoemission study of VO_2 ultrathin films deposited on TiO_2(110) 402–404 (1998) 719

Y.Y. Hervieu and M.P. Ruzaikin, Surface processes of impurity incorporation during MBE growth 408 (1998) 57

Semiconducting surfaces

J.Y. Xue, A.P.J. Stampfl, D. Wolfframm, D.A. Evans, M. Hollering, L. Ley, J.D. Riley and R.C.G. Leckey, The surface valence band structure of the two phases of ZnSe(100) 401 (1998) L401

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M. Naitoh, A. Konishi, H. Inenaga, S. Nishigaki, N. Oishi and F. Shoji, Ga-rich GaP(001)(2×4) surface structure studied by low-energy ion scattering spectroscopy 402–404 (1998) 623

S.C.A. Gay, S.J. Jenkins and G.P. Srivastava, Ab-initio density functional calculations for Si(001)/Bi(1 ML)-(2×1) 402–404 (1998) 641

S.J. Jenkins, G.P. Srivastava, R.J. Dixon and C.F. McConville, Ab initio calculation of geometry and bonding for overlaid and inlaid models of Si(001)/Sb(0.25 ML)-c(4×4) 402–404 (1998) 645

H.M. Tütüncü and G.P. Srivastava, Vibrational properties of ZnSe(110) surface 402–404 (1998) 649

D. Casagrande, G.P. Srivastava and A.C. Ferraz, Theoretical calculations for Si(001)-(2×1)Cl 402–404 (1998) 653

M. Çakmak and G.P. Srivastava, Theoretical study of the GaAs(110)-(1×1)–H_2S surface 402–404 (1998) 658

M. Shimoda, S. Tsukamoto and N. Koguchi, Coverage analysis of a sulfur-terminated GaAs(001)-(2×6) surface: the effect of double sulfur-treatment 402–404 (1998) 669

A. Mascaraque, J. Avila, M.C. Asensio and E.G. Michel, Band structure and gap opening in Pb/Ge(111) 402–404 (1998) 742

S. Scandolo, F. Ancilotto, G.L. Chiarotti, G. Santoro, S. Serra and E. Tosatti, First principles calculations of charge and spin density waves of $\sqrt{3}$-adsorbates on semiconductors 402–404 (1998) 808

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T. Komeda and Y. Nishioka, Atomic structure of segregated boron on Si(001) surface; scanning tunneling microscopy and cluster model calculation study 405 (1998) 38

B.K. Agrawal, P. Srivastava and S. Agrawal, First-principles calculation of electron surface states of the zinc-blende GaN(110) surface 405 (1998) 54

Surfaces and/or films (continued)

G.R. Bell, T.S. Jones and C.F. McConville, Spatial variation of plasmon damping near the polar surfaces of InAs in InSb 405 (1998) 280

L.I. Johansson, P.-A. Glans and N. Hellgren, A core level and valence band photoemission study of 6H-SiC(000$\bar{1}$) 405 (1998) 288

P.K. Baumann and R.J. Nemanich, Surface cleaning, electronic states and electron affinity of diamond(100), (111) and (110) surfaces 409 (1998) 320

A.A. Bailes, III, M.A. Boshart and L.E. Seiberling, Dimer elongation on the monohydride-covered Ge/Si(100) surface 410 (1998) L762

Superconducting surfaces

I. Vobornik, C. Quitmann, M. Zacchigna, F. Zwick, M. Grioni, A. Karkin, R.J. Kelley, M. Onellion and G. Margaritondo, Irradiation-induced disorder in high-T_c cuprates: electronic band structure study 402–404 (1998) 761

T. Oku and S. Nakajima, Surface structures of (Hg, Tl)-based oxides studied by high-resolution electron microscopy 407 (1998) L647

Interfaces

Liquid–liquid interfaces

C.-T. Chen, J.-R. Maa, Y.-M. Yang and C.-H. Chang, Effects of electrolytes and polarity of organic liquids on the coalescence of droplets at aqueous-organic interfaces 406 (1998) 167

Metal–electrolyte interfaces

M. Wilms, P. Broekmann, M. Kruft, Z. Park, C. Stuhlmann and K. Wandelt, STM investigation of specific anion adsorption on Cu(111) in sulfuric acid electrolyte 402–404 (1998) 83

A.V. Petukhov, W. Akemann, K.A. Friedrich and U. Stimming, Kinetics of electrooxidation of a CO monolayer at the platinum/electrolyte interface 402–404 (1998) 182

D.A. Emery, P.H. Middleton and I.S. Metcalfe, The effect of electrochemical current pumping on the work function of solid electrolyte supported catalysts 405 (1998) 308

K.P. Bohnen and D.M. Kolb, Charge- versus adsorbate-induced lifting of the Au(100)-(hex) reconstruction in an electrochemical environment 407 (1998) L629

L.E.A. Berlouis, D.A. Mamman and I.G. Azpuru, The electrochemical behaviour of copper in alkaline solutions containing fluoride, studied by in situ ellipsometry 408 (1998) 173

R. Gómez, J.M. Feliu, A. Aldaz and M.J. Weaver, Validity of double-layer charge-corrected voltammetry for assaying carbon monoxide coverages on ordered transition metals: comparisons with adlayer structures in electrochemical and ultrahigh vacuum environments 410 (1998) 48

Metal–insulator interfaces

C. Kohl, F. Calvayrac, P.-G. Reinhard and E. Suraud, Optical response of Na clusters on NaCl surfaces 405 (1998) 74

K.-S. Kim, Y. Takakuwa, T. Abukawa and S. Kono, RHEED-AES observation of In desorption on a single-domain Si(001)-(1×2) surface 410 (1998) 99

Metal–metal interfaces

J.E. Prieto, Ch. Rath, S. Müller, R. Miranda and K. Heinz, A structural analysis of the Co(0001) surface and the early stages of the epitaxial growth of Cu on it 401 (1998) 248

H.-S. Tao, T.E. Madey and J.E. Rowe, W(111)-based bimetallic systems: core-level photoelectron spectroscopy studies 407 (1998) L640

N. Garcia, J. Przeslawski and M. Sharonov, Giant conductance response to light pulses in metallic nanowires 407 (1998) L665

M. Nowicki and J. Osterwalder, Crystalline structure of surface layers for Ag/Cu(001) studied by incident beam electron diffraction 408 (1998) 165

D. Sotiropoulou and S. Ladas, An XPS and XAES study of the Ni/ZrO_2 interface 408 (1998) 182

O. Hellwig, K. Theiss-Bröhl, G. Wilhelmi and H. Zabel, Growth of fcc(111) on bcc(110): Influence of growth and annealing temperature on epitaxy and surface morphology for Pd on Cr 410 (1998) 362

Metal–semiconductor interfaces

A. Cricenti, P. Perfetti and G. Le Lay, High-resolution Si 2p core-level photoemission spectroscopy on Sb-terminated Si(100) surfaces: evidence for a strong interfacial component 401 (1998) 427

J. Almeida, G. Margaritondo, M. Righini, S. Selci, C. Coluzza, Ballistic-electron emission and secondary photoelectron microscopy of the sulfur-passivated Pt–GaP(001) interface 402–404 (1998) 470

R. Biagi, L. Rettighieri, U. del Pennino, V. Panella and P. Dumas, Charge accumulation layer induced by potassium adsorption on hydrogen terminated Si(111)(1×1) 402–404 (1998) 547

Y. Takeda, T. Urano, T. Ohtani, K. Tamiya and S. Hongo, Adsorption structure and silicide formation of Ba on the Si(001) surface 402–404 (1998) 692

P.J. Møller, Z.S. Li, T. Egebjerg, M. Sambi and G. Granozzi, Synchrotron-radiation-induced photoemission study of VO_2 ultrathin films deposited on TiO_2(110) 402–404 (1998) 719

A. Mascaraque, J. Avila, M.C. Asensio and E.G. Michel, Band structure and gap opening in Pb/Ge(111) 402–404 (1998) 742

W.J. Huisman and J.F. van der Veen, Modelling the atomic density across a solid–liquid interface 402–404 (1998) 866

Z. Gai, R.G. Zhao, H. Ji and W.S. Yang, Atomic structure of the Ge(001)-(7×5.5)-Ga surface 405 (1998) L484

E. Kampshoff, N. Wälchli and K. Kern, Silicide formation at palladium surfaces. Part I: Crystalline and amorphous silicide growth at the Pd(110) surface 406 (1998) 103

E. Kampshoff, N. Wälchli and K. Kern, Silicide formation at palladium surfaces. Part II: Amorphous silicide growth at the Pd(100) surface 406 (1998) 117

Interfaces (continued)

C. Polop, C. Rojas, E. Roman, J.A. Martín-Gago, B. Brena, D. Cocco and G. Paolucci, LEED structural determination of the c(2×2) Si/Cu(110) surface alloy 407 (1998) 268

C. Grupp and A. Taleb-Ibrahimi, Huge charge transfer from potassium on H:Si(111)-(1×1) 408 (1998) 160

K. Tamiya, T. Ohtani, Y. Takeda, T. Urano and S. Hongo, Adsorption structures of Te on Si(001) surface observed by low energy electron diffraction 408 (1998) 268

L. Gavioli, M.G. Betti and C. Mariani, Electronic properties of the Bi/Si(100) interface 409 (1998) 207

U. del Pennino, R. Companò, B. Salvarani and C. Mariani, Alkali metal/GaAs(110) interfaces: correlation effects and sub-gap electron energy loss spectra 409 (1998) 258

Schottky barrier

C. Grupp and A. Taleb-Ibrahimi, Huge charge transfer from potassium on H:Si(111)-(1×1) 408 (1998) 160

L. Stockman and H. van Kempen, Ballistic electron emission microscopy and spectroscopy of the Au/GaAs(110) interface 408 (1998) 232

Semiconductor–insulator interfaces

H. Kageshima and K. Shiraishi, Theoretical study of the band offset at silicon-oxide/silicon interfaces with interfacial defects 407 (1998) 133

Semiconductor–semiconductor interfaces

J.R. Power, P. Weightman and A.A. Cafolla, The initial stages of Ge–GaAs(100) interface formation studied by reflectance anisotropy spectroscopy and low-energy electron diffraction 402–404 (1998) 566

T.I. Kamins and R.S. Williams, A model for size evolution of pyramidal Ge islands on Si(001) during annealing 405 (1998) L580

G.R. Bell, T.S. Jones and C.F. McConville, Spatial variation of plasmon damping near the polar surfaces of InAs in InSb 405 (1998) 280

Solid–solid interfaces

D.A. Emery, P.H. Middleton and I.S. Metcalfe, The effect of electrochemical current pumping on the work function of solid electrolyte supported catalysts 405 (1998) 308

Heterostructures and thin film structures

Granular thin film

D. Babonneau, T. Cabioc'h, A. Naudon, J.C. Girard and M.F. Denanot, Silver nanoparticles encapsulated in carbon cages obtained by co-sputtering of the metal and graphite 409 (1998) 358

Metal–metal magnetic thin film structures

Y. Li, C. Polaczyk and D. Riegel, Thickness and magnetic field dependence of the ferromagnetism of ultrathin Gd films in Gd/W multilayers 402–404 (1998) 386

J. Zemek, V. Kamberský, P. de Haan, J. Weber and P. Janda, Surfaces and interfaces of Pd/Co multilayers 402–404 (1998) 529

U. Kohl, M. Dippel, G. Filleböck, K. Jacobs, B.-U. Runge and G. Schatz, Local magnetism of ultrathin fcc-Co films on Cu(100) investigated by ^{111}In probes 407 (1998) 104

Metal–metal nonmagnetic thin film structures

W. von der Linden, V. Dose, N. Memmel and R. Fischer, Probabilistic evaluation of growth models based on time-dependent Auger signals 409 (1998) 290

Semiconductor–semiconductor heterostructures

J.G. Belk, D.W. Pashley, C.F. McConville, B.A. Joyce and T.S. Jones, Surface morphology during strain relaxation in the growth of InAs on GaAs(110) 410 (1998) 82

Semiconductor–semiconductor thin film structures

S.W. Levine, J.R. Engstrom and P. Clancy, A kinetic Monte Carlo study of the growth of Si on Si(100) at varying angles of incident deposition 401 (1998) 112

A. Carlsson, L.R. Wallenberg, C. Persson and W. Seifert, Strain state in semiconductor quantum dots on surfaces: a comparison of electron microscopy and finite element calculations 406 (1998) 48

Thin film structures

T. Igel, R. Pfandzelter and H. Winter, Proton-induced Auger electrons from ultrathin Mn films on Fe(100) 405 (1998) 182

Ultrathin films

G. Fahsold, W. Keller, O. Krauth and A. Lehmann, Infrared absorption of Fe ultrathin films on ionic crystals 402–404 (1998) 790

Contacts

Y. Kawahito, H. Kasai, H. Nakanishi and A. Okiji, Effects of intra-site Coulomb interaction on quantized conductance in a quantum wire between an STM tip and a metal surface 409 (1998) L709

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Given below is a listing of keywords for the Subject and Materials Indexes used by Surface Science. The Subject index is divided into three classes: Theoretical Methods, Experimental Methods, and Phenomena. Please indicate below your abstract at least one keyword from as many of the three classes as appropriate to describe the contents of your manuscript. (You may also tick the appropriate box and include this list with your manuscript.) Occasionally it will not be possible to include a keyword from all three classes, e.g., a general theory manuscript will not exhibit a keyword from the Experimental Methods class. In such a case, omit the entry from the inapplicable class. Also, if appropriate, please select a keyword from one of the three classes of the Materials Index, i.e., Elemental and Chemical Identity, Physical State, and Electrical and Magnetic Behavior. You may use multiple keywords in the above mentioned six classes up to a maximum of eight in total. For example, many experimental papers will be characterized by more than one keyword in the Experimental Methods class of the Subject Index as well as by several keywords from the Materials Index. The keywords will be used as labels for the use in electronic navigation tools. Thus, careful attention to giving a correct, useful description of your work will generate more thorough use of your paper once it is published.

version of 1 October 1996

Subject index

Theoretical methods, models and techniques

- ☐ Ab initio quantum chemical methods and calculations
- ☐ Atom–solid interactions, scattering, diffraction
- ☐ Atomistic dynamics
- ☐ Computer simulations
- ☐ Construction and use of effective interatomic interactions
- ☐ Density functional calculations
- ☐ Electron density, excitation spectra calculations
- ☐ Electron–solid interactions, scattering, diffraction
- ☐ Equilibrium thermodynamics and statistical mechanics
- ☐ Green's function methods
- ☐ Ion–solid interactions, scattering, channeling
- ☐ Ising models
- ☐ Jellium models
- ☐ Many body and quasi-particle theories
- ☐ Models of non-equilibrium phenomena
- ☐ Models of non-linear phenomena
- ☐ Models of surface chemical reactions
- ☐ Models of surface kinetics
- ☐ Molecular dynamics
- ☐ Non-equilibrium thermodynamics and statistical mechanics
- ☐ Semi-empirical models and model calculations

Experimental sample preparation and characterization methods

- ☐ Adsorption isotherms
- ☐ Appearance potential spectroscopy
- ☐ Atom–solid reactions
- ☐ Atom–solid scattering and diffraction – elastic
- ☐ Atom–solid scattering and diffraction – inelastic
- ☐ Atomic force microscopy
- ☐ Auger electron spectroscopy
- ☐ Chemical vapor deposition
- ☐ Desorption induced by electronic transitions (DIET)
  - ☐ *Angle resolved DIET* (including electron stimulated desorption ion angular distribution (ESDIAD))
  - ☐ *Electron stimulated desorption (ESD)*
  - ☐ *Photon stimulated desorption (PSD)*
  - ☐ *Surface photochemistry*
- ☐ Electrical transport measurements
- ☐ Electrochemical methods
- ☐ Electron emission measurements
  - ☐ *Exoelectron emission*
  - ☐ *Field emission*
  - ☐ *Photoemission (total yield)*
  - ☐ *Secondary electron emission*
  - ☐ *Thermally-stimulated emission*
- ☐ Electron energy loss spectroscopy
- ☐ Electron microscopy
  - ☐ *Ballistic electron emission microscopy (BEEM)*
  - ☐ *Low-energy electron microscopy (LEEM)*
  - ☐ *Reflection electron microscopy (REM)*
  - ☐ *Scanning electron microscopy (SEM)*
  - ☐ *Scanning transmission electron microscopy (STEM)*
- ☐ Electron–solid diffraction
  - ☐ *Auger electron diffraction*
  - ☐ *Low energy electron diffraction (LEED)*
  - ☐ *Photoelectron diffraction*
  - ☐ *Photoelectron holography*
  - ☐ *Reflection high-energy electron diffraction (RHEED)*
  - ☐ *Transmission high-energy electron diffraction*
- ☐ Electron–solid scattering and transmission – elastic
- ☐ Electron–solid scattering and transmission – inelastic
- ☐ Electron spin resonance
- ☐ Ellipsometry
- ☐ Field emission microscopy
- ☐ Field emission spectroscopy
- ☐ Field ion microscopy
- ☐ Inverse photoemission spectroscopy
- ☐ Ion etching

- ☐ Ion implantation
- ☐ Ion scattering spectroscopy
  - ☐ *High energy ion scattering (HEIS)*
  - ☐ *Low energy ion scattering (LEIS)*
  - ☐ *Medium energy ion scattering (MEIS)*
- ☐ Isotopic exchange/traces
- ☐ Laser methods
  - ☐ *Laser annealing*
  - ☐ *Laser induced thermal desorption (LITD)*
  - ☐ *Resonance enhanced multiphoton ionization mass spectroscopy (REMPI/MS)*
- ☐ Liquid phase epitaxy
- ☐ Magnetic measurements
- ☐ Molecular beam epitaxy
- ☐ Molecule–solid reactions
- ☐ Molecule–solid scattering and diffraction – elastic
- ☐ Molecule–solid scattering and diffraction – inelastic
- ☐ Mössbauer spectroscopy
- ☐ Neutron scattering
- ☐ Non-linear optical methods
  - ☐ *Second harmonic generation*
  - ☐ *Sum frequency generation*
- ☐ Nuclear magnetic resonance
- ☐ Nuclear reaction analysis
- ☐ Photoelectron spectroscopy
  - ☐ *Angle resolved photoemission*
  - ☐ *Visible and ultraviolet photoelectron spectroscopy*
  - ☐ *Soft X-ray photoelectron spectroscopy*
  - ☐ *X-ray photoelectron spectroscopy*
  - ☐ *Synchrotron radiation photoelectron spectroscopy*
- ☐ Photon absorption spectroscopy
  - ☐ *Extended X-ray absorption fine structure (EXAFS)*
  - ☐ *Infrared absorption spectroscopy*
  - ☐ *Near edge extended X-ray absorption fine structure (NEXAFS)*
  - ☐ *Photoacoustic spectroscopy*
  - ☐ *Visible/ultraviolet absorption spectroscopy*
  - ☐ *Surface extended X-ray absorption fine structure (SEXAFS)*
  - ☐ *X-ray absorption spectroscopy*
- ☐ Photon stimulated desorption (non-electronic)
- ☐ Plasma processing
- ☐ Positron spectroscopy
- ☐ Radioactive tracer methods
- ☐ Raman scattering spectroscopy
- ☐ Reflection spectroscopy
- ☐ Scanning tunneling microscopy
- ☐ Scanning tunneling spectroscopies
- ☐ Secondary ion mass spectroscopy
- ☐ Solid phase epitaxy
- ☐ Sputter deposition
- ☐ Surface photovoltage spectroscopy
- ☐ Thermal desorption spectroscopy
- ☐ Work function measurements
- ☐ X-ray emission
- ☐ X-ray scattering, diffraction, and reflection

Phenomena

- ☐ Adhesion
- ☐ Adsorption kinetics
- ☐ Atom emission
- ☐ Atom–solid interactions
- ☐ Auger ejection
- ☐ Bending of surfaces
- ☐ Catalysis
- ☐ Chemisorption
- ☐ Compound formation
- ☐ Conductivity
- ☐ Corrosion
- ☐ Crystallization
- ☐ Dielectric phenomena
- ☐ Diffusion and migration
- ☐ Electrical transport (conductivity, resistivity, mobility, etc.)
- ☐ Electron bombardment
- ☐ Electron emission
- ☐ Electron–solid interactions
- ☐ Electron stimulated desorption
- ☐ Energy dissipation
- ☐ Epitaxy
- ☐ Etching
- ☐ Evaporation and sublimation
- ☐ Faceting
- ☐ Field effect
- ☐ Field emission
- ☐ Field evaporation
- ☐ Field ionization
- ☐ Friction
- ☐ Growth
- ☐ Hall effect
- ☐ Interface states
- ☐ Ion bombardment
- ☐ Ion emission
- ☐ Ion implantation
- ☐ Ion–solid interactions
- ☐ Light scattering
- ☐ Lubrication
- ☐ Luminescence
  - ☐ *Atom/ion stimulated luminescence*
  - ☐ *Chemiluminescence*
  - ☐ *Electroluminescence*
  - ☐ *Photoluminescence*
- ☐ Magnetic phenomena (cyclotron resonance, phase transitions, etc.)
- ☐ Nucleation
- ☐ Oxidation
- ☐ Photochemistry
- ☐ Photoconductivity
- ☐ Photoelectron diffraction
- ☐ Photoelectron emission
- ☐ Photon emission
- ☐ Photon stimulated desorption
- ☐ Physical adsorption
- ☐ Piezoelectric effect
- ☐ Positron–solid interactions
- ☐ Quantum effects
- ☐ Radiation damage
- ☐ Second harmonic generation
- ☐ Secondary electron emission
- ☐ Self-assembly
- ☐ Sintering
- ☐ Sputtering
- ☐ Sticking
- ☐ Superconductivity
- ☐ Surface chemical reaction
- ☐ Surface diffusion
- ☐ Surface electrical transport (surface conductivity, surface recombination, etc.)
- ☐ Surface electronic phenomena (work function, surface potential, surface states, etc.)
- ☐ Surface energy
- ☐ Surface melting
- ☐ Surface photovoltage
- ☐ Surface relaxation and reconstruction
- ☐ Surface roughening
- ☐ Surface segregation
- ☐ Surface stress
- ☐ Surface structure, morphology, roughness, and topography
- ☐ Surface tension
- ☐ Surface thermodynamics (including phase transitions)
- ☐ Surface waves
  - ☐ *Acoustic waves*
  - ☐ *Capillary waves*
  - ☐ *Magnons*
  - ☐ *Phonons*
  - ☐ *Plasmons*
  - ☐ *Polaritons*
- ☐ Thermal desorption
- ☐ Thermionic emission
- ☐ Tribology
- ☐ Tunneling
- ☐ Vibrations of adsorbed molecules
- ☐ Wetting

Materials index

ELEMENTAL AND CHEMICAL IDENTITY
(Include each component of an interface or multilayer structure as a separate category. Add your own specific elemental or chemical label if a suitable entry is not on the list.)

Elements

- ☐ Alkali metals
- ☐ Alkaline earth metals
- ☐ Aluminum
- ☐ Antimony
- ☐ Arsenic
- ☐ Bismuth
- ☐ Boron
- ☐ Bromine
- ☐ Cadmium
- ☐ Carbon
- ☐ Cerium
- ☐ Chalcogens
- ☐ Chlorine
- ☐ Chromium
- ☐ Cobalt
- ☐ Copper
- ☐ Diamond
- ☐ Gallium
- ☐ Germanium
- ☐ Gold
- ☐ Graphite
- ☐ Hafnium
- ☐ Hydrogen
- ☐ Indium
- ☐ Iodine
- ☐ Iridium
- ☐ Iron
- ☐ Lanthanides
- ☐ Lead
- ☐ Manganese
- ☐ Mercury
- ☐ Molybdenum
- ☐ Nickel
- ☐ Niobium
- ☐ Nitrogen
- ☐ Noble gases
- ☐ Osmium
- ☐ Palladium
- ☐ Phosphorus
- ☐ Platinum
- ☐ Rhenium
- ☐ Rhodium
- ☐ Ruthenium
- ☐ Scandium
- ☐ Silicon
- ☐ Silver
- ☐ Tantalum
- ☐ Technetium
- ☐ Thallium
- ☐ Thorium
- ☐ Tin
- ☐ Titanium
- ☐ Tungsten
- ☐ Uranium
- ☐ Vanadium
- ☐ Ytterbium
- ☐ Yttrium
- ☐ Zinc
- ☐ Zirconium
- ☐ Other .....*

Compounds (non-molecular solids)

- ☐ Alkali halides
- ☐ Alloys
- ☐ Aluminum oxide
- ☐ Barium oxide
- ☐ Biological compounds
- ☐ Borides
- ☐ Boron nitride
- ☐ Cadmium selenide
- ☐ Cadmium sulphide
- ☐ Cadmium telluride
- ☐ Carbides
- ☐ Cobalt oxides
- ☐ Copper oxides
- ☐ Gallium antimonide
- ☐ Gallium arsenide
- ☐ Gallium nitride
- ☐ Gallium phosphide
- ☐ Gallium selenide
- ☐ Halides
- ☐ Hydrides
- ☐ Indium antimonide
- ☐ Indium arsenide
- ☐ Indium oxides
- ☐ Indium phosphide
- ☐ Inorganic compounds
- ☐ Iron oxide
- ☐ Lead telluride
- ☐ Magnesium oxides
- ☐ Mercury telluride
- ☐ Mica
- ☐ Molybdenum oxides
- ☐ Nickel carbide
- ☐ Nickel oxides
- ☐ Nickel sulphide
- ☐ Nitrides
- ☐ Silicides
- ☐ Silicon carbide
- ☐ Silicon–germanium
- ☐ Silicon nitride
- ☐ Silicon oxides
- ☐ Steel
- ☐ Sulphides
- ☐ Tin oxides
- ☐ Tin telluride
- ☐ Titanium carbide
- ☐ Titanium oxide
- ☐ Tungsten oxide
- ☐ Uranium oxide
- ☐ Vanadium oxide
- ☐ Zeolites
- ☐ Zinc oxide
- ☐ Zinc selenide
- ☐ Other .....*

Molecules

- ☐ Alcohols
- ☐ Aldehydes
- ☐ Alkanes
- ☐ Alkenes
- ☐ Alkynes
- ☐ Ammonia
- ☐ Aromatics
- ☐ Biological molecules – nucleic acids
- ☐ Biological molecules – proteins
- ☐ Biological molecules – other .....*
- ☐ Carbon dioxide
- ☐ Carbon monoxide
- ☐ Carboxylic acid
- ☐ Cyanogen
- ☐ Deuterium
- ☐ Esters
- ☐ Ethers
- ☐ Fullerenes
- ☐ Halogens
- ☐ Hydrogen
- ☐ Hydrogen cyanide
- ☐ Hydrogen sulphide
- ☐ Ketones
- ☐ Nitrogen
- ☐ Nitrogen oxides
- ☐ Oxygen
- ☐ Ozone
- ☐ Phosphine
- ☐ Silane
- ☐ Sulphur dioxide
- ☐ Sulphur hexafluoride
- ☐ Water
- ☐ Other .....*

PHYSICAL STATE

Surfaces

- ☐ Amorphous surfaces
- ☐ Dendritic and/or fractile surfaces
- ☐ Glass surfaces
- ☐ Liquid surfaces
- ☐ Polycrystalline surfaces

- ☐ Single crystal surfaces
  - ☐ *Low index single crystal surfaces*
  - ☐ *High index single crystal surfaces*
  - ☐ *Stepped single crystal surfaces*
  - ☐ *Vicinal single crystal surfaces*
  - ☐ *Curved surfaces*
- ☐ Surface defects
- ☐ Whiskers

Interfaces
- ☐ Crystalline–amorphous interfaces
- ☐ Crystalline–glass interfaces
- ☐ Grain boundaries
- ☐ Liquid–gas interfaces
- ☐ Single crystal epitaxy
- ☐ Solid–liquid interfaces
- ☐ Solid–gas interfaces

Heterostructures
- ☐ Heterojunctions
- ☐ Quantum wells
- ☐ Superlattices

Non-epitaxial thin film structures
- ☐ Amorphous thin films
- ☐ Ceramic thin films
- ☐ Glassy thin films
- ☐ Polycrystalline thin films

☐ **Adatoms**

☐ **Clusters**

Particulate composites
- ☐ Blacks
- ☐ Ceramics
- ☐ Powders

☐ **Coatings**

☐ **Porous solids**

ELECTRICAL AND MAGNETIC BEHAVIOR

Surfaces and/or films
- ☐ Insulating films
- ☐ Insulating surfaces
- ☐ Magnetic films
- ☐ Magnetic surfaces
- ☐ Metallic films
- ☐ Metallic surfaces
- ☐ Semiconducting films
- ☐ Semiconducting surfaces
- ☐ Superconducting films
- ☐ Superconducting surfaces

Interfaces
- ☐ Magnetic interfaces
- ☐ Metal–electrolyte interfaces
- ☐ Metal–insulator interfaces
- ☐ Metal–metal interfaces
- ☐ Metal–semiconductor interfaces
- ☐ Schottky barrier
- ☐ Semiconductor–electrolyte interfaces
- ☐ Semiconductor–insulator interfaces
- ☐ Semiconductor–semiconductor interfaces
- ☐ Semiconductor–superconductor interfaces
- ☐ Other interfaces .....*

Heterostructures and thin film structures
- ☐ Metal–metal magnetic heterostructures
- ☐ Metal–metal magnetic thin film structures
- ☐ Metal–metal nonmagnetic heterostructures
- ☐ Metal–metal nonmagnetic thin film structures
- ☐ Metal–oxide–semiconductor (MOS) structures
- ☐ Metal–semiconductor magnetic heterostructures
- ☐ Metal–semiconductor magnetic thin film structures
- ☐ Metal–semiconductor nonmagnetic heterostructures
- ☐ Metal–semiconductor nonmagnetic thin film structures
- ☐ Semiconductor–semiconductor heterostructures
- ☐ Semiconductor–semiconductor thin film structures
- ☐ Superconductor–semiconductor heterostructures
- ☐ Superconductor–semiconductor thin film structures
- ☐ Other heterostructures .....*
- ☐ Other thin film structures .....*

☐ **Contacts**

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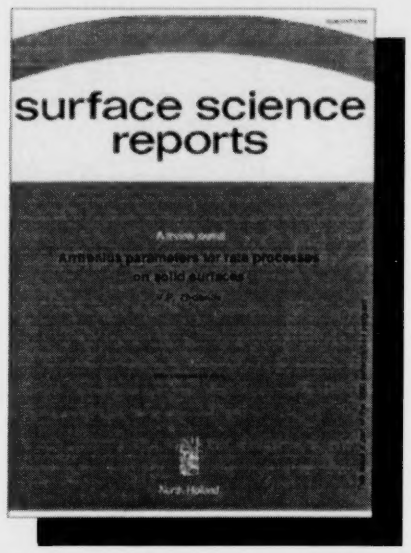

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Volumes 401–410

Author index	1
Subject index	29
Materials index	71

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